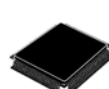
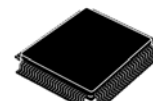


MPC560xS Microcontroller Data Sheet

MPC5606S



LQFP 144
20 x 20 x 1.4 mm



LQFP 176
24 x 24 x 1.4 mm

1 Overview

1.1 Document overview

This document describes the device features and highlights important electrical and physical characteristics. For functional characteristics, see the *MPC5606S Microcontroller Reference Manual*.

1.2 Description

The MPC5606S family of chips is designed to enable the development of automotive instrument cluster applications by providing a single-chip solution capable of hosting real-time applications and driving a TFT display directly using an on-chip color TFT display controller.

MPC5606S chips incorporate a cost-efficient host processor core compliant with the Power Architecture® embedded category. The processor is 100% user-mode compatible with the Power Architecture and capitalizes on the available development infrastructure of current Power Architecture devices with full support from available software drivers, operating systems and configuration code to assist with users' implementations.

Offering high performance processing at speeds up to 64 MHz, the MPC5606S family is optimized for low power consumption and supports a range of on-chip SRAM and internal flash memory sizes. The version with 1 MB of flash memory (MPC5606S) features 160 KB of on-chip graphics SRAM.

See [Table 1](#) for specific memory and feature sets of the product family members.

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1.3 Device comparison

Table 1. MPC5606S family device comparison

Feature	MPC5602S	MPC5604S	MPC5606S
CPU	e200z0h		
Execution speed	Static – 64 MHz		
Flash memory (ECC)	256 KB	512 KB	1 MB
EEPROM Emulation Block (ECC)	4 × 16 KB		
SRAM (ECC)	24 KB	48 KB	48 KB
Graphics SRAM	No	No	160 KB
MPU	12 entry		
eDMA	16 channels		
Display Control Unit (DCU)	No	No	Yes
Parallel Data Interface	No	No	Yes
Stepper Motor Controller (SMC)	6 motors		
Stepper Stall Detect (SSD)	Yes		
Sound Generation Logic (SGL)	Yes		
LCD driver	40 × 4, 38 × 6 ¹		
32 KHz slow external crystal oscillator	Yes		
Real-Time Counter and Autonomous Periodic Interrupt	Yes	Yes	Yes
Periodic Interrupt Timer (PIT)	4 ch, 32-bit		
Software Watchdog Timer (SWT)	Yes		
System Timer Module (STM)	4 ch, 32-bit		
Timed I/O ²	8 ch, 16-bit IC/OC		
	16 ch, 16-bit OPWM/IC/OC ³		
ADC ⁴	16 channels, 10-bit		
CAN (64 mailboxes)	1 × FlexCAN	2 × FlexCAN	2 × FlexCAN
CAN sampler	Yes		
SCI	2 × LINFlex		
SPI	2 × DSPI	2 × DSPI	3 ⁵ × DSPI
QuadSPI serial flash interface	No	No	Yes

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Table 1. MPC5606S family device comparison (continued)

Feature	MPC5602S	MPC5604S	MPC5606S
I ² C	2	2	4
GPIO	105	105	105 (144-pin package) 133 (176-pin package)
Debug	Nexus 1	Nexus 1	Nexus 2+ ⁶
Package	144 LQFP	144 LQFP	144 LQFP ⁷ 176 LQFP 208 MAPBGA ⁸

¹ Configuration is software-programmable.

² IC-Input Capture, OC-Output Compare, OPWM-Output Pulse Width Modulation.

³ This functionality is split over two eMIOS blocks.

⁴ Support for external multiplexer enabling up to 23 channels.

⁵ QuadSPI serial Flash controller can be optionally used as a third DSPI.

⁶ Nexus2+ available on 176 LQFP as alternate pin function and on 208 MAPBGA.

⁷ Not all features are available simultaneously in 144 LQFP package option.

⁸ The 208-pin package is not a production package; it is available in limited quantities for tool development only.

1.4 MPC5606S series blocks

1.4.1 Block diagram

Figure 1 shows a high-level block diagram of the MPC5606S series.

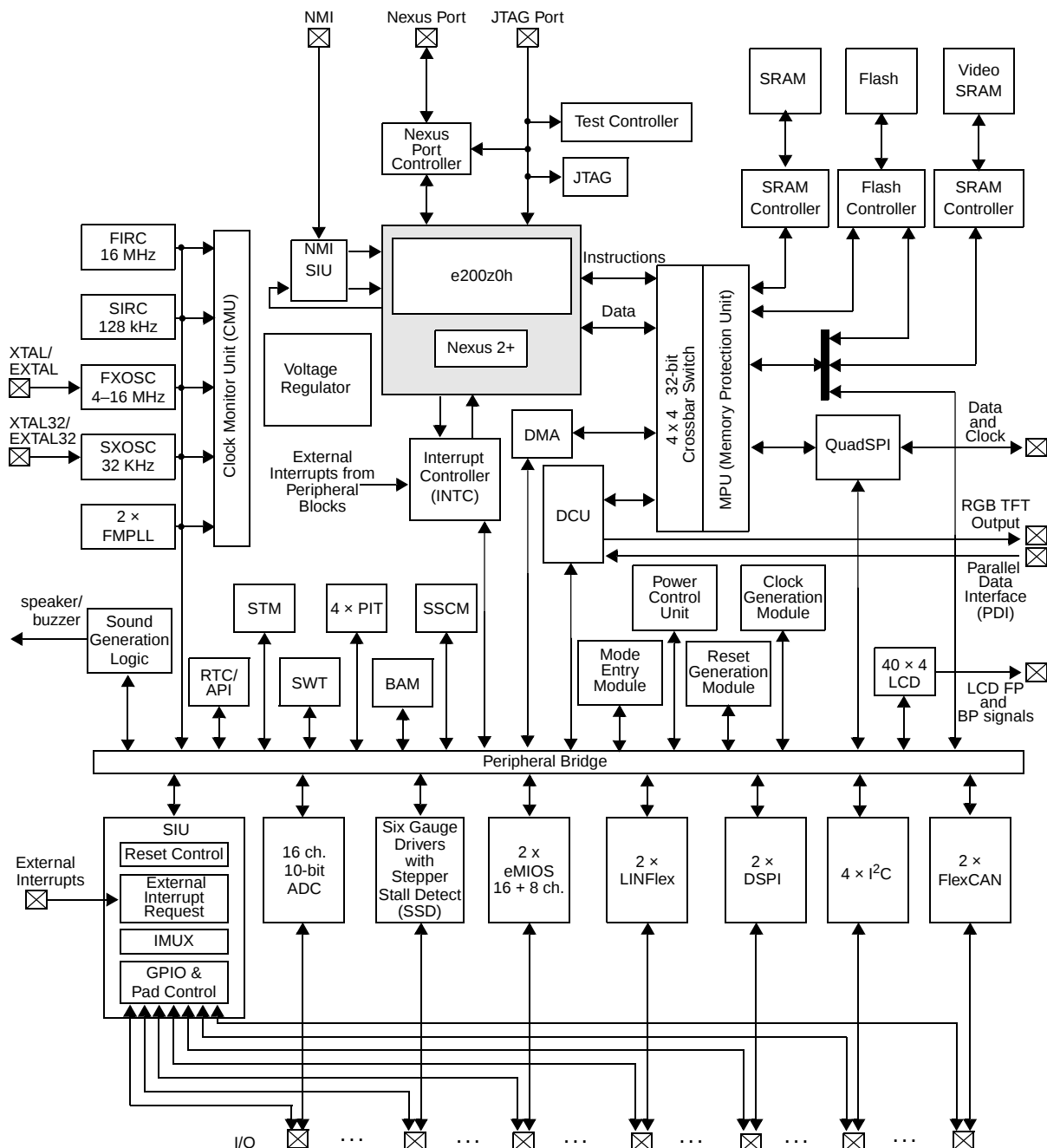


Figure 1. MPC5606S series block diagram

1.5 MPC5606S features

1.5.1 Summary

- Single issue, 32-bit Power Architecture technology compliant CPU core complex (e200z0h)
 - Compatible with Power Architecture instruction set

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Includes variable length encoding (VLE) instruction set for smaller code size footprint; with the encoding of mixed 16-bit and 32-bit instructions, it is possible to achieve significant code size footprint reduction over conventional Book E compliant code

- On-chip ECC flash memory with flash controller
 - Up to 1 MB primary flash—two 512 KB modules with prefetch buffer and 128-bit data access port
 - 64 KB data flash—separate 4×16 KB flash block for EEPROM emulation with prefetch buffer and 128-bit data access port
- Up to 48 KB on-chip ECC SRAM with SRAM controller
- Up to 160 KB on-chip non-ECC graphics SRAM with SRAM controller
- Memory Protection Unit (MPU) with up to 12 region descriptors and 32-byte region granularity to provide basic memory access permission
- Interrupt Controller (INTC) with up to 127 peripheral interrupt sources and eight software interrupts
- 2 Frequency-Modulated Phase-Locked Loops (FMPLLs)
 - Primary FMPLL provides a 64 MHz system clock
 - Auxiliary FMPLL is available for use as an alternate, modulated or non-modulated clock source to eMIOS modules and as alternate clock to the DCU for pixel clock generation
- Crossbar switch architecture enables concurrent access of peripherals, flash memory or RAM from multiple bus masters (AMBA 2.0 v6 AHB)
- 16-channel Enhanced Direct Memory Access controller (eDMA) with multiple transfer request sources using a DMA channel multiplexer
- Boot Assist Module (BAM) supports internal flash programming via a serial link (FlexCAN or LINFlex)
- Display Control Unit to drive TFT LCD displays
 - Includes processing of up to four planes that can be blended together
 - Offers a direct unbuffered hardware bit-blitter of up to 16 software-configurable dynamic layers in order to drastically minimize graphic memory requirements and provide fast animations
 - Programmable display resolutions are available up to WVGA
- Parallel Data Interface (PDI) for digital video input
- LCD segment driver module with two software programmable configurations:
 - Up to 40 frontplane drivers and 4 backplane drivers
 - Up to 38 frontplane drivers and 6 backplane drivers
- Stepper Motor Controller (SMC) module with high-current drivers for up to six instrument cluster gauges driven in full dual H-Bridge configuration including full diagnostics for short circuit detection
- Stepper motor return-to-zero and stall detection module
- Sound generation and playback utilizing PWM channels and eDMA; supports monotonic and polyphonic sound
- 24 eMIOS channels providing up to 16 PWM and 24 input capture / output compare channels
- 10-bit Analog-to-Digital Converter (ADC)
 - Maximum conversion time of 1 μ s
 - Up to 16 internal channels, expandable to 23 via external multiplexing
- Up to 2 Deserial Serial Peripheral Interface (DSPI) modules for full-duplex, synchronous, communications with external devices (extendable to include up to 8 multiplexed external channels)
- QuadSPI serial flash memory controller supporting single, dual and quad modes of operation to interface to external serial flash memory. QuadSPI can be configured to function as another DSPI module (MPC5606S only).
- 2 Local Interconnect Network Flexible (LINFlex) controller modules capable of autonomous message handling (master), autonomous header handling (slave mode), and UART support. Compliant with LIN protocol rev 2.1
- 2 full CAN 2.0B controllers with 64 configurable buffers each; bit rate programmable up to 1 Mbit/s
- Up to 4 Inter-integrated circuit (I²C) internal bus controllers with master/slave bus interface
- Up to 133 configurable general purpose pins supporting input and output operations

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- Real Time Counter (RTC) with multiple clock sources:
 - 128 kHz slow internal RC oscillator or 16 MHz fast internal RC oscillator supporting autonomous wakeup with 1 ms resolution with maximum timeout of 2 seconds
 - 32 KHz slow external crystal oscillator, supporting wakeup with 1 s resolution and maximum timeout of one hour
 - 4–16 MHz fast external crystal oscillator
- System timers:
 - 4-channel 32-bit System Timer Module (STM)—included in processor platform
 - 4-channel 32-bit Periodic Interrupt Timer (PIT) module
 - Software Watchdog Timer (SWT)
- System Integration Unit (SIU) module to manage resets, external interrupts, GPIO and pad control
- System Status and Configuration Module (SSCM) to provide information for identification of the device, last boot mode, or debug status and provides an entry point for the censorship password mechanism
- Clock Generation Module (MC_CGM) to generate system clock sources and provide a unified register interface, enabling access to all clock sources
- Clock Monitor Unit (CMU) to monitor the integrity of the main crystal oscillator and the PLL and act as a frequency meter, measuring the frequency of one clock source and comparing it to a reference clock
- Mode Entry Module (MC_ME) to control the device power mode, i.e., RUN, HALT, STOP, or STANDBY, control mode transition sequences, and manage the power control, voltage regulator, clock generation and clock management modules
- Reset Generation Module (MC_RGM) to manage reset assertion and release to the device at initial power-up
- Nexus development interface (NDI) per IEEE-ISTO 5001-2003 Class Two Plus standard
- Device/board boundary-scan testing supported per Joint Test Action Group (JTAG) of IEEE (IEEE 1149.1)
- On-chip voltage regulator controller for regulating the 3.3 or 5 V supply voltage down to 1.2 V for core logic (requires external ballast transistor)
- The MPC5606S microcontrollers are offered in the following packages:¹
 - 144 LQFP, 0.5 mm pitch, 20 mm × 20 mm outline
 - 176 LQFP, 0.5 mm pitch, 24 mm × 24 mm outline
 - 208 MAPBGA, 1.0 mm pitch, 17 mm × 17 mm outline (not a production package; available in limited quantities for tool development only)

1.6 Details

1.6.1 Low-power operation

MPC5606S devices are designed for optimized low-power operation and dynamic power management of the core processor and peripherals. Power management features include software-controlled clock gating of peripherals and multiple power domains to minimize leakage in low-power modes.

There are two static low-power modes, STANDBY and STOP, and two dynamic power modes—RUN and HALT. Both low power modes use clock gating to halt the clock for all or part of the device. The STANDBY mode also uses power gating to automatically turn off the power supply to parts of the device to minimize leakage.

STANDBY mode turns off the power to the majority of the chip to offer the lowest power consumption mode. The contents of the cores, on-chip peripheral registers and potentially some of the volatile memory are lost. STANDBY mode is configurable to make certain features available with the disadvantage that these consume additional current:

- It is possible to retain the contents of the full RAM or only 8 KB.

1. See the device comparison table or orderable parts summary for package offerings for each device in the family.

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- It is possible to enable the internal 16 MHz or 128 kHz RC oscillator, the external 4–16 MHz oscillator, or the external 32 KHz oscillator.
- It is possible to keep the LCD module active.

The device can be awakened from STANDBY mode via from any of up to 19 I/O pins, a reset or from a periodic wake-up using a low power oscillator.

STOP mode maintains power to the entire device allowing the retention of all on-chip registers and memory, and providing a faster recovery low power mode than the lowest STANDBY mode. There is no need to reconfigure the device before executing code. The clocks to the core and peripherals are halted and can be optionally stopped to the oscillator or PLL at the expense of a slower start-up time.

STOP is entered from RUN mode only. Wake-up from STOP mode is triggered by an external event or by the internal periodic wake-up, if enabled.

RUN modes are the main operating mode where the entire device can be powered and clocked and from which most processing activity is done. Four dynamic RUN modes are supported—RUN0 - RUN3. The ability to configure and select different RUN modes enables different clocks and power configurations to be supported with respect to each other and to allow switching between different operating conditions. The necessary peripherals, clock sources, clock speed and system clock prescalers can be independently configured for each of the four RUN modes of the device.

HALT mode is a reduced activity, low power mode intended for moderate periods of lower processing activity. In this mode the core system clocks are stopped but user-selected peripheral tasks can continue to run. It can be configured to provide more efficient power management features (switch-off PLL, flash memory, main regulator, etc.) at the cost of longer wake up latency. The system returns to RUN mode as soon as an event or interrupt is pending.

Table 2 summarizes the operating modes of MPC5606S devices.

Table 2. Operating mode summary¹

	Operating modes:	RUN	HALT	STOP	STANDBY		POR
SoC features	Core	On	CG	CG	Off	Off	—
	Peripherals	OP	OP	CG	Off ²	Off	—
	Flash memory	OP	OP	CG	Off	Off	—
	SRAM	On	On	CG	CG ³	8 KB ⁴	—
	Graphics RAM	On	On	CG	Off	Off	—
Clock sources	Main PLL	OP	OP	CG	Off	Off	—
	Auxiliary PLL	OP	OP	CG	Off	Off	—
	16 MHz IRC	On	On	OP	OP	OP	—
	X OSC	OP	OP	OP	OP	OP	—
	128 kHz IRC	On	On	On	On	On	—
	32 KHz XOSC	OP	OP	OP	OP	OP	—
Periodic Wake-up		—	OP	OP	OP	OP	—
Wake-up input		—	OP	OP	OP	OP	—
VREG mode		FP	FP	LP	LP	LP	—
Wakeup times ⁵	VREG start-up	—	—	50 μ s	250 μ s	50 μ s	250 μ s ⁶
	IRC wake-up	—	—	4 μ s	4 μ s	8 μ s	8 μ s
	Flash memory recovery	—	—	20 μ s	100 μ s	100 μ s	100 μ s
	OSC stabilization	—	—	1 ms	1 ms	1 ms	1 ms
	PLL lock	—	—	200 μ s	200 μ s	200 μ s	200 μ s
	S/W reconfig	—	—	—	Var	Var	—
	Mode switch over	—	TBD	24 μ s	28 μ s	28 μ s	BAM

¹ Table Key:

On- Powered and clocked

OP- Optionally configurable to be enabled or disabled (clock gated)

CG- Clock Gated, Powered but clock stopped

Off- Powered off and clock gated

FP- VREG Full Performance mode

LP- VREG Low Power mode, reduced output capability of VREG but lower power consumption

Var- Variable duration, based on the required reconfiguration and execution clock speed

BAM- Boot Assist Module Software and Hardware used for device start-up and configuration

² The LCD can optionally be kept running while the device is in STANDBY mode

³ All of the RAM content is retained, but not accessible in STANDBY mode

⁴ 8 KB of the RAM content is retained, but not accessible in STANDBY mode

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- 5 A high level summary of some key durations that need to be considered when recovering from low power modes. This does not account for all durations at wake up. Other delays will be necessary to consider including, but not limited to the external supply start-up time.
IRC Wake-up time must not be added to the overall wake-up time as it starts in parallel with the VREG.
All other wake-up times must be added to determine the total start-up time
- 6 This is the startup of the regulator that happens after the 5 V has reached beyond its POR range. If the external supply ramp rate is slow, measure from when VREG has crossed beyond the POR threshold, otherwise this value will depend on the ramp rate of the external supply (VDDR).

Additional notes on low power operation:

- Fast wake-up using the on-chip 16 MHz internal RC oscillator allows rapid execution from RAM on exit from low power modes
- The 16 MHz internal RC oscillator supports low speed code execution and clocking of peripherals when it is selected as the system clock and can also be used as the PLL input clock source to provide fast start-up without the external oscillator delay
- MPC5606S devices include an internal voltage regulator that includes the following features:
 - Regulates input to generate all internal supplies
 - Manages power gating
 - Low power regulators support operation when in STOP and STANDBY modes to minimize power consumption
 - Startup on-chip regulators in <50 μ s for rapid exit of STOP and STANDBY modes
 - Low voltage detection on main supply and 1.2 V regulated supplies

1.6.2 e200z0h core processor

The e200z0h processor is similar to other processors in the e200zx series but supports only the VLE instruction set and does not include the signal processing extension for DSP applications or a floating point unit.

The e200z0h has all the features of the e200z0 plus:

- Branch acceleration using Branch Target Buffer (BTB)
- Supports independent instruction and data accesses to different memory subsystems, such as SRAM and Flash memory via independent Instruction and Data BIUs

The e200z0h processor uses a four stage in-order pipeline for instruction execution. The Instruction Fetch (stage 1), Instruction Decode/Register file Read/Effective Address Calculation (stage 2), Execute/Memory Access (stage 3), and Register Writeback (stage 4) stages operate in an overlapped fashion, allowing single clock instruction execution for most instructions.

The integer execution unit consists of a 32-bit Arithmetic Unit (AU), a Logic Unit (LU), a 32-bit Barrel shifter (Shifter), a Mask-Insertion Unit (MIU), a Condition Register manipulation Unit (CRU), a Count-Leading-Zeros unit (CLZ), an 8×32 Hardware Multiplier array, result feed-forward hardware, and a hardware divider.

Most arithmetic and logical operations are executed in a single cycle with the exception of the divide and multiply instructions. A Count-Leading-Zeros unit operates in a single clock cycle. The Instruction Unit contains a PC incrementer and a dedicated Branch Address adder to minimize delays during change of flow operations. Branch target prefetching from the BTB is performed to accelerate certain taken branches. Sequential prefetching is performed to ensure a supply of instructions into the execution pipeline. Branch target prefetching is performed to accelerate taken branches. Prefetched instructions are placed into an instruction buffer capable of holding four instructions.

Conditional branches not taken execute in a single clock. Branches with successful target prefetching have an effective execution time of one clock on e200z0h. All other taken branches have an execution time of two clocks.

Memory load and store operations are provided for byte, halfword, and word (32-bit) data with automatic zero or sign extension of byte and halfword load data as well as optional byte reversal of data. These instructions can be pipelined to allow effective single cycle throughput. Load and store multiple word instructions allow low overhead context save and restore operations. The

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load/store unit contains a dedicated effective address adder to allow effective address generation to be optimized. Also, a load-to-use dependency does not incur any pipeline bubbles for most cases.

The Condition Register unit supports the condition register (CR) and condition register operations defined by the Power Architecture. The condition register consists of eight 4-bit fields that reflect the results of certain operations, such as move, integer and floating-point compare, arithmetic, and logical instructions, and provide a mechanism for testing and branching.

Vectored and autovectored interrupts are supported. Hardware vectored interrupt support is provided to allow multiple interrupt sources to have unique interrupt handlers invoked with no software overhead.

The CPU includes support for Variable Length Encoding (VLE) instruction enhancements. This allows the Power Architecture instruction set to be represented by a modified instruction set made up from a mixture of 16-bit and 32-bit instructions. This results in a significantly smaller code size footprint without affecting performance noticeably.

The CPU core is enhanced by an additional interrupt source—Non Maskable Interrupt. This interrupt source is routed directly from package pins, via edge detection logic in the SIU to the CPU, bypassing the Interrupt Controller completely. Once the edge detection logic is programmed, it can not be disabled, except by reset. The Non Maskable Interrupt is, as the name suggests, completely un-maskable and when asserted will always result in the immediate execution of the respective interrupt service routine. The Non maskable interrupt is not guaranteed to be recoverable.

The CPU core has an additional ‘Wait for Interrupt’ instruction that is used in conjunction with low power STOP mode. When Low Power Stop mode is selected, this instruction is executed to allow the system clock to be stopped. An external interrupt source or the system wake-up timer is used to restart the system clock and allow the CPU to service the interrupt.

Additional features include:

- Load/store unit
 - 1-cycle load latency
 - Misaligned access support
 - No load-to-use pipeline bubbles
- Thirty-two 32-bit general purpose registers (GPRs)
- Separate instruction bus and load/store bus Harvard architecture
- Reservation instructions for implementing read-modify-write constructs
- Multi-cycle divide (divw) and load multiple (lmw) store multiple (smw) multiple class instructions, can be interrupted to prevent increases in interrupt latency
- Extensive system development support through Nexus debug port

1.6.3 Crossbar switch (XBAR)

The XBAR multi-port crossbar switch supports simultaneous connections between four master ports and four slave ports. The crossbar supports a 32-bit address bus width and a 32-bit data bus width.

The crossbar allows four concurrent transactions to occur from any master port to any slave port but one of those transfers must be an instruction fetch from internal flash. If a slave port is simultaneously requested by more than one master port, arbitration logic selects the higher priority master and grants it ownership of the slave port. All other masters requesting that slave port are stalled until the higher priority master completes its transactions. Requesting masters having equal priority are granted access to a slave port in round-robin fashion, based upon the ID of the last master to be granted access.

The crossbar provides the following features:

- 4 master ports:
 - e200z0h core instruction port
 - e200z0h core complex load/store data port
 - eDMA controller
 - Display control unit

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- 4 slave ports:
 - 1 flash port dedicated to the CPU
 - Platform SRAM
 - QuadSPI serial flash controller
 - 1 slave port combining:
 - Flash port dedicated to the Display Control Unit and eDMA module
 - Graphics SRAM
 - Peripheral bridge
- 32-bit internal address bus, 32-bit internal data bus

1.6.4 Enhanced Direct Memory Access (eDMA)

The eDMA module is a controller capable of performing complex data movements via 16 programmable channels, with minimal intervention from the host processor. The hardware micro architecture includes a DMA engine which performs source and destination address calculations, and the actual data movement operations, along with an SRAM-based memory containing the transfer control descriptors (TCD) for the channels. This implementation is utilized to minimize the overall block size. The eDMA module provides the following features:

- 16 channels support independent 8-, 16- or 32-bit single value or block transfers
- Supports variable sized queues and circular queues
- Source and destination address registers are independently configured to post-increment or remain constant
- Each transfer is initiated by a peripheral, CPU, periodic timer interrupt or eDMA channel request
- Each DMA channel can optionally send an interrupt request to the CPU on completion of a single value or block transfer
- DMA transfers possible between system memories, QuadSPI, DSPIs, I²C, ADC, eMIOS and General Purpose I/Os (GPIOs)
- Programmable DMA Channel Mux allows assignment of any DMA source to any available DMA channel with up to a total of 64 potential request sources.

1.6.5 Inter-IC communications module (I²C)

The I²C module features the following:

- Up to four I²C modules supported
- Two-wire bi-directional serial bus for on-board communications
- Compatibility with I²C bus standard
- Multimaster operation
- Software-programmable for one of 256 different serial clock frequencies
- Software-selectable acknowledge bit
- Interrupt-driven, byte-by-byte data transfer
- Arbitration-lost interrupt with automatic mode switching from master to slave
- Calling address identification interrupt
- Start and stop signal generation/detection
- Repeated START signal generation
- Acknowledge bit generation/detection
- Bus-busy detection

1.6.6 Interrupt Controller (INTC)

The INTC provides priority-based preemptive scheduling of interrupt requests, suitable for statically scheduled hard real-time systems.

For high priority interrupt requests, the time from the assertion of the interrupt request from the peripheral to when the processor is executing the interrupt service routine (ISR) has been minimized. The INTC provides a unique vector for each interrupt request source for quick determination of which ISR needs to be executed. It also provides an ample number of priorities so that lower priority ISRs do not delay the execution of higher priority ISRs. To allow the appropriate priorities for each source of interrupt request, the priority of each interrupt request is software configurable.

When multiple tasks share a resource, coherent accesses to that resource need to be supported. The INTC supports the priority ceiling protocol for coherent accesses. By providing a modifiable priority mask, the priority can be raised temporarily so that all tasks which share the resource can not preempt each other.

Multiple processors can assert interrupt requests to each other through software settable interrupt requests. These same software settable interrupt requests also can be used to break the work involved in servicing an interrupt request into a high priority portion and a low priority portion. The high priority portion is initiated by a peripheral interrupt request, but then the ISR asserts a software settable interrupt request to finish the servicing in a lower priority ISR. Therefore these software settable interrupt requests can be used instead of the peripheral ISR scheduling a task through the RTOS. The INTC provides the following features:

- Unique 9-bit vector for each of the possible 128 separate interrupt sources
- 8 software triggerable interrupt sources
- 16 priority levels with fixed hardware arbitration within priority levels for each interrupt source
- Ability to modify the ISR or task priority.
 - Modifying the priority can be used to implement the Priority Ceiling Protocol for accessing shared resources.
- External non maskable interrupt directly accessing the main core critical interrupt mechanism
- 32 external interrupts

1.6.7 QuadSPI serial flash controller

The QuadSPI module enables use of external serial flash memories supporting single, dual and quad modes of operation. It features the following:

- Memory mapping of external serial flash
- Automatic serial flash read command generation by CPU, DMA or DCU read access on AHB bus
- Supports single, dual and quad serial flash read commands
- Flexible buffering scheme to maximize read bandwidth of serial flash
- ‘Legacy’ mode allowing QuadSPI to be used as a standard DSPI (no DSI or CSI mode)

1.6.8 System Integration Unit (SIU)

The SIU controls MCU reset configuration, pad configuration, external interrupt, general purpose I/O (GPIO), internal peripheral multiplexing, and the system reset operation.

The GPIO features the following:

- Up to 4 levels of internal pin multiplexing, allowing exceptional flexibility in the allocation of device functions for each package
- Centralized general purpose input output (GPIO) control of up to 132 input/output pins (package dependent)
- All GPIO pins can be independently configured to support pull-up, pull down, or no pull
- Reading and writing to GPIO supported both as individual pins and 16-bit wide ports

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- All peripheral pins can be alternatively configured as both general purpose input or output pins except ADC channels which support alternative configuration as general purpose inputs
- Direct readback of the pin value supported on all digital output pins through the SIU
- Configurable digital input filter that can be applied to up to 14 general purpose input pins for noise elimination on external interrupts
- Register configuration protected against change with soft lock for temporary guard or hard lock to prevent modification until next reset.

1.6.9 Flash memory

The MPC5606S microcontroller has the following flash memory features:

- Up to 1 MB of burst flash memory
 - Typical flash memory access time: 0 wait-state for buffer hits, 2 wait-states for page buffer miss at 64 MHz
 - Two 4×128-bit page buffers with programmable prefetch control
 - 1 set of page buffers can be allocated for code-only, fixed partitions of code and data, all available for any access
 - 1 set of page buffers allocated to Display Controller Unit and the eDMA
 - 64-bit ECC with single-bit correction, double-bit detection for data integrity
 - 64 KB data flash memory — separate 4×16 KB flash block for EEPROM emulation with prefetch buffer and 128-bit data access port
- Small block flash memory arrangement to support features such as boot block, operating system block
- Hardware managed flash memory writes, erase and verify sequence
- Censorship protection scheme to prevent flash memory content visibility
- Separate dedicated 64 KB data flash memory for EEPROM emulation
 - 4 erase sectors each containing 16 KB of memory
 - Offers Read-While-Write functionality from main program space
 - Same data retention and program erase specification as main program flash memory array

1.6.10 SRAM

The MPC5606S microcontrollers have up to 48 KB general-purpose on-chip SRAM with the following features:

- Typical SRAM access time: 0 wait-state for reads and 32-bit writes; 1 wait-state for 8- and 16-bit writes if back to back with a read to same memory block
- 32-bit ECC with single-bit correction, double bit detection for data integrity
- Supports byte (8-bit), half word (16-bit), and word (32-bit) writes for optimal use of memory
- User transparent ECC encoding and decoding for byte, half word, and word accesses
- Separate internal power domain applied to full SRAM block, 8 KB SRAM block during STANDBY modes to retain contents during low power mode.

1.6.11 On-chip graphics SRAM

The MPC5606S microcontroller has 160 KB on-chip graphics SRAM with the following features:

- Usable as general purpose SRAM
- Typical SRAM access time: 0 wait-state for reads and 32-bit writes
- Supports byte (8-bit), half word (16-bit), and word (32-bit) writes for optimal use of memory

1.6.12 Memory Protection Unit (MPU)

The MPU features the following:

- 12 region descriptors for per master protection
- Start and end address defined with 32-byte granularity
- Overlapping regions supported
- Protection attributes can optionally include process ID
- Protection offered for 3 concurrent read ports
- Read and write attributes for all masters
- Execute and supervisor/user mode attributes for processor masters

1.6.13 Boot Assist Module (BAM)

The BAM is a block of read-only memory that is programmed once by Freescale. The BAM program is executed every time the MCU is powered-on or reset in normal mode. The BAM supports different modes of booting. They are:

- Booting from internal flash memory
- Serial boot loading (A program is downloaded into RAM via FlexCAN or LINFlex and then executed)
- Booting from external memory

Additionally the BAM:

- Enables and manages the transition of the MCU from reset to user code execution
- Configures device for serial bootloader
- Enables multiple bootcode starting locations out of reset through implementation of search for valid Reset Configuration Halfword
- Enables or disables software watchdog timer out of reset through BAM read of Reset Configuration Halfword option bit

1.6.14 Enhanced Modular Input/Output System (eMIOS)

MPC5606S microcontrollers have two eMIOS modules—one with 16 channels and one with 8—with input/output channels supporting a range of 16-bit input capture, output compare, and Pulse Width Modulation functions.

The modules are configurable and can implement 8-channel, 16-bit input capture/output compare or 16-channel, 16-bit output pulse width modulation/input compare/output compare. Up to five additional channels are configurable as modulus counters.

eMIOS other features include:

- Selectable clock source from main FMPLL, auxiliary FMPLL, external 4–16 MHz oscillator or 16 MHz Internal RC oscillator
- Timed I/O channels with 16-bit counter resolution
- Buffered updates
- Support for shifted PWM outputs to minimize occurrence of concurrent edges
- Edge aligned output pulse width modulation
 - Programmable pulse period and duty cycle
 - Supports 0% and 100% duty cycle
 - Shared or independent time bases
- Programmable phase shift between channels
- Selectable combination of pairs of eMIOS outputs to support sound generation
- DMA transfer support

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- Selectable clock source from the primary FMPLL, auxiliary FMPLL, external 4–16 MHz oscillator or the 16 MHz internal RC oscillator.

The channel configuration options for the 16-channel eMIOS module are summarized in [Table 3](#).

Table 3. 16-Channel eMIOS module channel configuration

Channel mode	Channel number				
	8 IC/OC Counter	9–15 IC/OC	16 PWM Counter	17–22 PWM	23 PWM Counter
General Purpose Input/Output	X	X	X	X	X
Single Action Input Capture	X	X	X	X	X
Single Action Output Compare	X	X	X	X	X
Modulus Counter Buffered ¹	X		X		X
Output Pulse Width and Frequency Modulation Buffered			X	X	X
Output Pulse Width Modulation Buffered			X	X	X

¹ Modulus up and down counters to support driving local and global counter busses

The channel configuration options for the 8-channel eMIOS module are summarized in [Table 4](#).

Table 4. 8-Channel eMIOS module channel configuration

Channel mode	Channel number		
	16 PWM Counter	17–22 PWM	23 PWM Counter
General Purpose Input/Output	X	X	X
Single Action Input Capture	X	X	X
Single Action Output Compare	X	X	X
Modulus Counter Buffered ¹	X		X
Output Pulse Width and Frequency Modulation Buffered	X	X	X
Output Pulse Width Modulation Buffered	X	X	X

¹ Modulus up and down counters to support driving local and global counter busses

1.6.15 Analog-to-Digital Converter (ADC)

The ADC features the following:

- 10-bit A/D resolution
- 0 to 5 V common mode conversion range
- Supports conversions speeds of up to 1 μ s

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- 16 internal and 8 external channels support
 - Up to 16 single-ended inputs channels
 - All channels configured to have alternate function as general purpose input/output pins
 - 10-bit ± 3 counts accuracy (TUE)
 - External multiplexer support to increase up to 23 channels
 - Automatic 1×8 multiplexer control
 - External multiplexer connected to a dedicated input channel
 - Shared register between the 8 external channels
 - Result register available for every non-multiplexed channel
 - Configurable Left or Right aligned result format
 - Supports for one-shot, scan and injection conversion modes
 - Injection mode status bit implemented on adjacent 16-bit register for each result
 - Supports Access to Result and injection status with single 32-bit read
 - Independently enabling of function for channels:
 - Offset Refresh
 - Conversion Triggering support
 - Internal conversion triggering from periodic interrupt timer (PIT)
 - 4 configurable analog comparator channels offering range comparison with triggered alarm
 - Greater than
 - Less than
 - Out of range
 - All unused analog inputs can be used as general purpose input and output pins
 - Power Down mode
 - Optional support for DMA transfer of results

1.6.16 Deserial Serial Peripheral Interface (DSPI)

The deserial serial peripheral interface (DSPI) modules provide a synchronous serial interface for communication between the MPC5606S MCU and external devices.

The DSPI features the following:

- Up to two DSPI modules
- Full duplex, synchronous transfers
- Master or slave operation
- Programmable master bit rates
- Programmable clock polarity and phase
- End-of-transmission interrupt flag
- Programmable transfer baud rate
- Programmable data frames from 4 to 16 bits
- Up to 6 chip select lines available, depending on package and pin multiplexing, enable 64 external devices to be selected using external muxing from a single DSPI
- 8 clock and transfer attributes registers
- Chip select strobe available as alternate function on one of the chip select pins for deglitching
- FIFOs for buffering up to 4 transfers on the transmit and receive side
- General purpose I/O functionality on pins when not used for SPI
- Queueing operation possible through use of eDMA

1.6.17 FlexCAN

The MPC5606S MCU contains two controller area network (FlexCAN) modules. The FlexCAN module is a communication controller implementing the CAN protocol according to Bosch Specification version 2.0B. The CAN protocol was designed to be used primarily as a vehicle serial data bus, meeting the specific requirements of this field: real-time processing, reliable operation in the EMI environment of a vehicle, cost-effectiveness and required bandwidth.

The FlexCan modules offer the following:

- Compliant with CAN protocol specification, Version 2.0B active
- 64 mailboxes, each configurable as transmit or receive
 - Mailboxes configurable while module remains synchronized to CAN bus
- Transmit features
 - Supports configuration of multiple mailboxes to form message queues of scalable depth
 - Arbitration scheme according to message ID or message buffer number
 - Internal arbitration to guarantee no inner or outer priority inversion
 - Transmit abort procedure and notification
- Receive features
 - Individual programmable filters for each mailbox
 - 8 mailboxes configurable as a 6-entry receive FIFO
 - 8 programmable acceptance filters for receive FIFO
- Programmable clock source
 - System clock
 - Direct oscillator clock to avoid PLL jitter
- Listen only mode capabilities
- CAN Sampler
 - Can catch the 1st message sent on the CAN network while the MPC5606S is stopped. This guarantees a clean startup of the system without missing messages on the CAN network.
 - The CAN sampler is connected to one of the CAN RX pins.

1.6.18 Serial communication interface module (LINFlex)

The MPC5606S devices include up to two LINFlex modules and support for LIN Master mode, LIN Slave mode and UART mode. The modules are LIN state machine compliant to the LIN 1.3 and 2.0 and 2.1 Specifications and handle LIN frame transmission and reception without CPU intervention.

Other features include:

- Autonomous LIN frame handling
- Message buffer to store identifier and up to eight data bytes
- Supports message length of up to 64 bytes
- Detection and flagging of LIN errors
- Sync field; Delimiter; ID parity; Bit, Framing; Checksum and Timeout errors
- Classic or extended checksum calculation
- Configurable Break duration of up to 36-bit times
- Programmable Baud rate prescalers (13-bit mantissa, 4-bit fractional)
- Diagnostic features
 - Loop back
 - Self Test
 - LIN bus stuck dominant detection

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- Interrupt driven operation with 16 interrupt sources
 - LIN slave mode features
 - Autonomous LIN header handling
 - Autonomous LIN response handling
 - Discarding of irrelevant LIN responses using up to 16 ID filters
 - UART mode
 - Full-duplex operation
 - Standard non return-to-zero (NRZ) mark/space format
 - Data buffers with 4-byte receive, 4-byte transmit
 - Configurable word length (8-bit or 9-bit words)
 - Error detection and flagging
 - Parity, noise and framing errors
 - Interrupt driven operation with 4 interrupts sources
 - Separate transmitter and receiver CPU interrupt sources
 - 16-bit programmable baud-rate modulus counter and 16-bit fractional
 - 2 receiver wake-up methods

1.6.19 System clocks and clock generation modules

The system clock on the MPC5606S can be derived from an external oscillator, an on-chip FMPLL, or the internal 16 MHz oscillator.

- The source system clock frequency can be changed via an on-chip programmable clock divider ($\div 1$ to $\div 32$).
- Additional programmable peripheral bus clock divider ratio ($\div 1$ to $\div 16$)
- The MPC5606S has 2 on-chip FMPLLs—the primary module and an auxiliary module.
 - Each features the following:
 - Input clock frequency from 4 MHz to 16 MHz
 - Lock detect circuitry continuously monitors lock status
 - Loss Of Clock (LOC) detection for reference and feedback clocks
 - On-chip loop filter (for improved electromagnetic interference performance and reduction of number of external components required)
 - Support for frequency ramping from PLL
 - The primary FMPLL module is for use as a system clock source. The auxiliary FMPLL is available for use as an alternate, modulated or non-modulated clock source to eMIOS modules and as alternate clock to the DCU for pixel clock generation.
- The main oscillator provides the following features:
 - Input frequency range 4–16 MHz
 - Square-wave input mode
 - Oscillator input mode 3.3 V (5.0 V)
 - Automatic level control
 - PLL reference
- MPC5606S includes a 32 KHz low power external oscillator for slow execution, low power, and Real Time Clock
- Dedicated internal 128 kHz RC oscillator for low power mode operation and self wake-up
 - $\pm 10\%$ accuracy across voltage and temperature (after factory trimming)
 - Trimming registers to support improved accuracy with in-application calibration
- Dedicated 16 MHz internal RC oscillator
 - Used as default clock source out of reset

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Provides a clock for rapid start-up from low power modes

- Provides a back-up clock in the event of PLL or External Oscillator clock failure
- Offers an independent clock source for the Watchdog timer
- $\pm 5\%$ accuracy across voltage and temperature (after factory trimming)
- Trimming registers to support frequency adjustment with in-application calibration

1.6.20 Periodic Interrupt Timer module (PIT)

The PIT features the following:

- 4 general purpose interrupt timers
- Up to 2 dedicated interrupt timers for triggering ADC conversions
- 32-bit counter resolution
- Clocked by system clock frequency
- 32-bit counter for Real Time Interrupt, clocked from main external oscillator

1.6.21 Real Time Counter (RTC)

Real Timer Counter supports wake-up from Low Power modes or Real Time Clock generation

- Configurable resolution for different timeout periods
 - 1 s resolution for >1 hour period
 - 1 ms resolution for 2 second period
- Selectable clock sources from external 32 KHz crystal, external 4–16 MHz crystal, internal 128 kHz RC oscillator or divided internal 16 MHz RC oscillator

1.6.22 System Timer Module (STM)

The STM is a 32-bit timer designed to support commonly required system and application software timing functions. The STM includes a 32-bit up counter and four 32-bit compare channels with a separate interrupt source for each channel. The counter is driven by the system clock divided by an 8-bit prescale value (1 to 256).

- One 32-bit up counter with 8-bit prescaler
- Four 32-bit compare channels
- Independent interrupt source for each channel
- Counter can be stopped in debug mode

1.6.23 Software Watchdog Timer (SWT)

The Watchdog features the following:

- Watchdog supporting software activation or enabled out of Reset
- Supports normal or windowed mode
- Watchdog timer value writable once after reset
- Watchdog supports optional halting during low power modes
- Configurable response on timeout: reset, interrupt, or interrupt followed by reset
- Selectable clock source for main system clock or internal 16 MHz RC oscillator clock

1.6.24 Display Control Unit (DCU)

The DCU is a display controller designed to drive TFT LCD displays capable of driving up to WQVGA resolution screens with 16 layers and 4 planes with real time alpha-blending.

The DCU generates all the necessary signals required to drive the display: up to 24-bit RGB data bus, Pixel Clock, Data Enable, Horizontal-Sync and Vertical-Sync.

Internal memory resource of the MPC5606S allows to easily handle complex graphics contents (pictures, icons, languages, fonts) on a color TFT panel in up to Wide Quarter Video Graphics Array (WQVGA) sizes. All the data fetches from internal and/or external memory are performed by the internal four-channel DMA of the DCU providing a high speed/low latency access to the system backbone.

Control Descriptors (CDs) associated with each layer enable effective merging of different resolutions into one plane to optimize use of internal memory buffers. A layer may be constructed from graphic content of various resolutions including 1bpp, 2bpp, 4bpp, 8bpp, 16bpp, 24bpp and 24bpp+alpha. The ability of the DCU to handle input data in resolutions as low as 1bpp, 2bpp and 4bpp enables a highly efficient use of internal memory resources of the MPC5606S. A special tiled mode can be enabled on any of the 16 layers to repeat a pattern optimizing graphic memory usage.

A hardware cursor can be managed independently of the layers at blending level increasing the efficient use of the internal DCU resources.

To secure the content of all critical information to be displayed, a safety mode can be activated to check the integrity of critical data along the whole system data path from the memory to the TFT pads.

The DCU features the following:

- Display color depth: up to 24 bpp
- Generation of all RGB and control signals for TFT
- Four-plane blending
- Maximum number of Input Layers: 16 (fixed priority)
- Dynamic Look-Up-Table (Color and Gamma Look-Up)
- α -blending range: up to 256 levels
- Transparency Mode
- Gamma Correction
- Tiled mode on all the layers
- Hardware Cursor
- Critical display content integrity monitoring for Functional Safety support
- Internal Direct Memory Access (DMA) module to transfer data from internal and / or external memory.

1.6.25 Parallel Data Interface (PDI)

The PDI is a digital interface used to receive external digital video or graphic content into the DCU.

The PDI input is directly injected into the DCU background plane FIFO. When the PDI is activated, all the DCU synchronization is extracted from the external video stream to guarantee the synchronization of the two video sources.

The PDI can be used to:

- Connect a Video Camera output directly to the PDI
- Connect a secondary display driver as slave with a minimum of extra cost
- Connect a device gathering various Video sources
- Provide flexibility to allow the DCU to be used in slave mode (external synchronization)

The PDI features the following:

- Supported color modes:

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- 8-bit color multiplexed
- RGB565
- 16-bit/18-bit RAW color
- Supported synchronization modes:
 - Embedded ITU-R BT.656-4 (RGB565 mode 2)
 - HSYNC, VSYNC
 - Data Enable
- Direct interface with DCU background plane FIFO
- Synchronization generation for the DCU

1.6.26 Liquid Crystal Display (LCD) driver

The LCD driver module has two configurations allowing a maximum of 160 or 228 LCD segments:

- Up to 40 frontplane drivers and 4 backplane drivers
- Up to 38 frontplane drivers and 6 backplane drivers

Each segment is controlled and can be masked by a corresponding bit in the LCD RAM.

Four to six multiplex modes (1/1, 1/2, 1/3, 1/4, 1/5, 1/6 duty), and three bias (1/1, 1/2, 1/3) methods are available. All frontplane and backplane pins can be multiplexed with other port functions.

The LCD driver module features the following:

- Programmable frame clock generator from different clock sources:
 - System clock
 - Internal RC oscillator
- Programmable bias voltage level selector
- On-chip generation of all output voltage levels
 - LCD voltage reference taken from main 5V supply
- LCD RAM – contains the data to be displayed on the LCD
 - Data can be read from or written to the display RAM at any time
- End of Frame interrupt:
 - To optimize the refresh of the data without visual artefact
 - Selectable number of frames between each interrupt
- Contrast adjustment using programmable internal voltage reference
- Remapping capability of 4 or 6 backplanes with frontplanes;
 - To increase pin selection flexibility
- In low power modes, the LCD operation can be suspended under software control. The LCD can also operate in low power modes, clocked by the internal 128 kHz IRC or external 32 KHz crystal oscillator
- Selectable output current boost during transitions

1.6.27 Stepper Motor Controller (SMC)

The SMC module is a PWM motor controller suitable to drive instruments in a cluster configuration or any other loads requiring a PWM signal. The motor controller has twelve PWM channels associated with two pins each (24 pins in total).

The SMC module includes the following features:

- 10/11-bit PWM counter
- 11-bit resolution with selectable PWM dithering function

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- Left, right, or center aligned PWM
- Output slew rate control
- Output Short Circuit Detection

This module is suited for, but not limited to, driving small stepper and air core motors used in instrumentation applications. This module can be used for other motor control or PWM applications that match the frequency, resolution, and output drive capabilities of the module.

1.6.28 Stepper Stall Detect (SSD)

The stepper stall detector (SSD) module provides a circuit to measure and integrate the induced voltage on the non-driven coil of a stepper motor using full steps when the gauge pointer is returning to zero (RTZ).

The SSD module features the following:

- Programmable full step state
- Programmable integration polarity
- Blanking (recirculation) state
- 16-bit integration accumulator register
- 16-bit modulus down counter with interrupt

1.6.29 Sound Generation Logic (SGL)

The SGL has two modes of operation:

- Amplitude modulated PWM mode for low cost buzzers using any two eMIOS channels:
 - Monophonic signal with amplitude control
 - 8-bit amplitude resolution
 - Ability to mix any two eMIOS channels.
 - Requires simple external RC lowpass filter
- Digital sample mode for higher quality sound using one eMIOS channel and eDMA
 - Up to 10-bit audio amplitude resolution
 - Polyphonic sound synthesis
 - Playback of sample based waveforms
 - Text-to-speech possibility
 - Requires external lowpass filter

1.6.30 IEEE 1149.1 JTAG Controller (JTAGC)

JTAGC features the following:

- Backward compatible to standard JTAG IEEE 1149.1-2001 test access port (TAP) interface
- Support for boundary scan testing

1.6.31 Nexus Development Interface (NDI)

Nexus features the following:

- Per IEEE-ISTO 5001-2003
- Nexus 2 Plus features supported
 - Static debug
 - Watchpoint messaging

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- Ownership trace messaging
- Program trace messaging
- Real time read/write of any internally memory mapped resources through JTAG pins
- Overrun control, which selects whether to stall before Nexus overruns or keep executing and allow overwrite of information
- Watchpoint triggering, watchpoint triggers program tracing
- Configured via the IEEE 1149.1 (JTAG) port
- Nexus Auxiliary port supported on the 176 LQFP and 208-pin BGA package FOR DEVELOPMENT ONLY
 - Narrow Auxiliary Nexus port supporting support trace, with 2 MDO pins
 - Wide Auxiliary Nexus port supporting higher bandwidth trace, with 4 MDO pins

2 Pinout and signal descriptions

2.1 144 LQFP package pinouts

This section shows the pinouts for the 144-pin LQFP packages.

WARNING

Any pins labeled “NC” must not be connected to any external circuit.

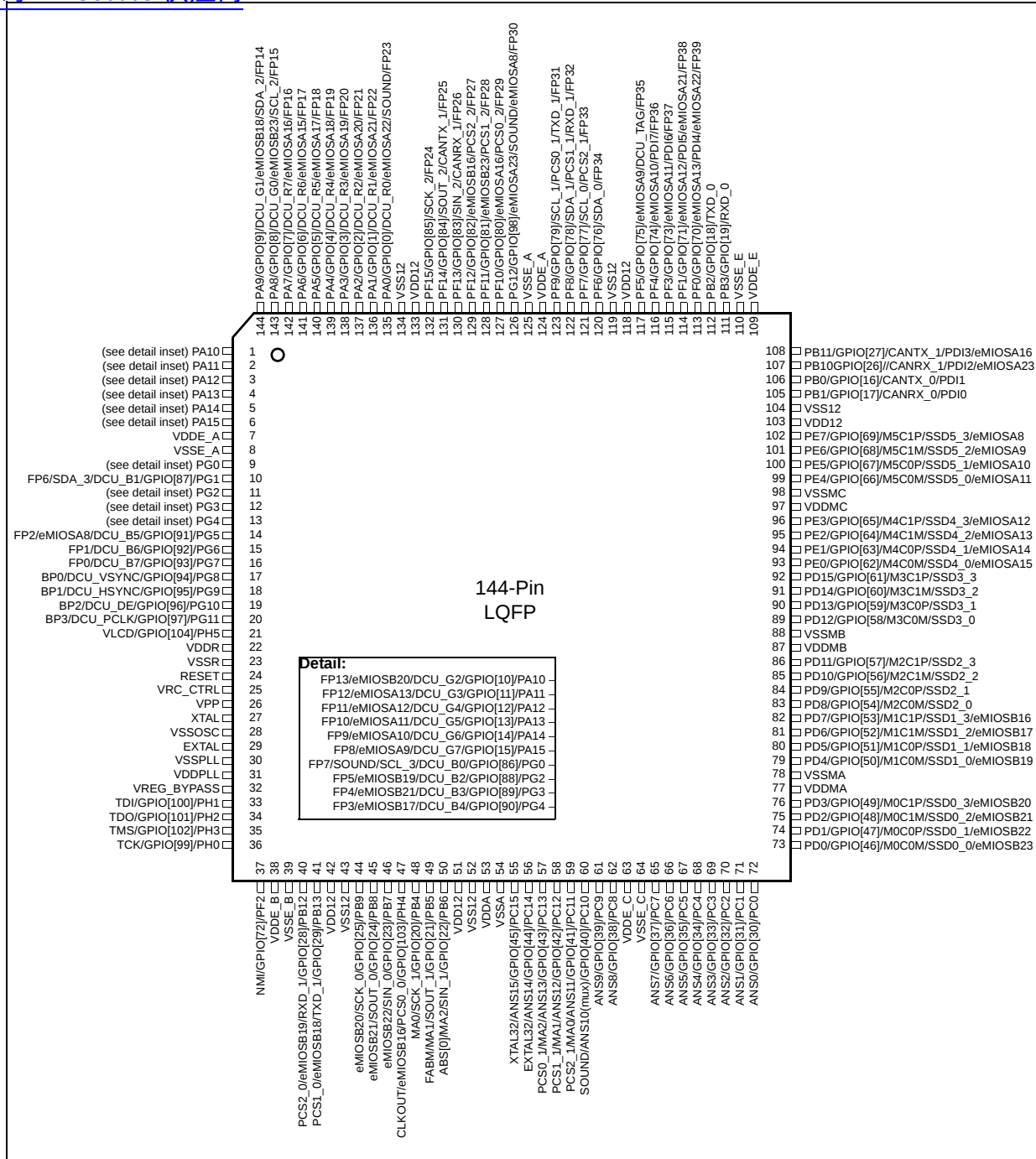
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Figure 2. 144-pin LQFP pinout for MPC5606S



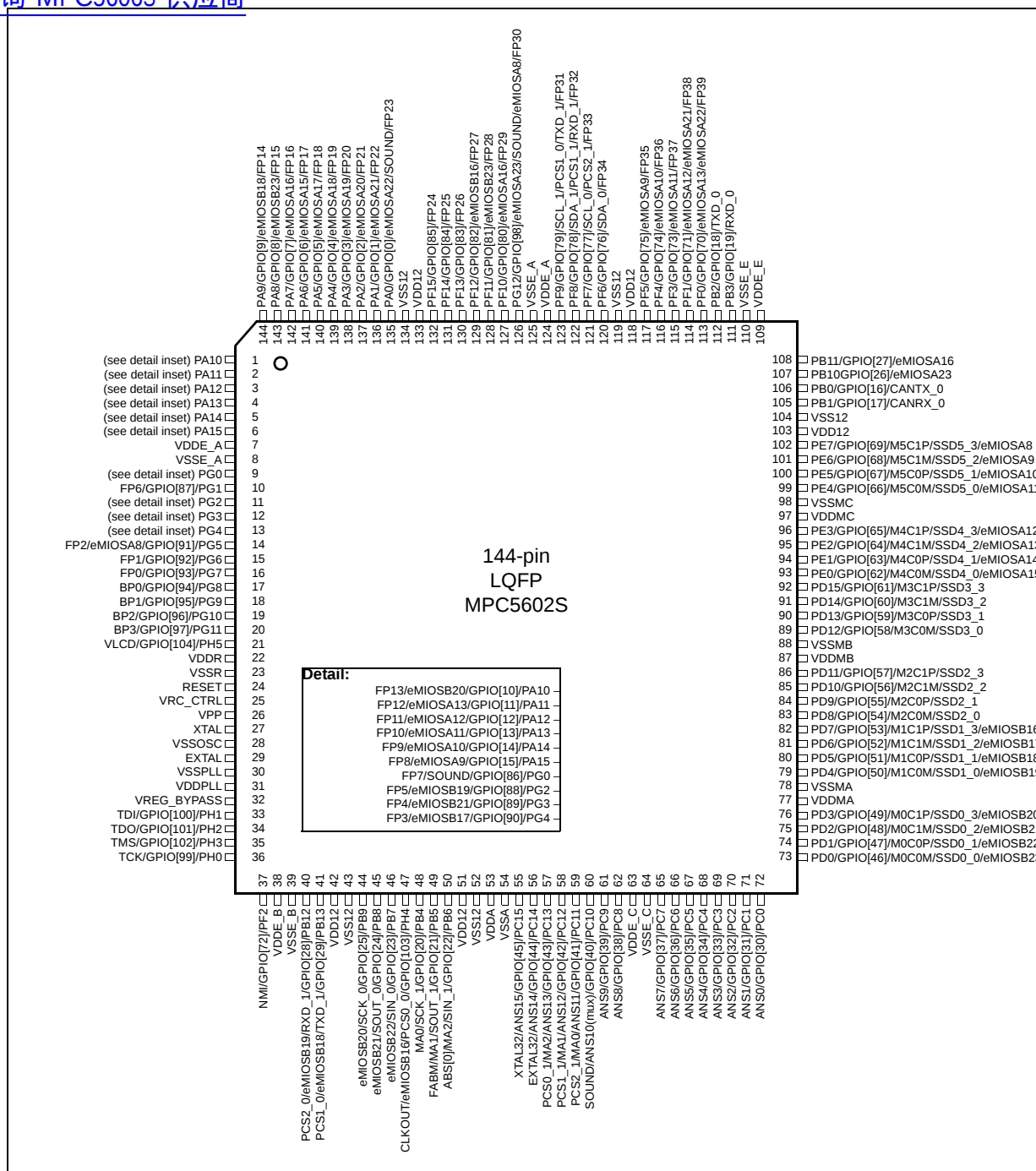
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Figure 4. 144-pin LQFP pinout for MPC5602S

2.2 176 LQFP package pinout

Figure 5 shows the pinout for the 176-pin LQFP package.

WARNING

Any pins labeled “NC” must not be connected to any external circuit.

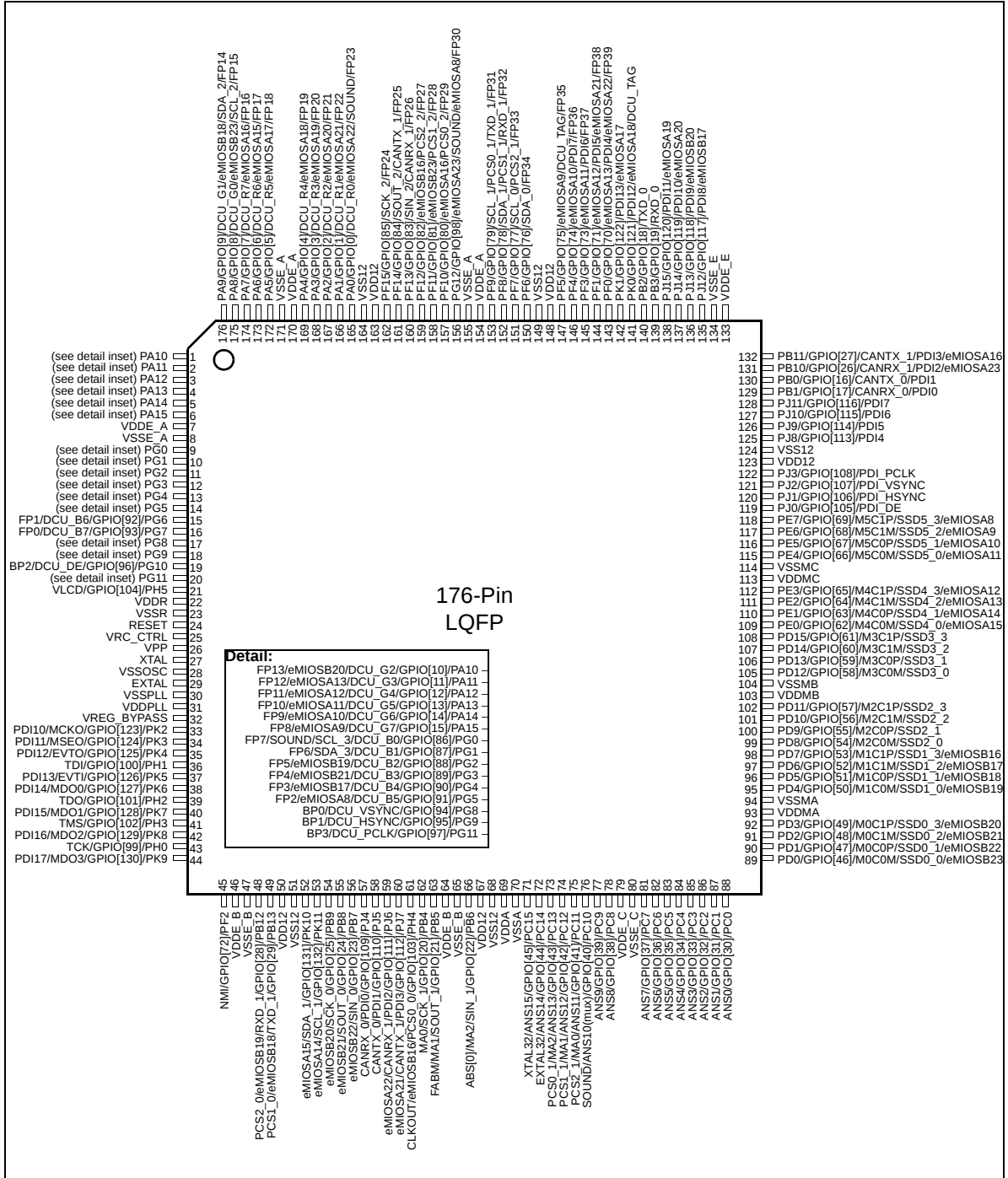


Figure 5. 176-pin LQFP Pinout

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2.3 208 MAPBGA package ballmap

Figure 6 shows the ballmap for the 208-pin BGA package.

WARNING

Any pins labeled "NC" must not be connected to any external circuit.

	1	2	3	4	5	6	7	8	9	10	11	12	13	14	15	16
A	PA0	PJ0	PJ1	PJ3	PJ5	PJ7	PJ14	PF0	PF5	PK9	PK5	NC	NC	PF10	PF11	PF12
B	PA1	VDDE_A	PJ2	PJ4	PJ6	PJ8	PJ15	PF1	PF6	NC	PK6	PK2	NC	NC	VDDE_E	PF13
C	PA2	PA3	VDDE_A	PJ9	PJ10	PJ12	PK0	PF3	PF7	NC	PK7	PK3	NC	VDDE_E	NC	PF14
D	PA4	PA5	PG0	VDD12	PJ11	PJ13	PK1	PF4	VDD12	PG12	PK8	PK4	VDD12	NC	NC	PF15
E	PA6	PA7	PG1	PG2									NC	NC	NC	NC
F	PA8	PA9	PG3	PG4									NC	NC	NC	NC
G	PA10	PA11	PG5	PG6				VSS	VSS	VSS			NC	PE7	PE1	NC
H	PA12	PA13	PA15	PG7				VSS	VSS	VSS			PE5	PE6	VDDMC	VSSMC
J	RESET	PA14	PG8	PG10				VSS	VSS	VSS			PE4	PE2	PE0	PD8
K	EXTAL	VDDE_A	PG9	PG11				VSS	VSS	VSS			PE3	PD13	PD9	PD7
L	VSSPLL	VDDPLL	NMI/PF2	MDO3									PD15	PD12	VDDMB	VSSMB
M	XTAL	VPP	PH3	VREG BYPASS									PD14	PD11	PD5	PD6
N	VDDR	VLCD	PH2	VDD12	PK11	PK10	PB8	PB5	PC13	PC9	PC6	PB11	VDDMA	PD10	PD4	PD3
P	VRC_CTRL	PH1	VDDE_B	MDO2	MDO1	PB13	PB7	PB4	PC12	PC8	PC5	PC3	PB10	NC	PD2	PD1
R	PH0	VDDE_B	EVTO	PF9	PH4	PB12	PB6	PC15	PC11	PC7	PC4	PC2	PB3	PB2	VDDE_B	PD0
T	MCKO	MSEO	EVTI	PF8	MDO0	PB9	VDDE_C	PC14	PC10	VSSA	VDDA	PC1	PC0	PB1	PB0	VSSMA

Figure 6. 208-pin MAPBGA pinout

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2.4 Pad configuration during reset phases

All pads have a fixed configuration under reset.

During the power-up phase, all pads are forced to tristate.

After power-up phase, all pads are floating with the following exceptions:

- PB[5] (FAB) is pulldown. Without external strong pullup the device starts fetching from flash.
- RESET pad is driven low. This is released only after PHASE2 reset completion.
- Main oscillator pads (EXTAL, XTAL) are tristate.
- Nexus output pads (MDO[n], MCKO, EVTO, MSEO) are forced to output.
- The following pads are pullup:
 - PB[6]
 - PH[0]
 - PH[1]
 - PH[3]
 - EVTI

2.5 Voltage supply pins

Voltage supply pins are used to provide power to the device. Two dedicated pins are used for 1.2 V regulator stabilization.

There is a preferred power-up sequence for devices in the MPC5606S family. That sequence is described in the following paragraphs.

Broadly, the supply voltages can be grouped as follows:

- VREG HV supply (V_{DDR})
- Generic IO supply or noise free supply
 - V_{DDA}
 - V_{DDE_A}
 - V_{DDE_B}
 - V_{DDE_C}
 - V_{DDE_E}
 - V_{DDMA}
 - V_{DDMB}
 - V_{DDMC}
 - V_{DDPLL}
- LV supply (V_{DD12})

The preferred order of ramp up is as follows:

1. Generic IO supply or noise free supply
2. VREG HV supply (V_{DDR} - Should be the last HV supply to ramp up. It is also OK if all HV supplies including V_{DDR} ramp up together)
3. LV supply

The reason for following this sequence is to ensure that when VREG releases its LVDs, the I/O and other HV segments are powered properly. This is important because the MPC5606S does not monitor LVDs on I/O HV supplies.

Table 5. Voltage supply pin descriptions

Supply Pin	Function	Pin number	
		144 LQFP	176 LQFP
VDD12 ¹	1.2 V core supply	42, 51, 103, 118, 133	50, 67, 123, 148, 163
VDDA	3.3 V/5 V ADC supply source	53	69
VDDE_A	3.3 V/5 V I/O supply	7, 124	7, 154, 170
VDDE_B	3.3 V/5 V I/O supply	38	46, 64
VDDE_C	3.3 V/5 V I/O supply	63	79
VDDE_E	3.3 V/5 V I/O supply	109	133
VDDMA ²	Motor pads 5 V supply	77	93
VDDMB ²	Motor pads 5 V supply	87	103
VDDMC ²	Motor pads 5 V supply	97	113
VDDPLL	1.2 V PLL supply	31	31
VDDR	VREG reg supply	22	22
VPP ³	9 V - 12 V flash test analog write signal	26	26
VSS	Digital ground	8, 23, 39, 43, 52, 64, 104, 110, 119, 125, 134	8, 23, 47, 51, 68, 80, 124, 134, 149, 155, 164, 65, 171
VSSA	ADC ground	54	70
VSSMA	Stepper motor ground	78	94
VSSMB	Stepper motor ground	88	104
VSSMC	Stepper motor ground	98	114
VSSOSC	MHz oscillator ground	28	28
VSSPLL	PLL ground	30	30

¹ Decoupling capacitors must be connected between these pins and the nearest V_{SS12} pin.

² All stepper motor supplies need to be at same level (3.3 V or 5 V).

³ This signal needs to be connected to ground during normal operation.

2.6 Pad types

The pads available for system pins and functional port pins are described in:

- The port pin summary table
- The pad type descriptions
- The description of the pad configuration registers in the SIUL chapter of the device reference manual
- The device data sheet

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2.7 System pins

The system pins are listed in [Table 6](#).

Table 6. System pin descriptions

System pin	Function	I/O direction	Pad type	RESET config	Pin No.		
					144 LQFP	176 LQFP	208 MAPBGA
RESET	Bidirectional reset with Schmitt-Trigger characteristics and noise filter.	I/O	M	Input, weak pull up	24	24	J1
EXTAL	Analog output of the oscillator amplifier circuit. Input for the clock generator in bypass mode.		X	-	29	29	K1
XTAL	Analog input of the oscillator amplifier circuit. Needs to be grounded if oscillator bypass mode is used.	I	X	-	27	27	M1
VRC_CTRL	VREG ballast control gain				25	25	P1
VREG_BYPASS ¹	Pin used for factory testing	I	X	-	32	32	M1

¹ VREG_BYPASS should be pulled down externally.

2.8 Debug pins

The debug pins are listed in [Table 7](#).

Table 7. Debug pin descriptions

Debug pin	Function	Pad type	I/O direction	RESET config	Pin number		
					144 LQFP	176 LQFP ₁	208 MAPBGA
EVTI	Nexus event input	M1	I/O	Input, Pull Up	—	37	T3
EVTO	Nexus event output	M1	I/O	Input, Pull Up	—	35	R3
MCKO	Nexus message clock output	F	I/O	Input, Pull Up	—	33	T1
MDO0	Nexus message clock output	M1	I/O	Input, Pull Up	—	38	T5

Table 7. Debug pin descriptions (continued)

Debug pin	Function	Pad type	I/O direction	RESET config	Pin number		
					144 LQFP	176 LQFP ¹	208 MAPBGA
MDO1	Nexus message clock output	M1	I/O	Input, Pull Up	—	40	P5
MDO2	Nexus message clock output	M1	I/O	Input, Pull Up	—	42	P4
MDO3	Nexus message clock output	M1	I/O	Input, Pull Up	—	44	L4
MSEO	Nexus message clock output	M1	I/O	Input, Pull Up	—	34	T2

¹ On the 176-pin package, the debug pins are multiplexed with other pins. The multiplexing is described in the port pin summary table.

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2.9 Port pin summary

The functional port pins are listed in Table 8.

Table 8. Port pin summary

Port pin	PCR register	Alternate function ¹	Function	Special function ²	Peripheral ³	I/O direction	Pad type ⁴	RESET config. ⁵	Pin number		
									144 LQFP	176 LQFP	208 MAPBGA
PA[0]	PCR[0]	Option 0 Option 1 Option 2 Option 3	GPIO[0] DCU_R0 eMIOA[22] SOUND	FP23	SIUL DCU PWM/Timer Sound	I/O	M1	None, None	135	165	A1
PA[1]	PCR[1]	Option 0 Option 1 Option 2 Option 3	GPIO[1] DCU_R1 eMIOA[21] —	FP22	SIUL DCU PWM/Timer —	I/O	M1	None, None	136	166	B1
PA[2]	PCR[2]	Option 0 Option 1 Option 2 Option 3	GPIO[2] DCU_R2 eMIOA[20] —	FP21	SIUL DCU PWM/Timer —	I/O	M1	None, None	137	167	C1
PA[3]	PCR[3]	Option 0 Option 1 Option 2 Option 3	GPIO[3] DCU_R3 eMIOA[19] —	FP20	SIUL DCU PWM/Timer —	I/O	M1	None, None	138	168	C2
PA[4]	PCR[4]	Option 0 Option 1 Option 2 Option 3	GPIO[4] DCU_R4 eMIOA[18] —	FP19	SIUL DCU PWM/Timer —	I/O	M1	None, None	139	169	D1
PA[5]	PCR[5]	Option 0 Option 1 Option 2 Option 3	GPIO[5] DCU_R5 eMIOA[17] —	FP18	SIUL DCU PWM/Timer —	I/O	M1	None, None	140	172	D2
PA[6]	PCR[6]	Option 0 Option 1 Option 2 Option 3	GPIO[6] DCU_R6 eMIOA[15] —	FP17	SIUL DCU PWM/Timer —	I/O	M1	None, None	141	173	E1

Table 8. Port pin summary (continued)

Port pin	PCR register	Alternate function ¹	Function	Special function ²	Peripheral ³	I/O direction	Pad type ⁴	RESET config. ⁵	Pin number		
									144 LQFP	176 LQFP	208 MAPBGA
PA[7]	PCR[7]	Option 0 Option 1 Option 2 Option 3	GPIO[7] DCU_R7 eMIOA[16] —	FP16	SIUL DCU PWM/Timer —	I/O	M1	None, None	142	174	E2
PA[8]	PCR[8]	Option 0 Option 1 Option 2 Option 3	GPIO[8] DCU_G0 eMIOB[23] SCL_2	FP15	SIUL DCU PWM/Timer I ² C_2	I/O	M1	None, None	143	175	F1
PA[9]	PCR[9]	Option 0 Option 1 Option 2 Option 3	GPIO[9] DCU_G1 eMIOB[18] SDA_2	FP14	SIUL DCU PWM/Timer I ² C_2	I/O	M1	None, None	144	176	F2
PA[10]	PCR[10]	Option 0 Option 1 Option 2 Option 3	GPIO[10] DCU_G2 eMIOB[20] —	FP13	SIUL DCU PWM/Timer —	I/O	M1	None, None	1	1	G1
PA[11]	PCR[11]	Option 0 Option 1 Option 2 Option 3	GPIO[11] DCU_G3 eMIOA[13] —	FP12	SIUL DCU PWM/Timer —	I/O	M1	None, None	2	2	G2
PA[12]	PCR[12]	Option 0 Option 1 Option 2 Option 3	GPIO[12] DCU_G4 eMIOA[12] —	FP11	SIUL DCU PWM/Timer —	I/O	M1	None, None	3	3	H1
PA[13]	PCR[13]	Option 0 Option 1 Option 2 Option 3	GPIO[13] DCU_G5 eMIOA[11] —	FP10	SIUL DCU PWM/Timer —	I/O	M1	None, None	4	4	H2
PA[14]	PCR[14]	Option 0 Option 1 Option 2 Option 3	GPIO[14] DCU_G6 eMIOA[10] —	FP9	SIUL DCU PWM/Timer —	I/O	M2	None, None	5	5	J2

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Table 8. Port pin summary (continued)

Port pin	PCR register	Alternate function ¹	Function	Special function ²	Peripheral ³	I/O direction	Pad type ⁴	RESET config. ⁵	Pin number		
									144 LQFP	176 LQFP	208 MAPBGA
PA[15]	PCR[15]	Option 0 Option 1 Option 2 Option 3	GPIO[15] DCU_G7 eMIOA[9] —	FP8	SIUL DCU PWM/Timer —	I/O	M1	None, None	6	6	H3
PB[0]	PCR[16]	Option 0 Option 1 Option 2 Option 3	GPIO[16] CANTX_0 PDI1 —	—	SIUL FlexCAN_0 PDI —	I/O	M1	None, None	106	130	T15
PB[1]	PCR[17]	Option 0 Option 1 Option 2 Option 3	GPIO[17] CANRX_0 PDI0 —	—	SIUL FlexCAN_0 PDI —	I/O	S	None, None	105	129	T14
PB[2]	PCR[18]	Option 0 Option 1 Option 2 Option 3	GPIO[18] TXD_0 — —	—	SIUL LINFlex_0 — —	I/O	S	None, None	112	140	R14
PB[3]	PCR[19]	Option 0 Option 1 Option 2 Option 3	GPIO[19] RXD_0 — —	—	SIUL LINFlex_0 — —	I/O	S	None, None	111	139	R13
PB[4]	PCR[20]	Option 0 Option 1 Option 2 Option 3	GPIO[20] SCK_1 MA0 —	—	SIUL DSPL_1 ADC —	I/O	M1	None, None	48	62	P8
PB[5]	PCR[21]	Option 0 Option 1 Option 2 Option 3	GPIO[21] SOUT_1 MA1 FABM	—	SIUL DSPL_1 ADC Control	I/O	M1	Input, Pull-down	49	63	N8
PB[6]	PCR[22]	Option 0 Option 1 Option 2 Option 3	GPIO[22] SIN_1 MA2 ABS[0]	—	SIUL DSPL_1 ADC Control	I/O	S	Input, Pullup	50	66	R7

Table 8. Port pin summary (continued)

Port pin	PCR register	Alternate function ¹	Function	Special function ²	Peripheral ³	I/O direction	Pad type ⁴	RESET config. ⁵	Pin number		
									144 LQFP	176 LQFP	208 MAPBGA
PB[7]	PCR[23]	Option 0 Option 1 Option 2 Option 3	GPIO[23] SIN_0 eMIOSB[22] —	—	SIUL DSPL_0 PWM/Timer —	I/O	S	None, None	46	56	P7
PB[8]	PCR[24]	Option 0 Option 1 Option 2 Option 3	GPIO[24] SOUT_0 eMIOSB[21] —	—	SIUL DSPL_0 PWM/Timer —	I/O	M1	None, None	45	55	N7
PB[9]	PCR[25]	Option 0 Option 1 Option 2 Option 3	GPIO[25] SCK_0 eMIOSB[20] —	—	SIUL DSPL_0 PWM/Timer —	I/O	M1	None, None	44	54	T6
PB[10]	PCR[26]	Option 0 Option 1 Option 2 Option 3	GPIO[26] CANRX_1 PDI2 eMIOSA[23]	—	SIUL FlexCAN_1 PDI PWM/Timer	I/O	S	None, None	107	131	P13
PB[11]	PCR[27]	Option 0 Option 1 Option 2 Option 3	GPIO[27] CANTX_1 PDI3 eMIOSA[16]	—	SIUL FlexCAN_1 PDI PWM/Timer	I/O	M1	None, None	108	132	N12
PB[12]	PCR[28]	Option 0 Option 1 Option 2 Option 3	GPIO[28] RXD_1 eMIOSB[19] PCS2_0	—	SIUL LINFlex_1 PWM/Timer DSPL_0	I/O	S	None, None	40	48	R6
PB[13]	PCR[29]	Option 0 Option 1 Option 2 Option 3	GPIO[29] TXD_1 eMIOSB[18] PCS1_0	—	SIUL LINFlex_1 PWM/Timer DSPL_0	I/O	S	None, None	41	49	P6
PB[14]	—	—	Reserved	—	—	—	—	—	—	—	—
PB[15]	—	—	Reserved	—	—	—	—	—	—	—	—
PC[0]	PCR[30]	Option 0 Option 1 Option 2 Option 3	GPIO[30] — — —	ANS[0]	SIUL — — —	I/O	J	None, None	72	88	T13

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Table 8. Port pin summary (continued)

Port pin	PCR register	Alternate function ¹	Function	Special function ²	Peripheral ³	I/O direction	Pad type ⁴	RESET config. ⁵	Pin number		
									144 LQFP	176 LQFP	208 MAPBGA
PC[1]	PCR[31]	Option 0 Option 1 Option 2 Option 3	GPIO[31] — — —	ANS[1]	SIUL — — —	I/O	J	None, None	71	87	T12
PC[2]	PCR[32]	Option 0 Option 1 Option 2 Option 3	GPIO[32] — — —	ANS[2]	SIUL — — —	I/O	J	None, None	70	86	R12
PC[3]	PCR[33]	Option 0 Option 1 Option 2 Option 3	GPIO[33] — — —	ANS[3]	SIUL — — —	I/O	J	None, None	69	85	P12
PC[4]	PCR[34]	Option 0 Option 1 Option 2 Option 3	GPIO[34] — — —	ANS[4]	SIUL — — —	I/O	J	None, None	68	84	R11
PC[5]	PCR[35]	Option 0 Option 1 Option 2 Option 3	GPIO[35] — — —	ANS[5]	SIUL — — —	I/O	J	None, None	67	83	P11
PC[6]	PCR[36]	Option 0 Option 1 Option 2 Option 3	GPIO[36] — — —	ANS[6]	SIUL — — —	I/O	J	None, None	66	82	N11
PC[7]	PCR[37]	Option 0 Option 1 Option 2 Option 3	GPIO[37] — — —	ANS[7]	SIUL — — —	I/O	J	None, None	65	81	R10
PC[8]	PCR[38]	Option 0 Option 1 Option 2 Option 3	GPIO[38] — — —	ANS[8]	SIUL — — —	I/O	J	None, None	62	78	P10

Table 8. Port pin summary (continued)

Port pin	PCR register	Alternate function ¹	Function	Special function ²	Peripheral ³	I/O direction	Pad type ⁴	RESET config. ⁵	Pin number		
									144 LQFP	176 LQFP	208 MAPBGA
PC[9]	PCR[39]	Option 0 Option 1 Option 2 Option 3	GPIO[39] — — —	ANS[9]	SIUL — — —	I/O	J	None, None	61	77	N10
PC[10]	PCR[40]	Option 0 Option 1 Option 2 Option 3	GPIO[40] — SOUND —	ANS[10]	SIUL — SGL —	I/O	J	None, None	60	76	T9
PC[11]	PCR[41]	Option 0 Option 1 Option 2 Option 3	GPIO[41] — MA0 PCS2_1	ANS[11]	SIUL — ADC DSPI_1	I/O	J	None, None	59	75	R9
PC[12]	PCR[42]	Option 0 Option 1 Option 2 Option 3	GPIO[42] — MA1 PCS1_1	ANS[12]	SIUL — ADC DSPI_1	I/O	J	None, None	58	74	P9
PC[13]	PCR[43]	Option 0 Option 1 Option 2 Option 3	GPIO[43] — MA2 PCS0_1	ANS[13]	SIUL — ADC DSPI_1	I/O	J	None, None	57	73	N9
PC[14]	PCR[44]	Option 0 Option 1 Option 2 Option 3	GPIO[44] — — —	ANS[14] EXTAL32	SIUL — — —	I/O	J	None, None	56	72	T8
PC[15]	PCR[45]	Option 0 Option 1 Option 2 Option 3	GPIO[45] — — —	ANS[15] XTAL32	SIUL — — —	I/O	J	None, None	55	71	R8
PD[0]	PCR[46]	Option 0 Option 1 Option 2 Option 3	GPIO[46] MOCOM SSD0_0 eMIOSB[23]	—	SIUL SMC SSD PWM/Timer	I/O	SMD	None, None	73	89	R16

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Table 8. Port pin summary (continued)

Port pin	PCR register	Alternate function ¹	Function	Special function ²	Peripheral ³	I/O direction	Pad type ⁴	RESET config. ⁵	Pin number		
									144 LQFP	176 LQFP	208 MAPBGA
PD[1]	PCR[47]	Option 0 Option 1 Option 2 Option 3	GPIO[47] M0C0P SSD0_1 eMIOSB[22]	—	SIUL SMC SSD PWM/Timer	I/O	SMD	None, None	74	90	P16
PD[2]	PCR[48]	Option 0 Option 1 Option 2 Option 3	GPIO[48] M0C1M SSD0_2 eMIOSB[21]	—	SIUL SMC SSD PWM/Timer	I/O	SMD	None, None	75	91	P15
PD[3]	PCR[49]	Option 0 Option 1 Option 2 Option 3	GPIO[49] M0C1P SSD0_3 eMIOSB[20]	—	SIUL SMC SSD PWM/Timer	I/O	SMD	None, None	76	92	N16
PD[4]	PCR[50]	Option 0 Option 1 Option 2 Option 3	GPIO[50] M1C0M SSD1_0 eMIOSB[19]	—	SIUL SMC SSD PWM/Timer	I/O	SMD	None, None	79	95	N15
PD[5]	PCR[51]	Option 0 Option 1 Option 2 Option 3	GPIO[51] M1C0P SSD1_1 eMIOSB[18]	—	SIUL SMC SSD PWM/Timer	I/O	SMD	None, None	80	96	M15
PD[6]	PCR[52]	Option 0 Option 1 Option 2 Option 3	GPIO[52] M1C1M SSD1_2 eMIOSB[17]	—	SIUL SMC SSD PWM/Timer	I/O	SMD	None, None	81	97	M16
PD[7]	PCR[53]	Option 0 Option 1 Option 2 Option 3	GPIO[53] M1C1P SSD1_3 eMIOSB[16]	—	SIUL SMC SSD PWM/Timer	I/O	SMD	None, None	82	98	K16
PD[8]	PCR[54]	Option 0 Option 1 Option 2 Option 3	GPIO[54] M2C0M SSD2_0 —	—	SIUL SMC SSD —	I/O	SMD	None, None	83	99	J16

Table 8. Port pin summary (continued)

Port pin	PCR register	Alternate function ¹	Function	Special function ²	Peripheral ³	I/O direction	Pad type ⁴	RESET config. ⁵	Pin number		
									144 LQFP	176 LQFP	208 MAPBGA
PD[9]	PCR[55]	Option 0 Option 1 Option 2 Option 3	GPIO[55] M2C0P SSD2_1 —	—	SIUL SMC SSD —	I/O	SMD	None, None	84	100	K15
PD[10]	PCR[56]	Option 0 Option 1 Option 2 Option 3	GPIO[56] M2C1M SSD2_2 —	—	SIUL SMC SSD —	I/O	SMD	None, None	85	101	N14
PD[11]	PCR[57]	Option 0 Option 1 Option 2 Option 3	GPIO[57] M2C1P SSD2_3 —	—	SIUL SMC SSD —	I/O	SMD	None, None	86	102	M14
PD[12]	PCR[58]	Option 0 Option 1 Option 2 Option 3	GPIO[58] M3C0M SSD3_0 —	—	SIUL SMC SSD —	I/O	SMD	None, None	89	105	L14
PD[13]	PCR[59]	Option 0 Option 1 Option 2 Option 3	GPIO[59] M3C0P SSD3_1 —	—	SIUL SMC SSD —	I/O	SMD	None, None	90	106	K14
PD[14]	PCR[60]	Option 0 Option 1 Option 2 Option 3	GPIO[60] M3C1M SSD3_2 —	—	SIUL SMC SSD —	I/O	SMD	None, None	91	107	M13
PD[15]	PCR[61]	Option 0 Option 1 Option 2 Option 3	GPIO[61] M3C1P SSD3_3 —	—	SIUL SMC SSD —	I/O	SMD	None, None	92	108	L13
PE[0]	PCR[62]	Option 0 Option 1 Option 2 Option 3	GPIO[62] M4C0M SSD4_0 eMIOA[15]	—	SIUL SMC SSD PWM/Timer	I/O	SMD	None, None	93	109	J15

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Table 8. Port pin summary (continued)

Port pin	PCR register	Alternate function ¹	Function	Special function ²	Peripheral ³	I/O direction	Pad type ⁴	RESET config. ⁵	Pin number		
									144 LQFP	176 LQFP	208 MAPBGA
PE[1]	PCR[63]	Option 0 Option 1 Option 2 Option 3	GPIO[63] M4C0P SSD4_1 eMIOA[14]	—	SIUL SMC SSD PWM/Timer	I/O	SMD	None, None	94	110	G15
PE[2]	PCR[64]	Option 0 Option 1 Option 2 Option 3	GPIO[64] M4C1M SSD4_2 eMIOA[13]	—	SIUL SMC SSD PWM/Timer	I/O	SMD	None, None	95	111	J14
PE[3]	PCR[65]	Option 0 Option 1 Option 2 Option 3	GPIO[65] M4C1P SSD4_3 eMIOA[12]	—	SIUL SMC SSD PWM/Timer	I/O	SMD	None, None	96	112	K13
PE[4]	PCR[66]	Option 0 Option 1 Option 2 Option 3	GPIO[66] M5C0M SSD5_0 eMIOA[11]	—	SIUL SMC SSD PWM/Timer	I/O	SMD	None, None	99	115	J13
PE[5]	PCR[67]	Option 0 Option 1 Option 2 Option 3	GPIO[67] M5C0P SSD5_1 eMIOA[10]	—	SIUL SMC SSD PWM/Timer	I/O	SMD	None, None	100	116	H13
PE[6]	PCR[68]	Option 0 Option 1 Option 2 Option 3	GPIO[68] M5C1M SSD5_2 eMIOA[9]	—	SIUL SMC SSD PWM/Timer	I/O	SMD	None, None	101	117	H14
PE[7]	PCR[69]	Option 0 Option 1 Option 2 Option 3	GPIO[69] M5C1P SSD5_3 eMIOA[8]	—	SIUL SMC SSD PWM/Timer	I/O	SMD	None, None	102	118	G14
PE[8]	—	—	Reserved	—	—	—	—	—	—	—	—
PE[9]	—	—	Reserved	—	—	—	—	—	—	—	—
PE[10]	—	—	Reserved	—	—	—	—	—	—	—	—
PE[11]	—	—	Reserved	—	—	—	—	—	—	—	—
PE[12]	—	—	Reserved	—	—	—	—	—	—	—	—

Table 8. Port pin summary (continued)

Port pin	PCR register	Alternate function ¹	Function	Special function ²	Peripheral ³	I/O direction	Pad type ⁴	RESET config. ⁵	Pin number		
									144 LQFP	176 LQFP	208 MAPBGA
PE[13]	—	—	Reserved	—	—	—	—	—	—	—	—
PE[14]	—	—	Reserved	—	—	—	—	—	—	—	—
PE[15]	—	—	Reserved	—	—	—	—	—	—	—	—
PF[0]	PCR[70]	Option 0 Option 1 Option 2 Option 3	GPIO[70] eMIOA[13] PDI4 eMIOA[22]	FP39	SIUL PWM/Timer PDI PWM/Timer	I/O	S	None, None	113	143	A8
PF[1]	PCR[71]	Option 0 Option 1 Option 2 Option 3	GPIO[71] eMIOA[12] PDI5 eMIOA[21]	FP38	SIUL PWM/Timer PDI PWM/Timer	I/O	S	None, None	114	144	B8
PF[2]	PCR[72]	Option 0 Option 1 Option 2 Option 3	GPIO[72] NMI — —	—	SIUL NMI — —	I/O	S	None, None	37	45	L3
PF[3]	PCR[73]	Option 0 Option 1 Option 2 Option 3	GPIO[73] eMIOA[11] PDI6 —	FP37	SIUL PWM/Timer PDI —	I/O	M1	None, None	115	145	C8
PF[4]	PCR[74]	Option 0 Option 1 Option 2 Option 3	GPIO[74] eMIOA[10] PDI7 —	FP36	SIUL PWM/Timer PDI —	I/O	M1	None, None	116	146	D8
PF[5]	PCR[75]	Option 0 Option 1 Option 2 Option 3	GPIO[75] eMIOA[9] DCU_TAG —	FP35	SIUL PWM/Timer DCU —	I/O	M1	None, None	117	147	A9
PF[6]	PCR[76]	Option 0 Option 1 Option 2 Option 3	GPIO[76] SDA_0 — —	FP34	SIUL I ² C_0 — —	I/O	S	None, None	120	150	B9

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Table 8. Port pin summary (continued)

Port pin	PCR register	Alternate function ¹	Function	Special function ²	Peripheral ³	I/O direction	Pad type ⁴	RESET config. ⁵	Pin number		
									144 LQFP	176 LQFP	208 MAPBGA
PF[7]	PCR[77]	Option 0 Option 1 Option 2 Option 3	GPIO[77] SCL_0 PCS2_1 —	FP33	SIUL I ² C_0 DSPI_1 —	I/O	S	None, None	121	151	C9
PF[8]	PCR[78]	Option 0 Option 1 Option 2 Option 3	GPIO[78] SDA_1 PCS1_1 RXD_1	FP32	SIUL I ² C_1 DSPI_1 LINFlex_1	I/O	S	None, None	122	152	T4
PF[9]	PCR[79]	Option 0 Option 1 Option 2 Option 3	GPIO[79] SCL_1 PCS0_1 TXD_1	FP31	SIUL I ² C_1 DSPI_1 LINFlex_1	I/O	S	None, None	123	153	R4
PF[10]	PCR[80]	Option 0 Option 1 Option 2 Option 3	GPIO[80] eMIOA[16] PCS0_2 —	FP29	SIUL PWM/Timer QuadSPI —	I/O	M1	None, None	127	157	A14
PF[11]	PCR[81]	Option 0 Option 1 Option 2 Option 3	GPIO[81] eMIOSB[23] IO2/PCS1_2 ⁶ —	FP28	SIUL PWM/Timer QuadSPI —	I/O	M1	None, None	128	158	A15
PF[12]	PCR[82]	Option 0 Option 1 Option 2 Option 3	GPIO[82] eMIOSB[16] IO3/PCS2_2 ⁶ —	FP27	SIUL PWM/Timer QuadSPI —	I/O	M1	None, None	129	159	A16
PF[13]	PCR[83]	Option 0 Option 1 Option 2 Option 3	GPIO[83] IO0/SIN_2 ⁶ CANRX_1 —	FP26	SIUL QuadSPI FlexCAN_1 —	I/O	M1	None, None	130	160	B16
PF[14]	PCR[84]	Option 0 Option 1 Option 2 Option 3	GPIO[84] IO1/SOUT_2 ⁶ CANTX_1 —	FP25	SIUL QuadSPI FlexCAN_1 —	I/O	M1	None, None	131	161	C16

Table 8. Port pin summary (continued)

Port pin	PCR register	Alternate function ¹	Function	Special function ²	Peripheral ³	I/O direction	Pad type ⁴	RESET config. ⁵	Pin number		
									144 LQFP	176 LQFP	208 MAPBGA
PF[15]	PCR[85]	Option 0 Option 1 Option 2 Option 3	GPIO[85] SCK_2 — —	FP24	SIUL QuadSPI — —	I/O	F	None, None	132	162	D16
PG[0]	PCR[86]	Option 0 Option 1 Option 2 Option 3	GPIO[86] DCU_B0 SCL_3 SOUND	FP7	SIUL DCU I ² C_3 SGL	I/O	M2	None, None	9	9	D3
PG[1]	PCR[87]	Option 0 Option 1 Option 2 Option 3	GPIO[87] DCU_B1 SDA_3 —	FP6	SIUL DCU I ² C_3 —	I/O	M1	None, None	10	10	E3
PG[2]	PCR[88]	Option 0 Option 1 Option 2 Option 3	GPIO[88] DCU_B2 eMIOSB[19] —	FP5	SIUL DCU PWM/Timer —	I/O	M2	None, None	11	11	E4
PG[3]	PCR[89]	Option 0 Option 1 Option 2 Option 3	GPIO[89] DCU_B3 eMIOSB[21] —	FP4	SIUL DCU PWM/Timer —	I/O	M1	None, None	12	12	F3
PG[4]	PCR[90]	Option 0 Option 1 Option 2 Option 3	GPIO[90] DCU_B4 eMIOSB[17] —	FP3	SIUL DCU PWM/Timer —	I/O	M2	None, None	13	13	F4
PG[5]	PCR[91]	Option 0 Option 1 Option 2 Option 3	GPIO[91] DCU_B5 eMIOSA[8] —	FP2	SIUL DCU PWM/Timer —	I/O	M1	None, None	14	14	G3
PG[6]	PCR[92]	Option 0 Option 1 Option 2 Option 3	GPIO[92] DCU_B6 — —	FP1	SIUL DCU — —	I/O	M2	None, None	15	15	G4

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Table 8. Port pin summary (continued)

Port pin	PCR register	Alternate function ¹	Function	Special function ²	Peripheral ³	I/O direction	Pad type ⁴	RESET config. ⁵	Pin number		
									144 LQFP	176 LQFP	208 MAPBGA
PG[7]	PCR[93]	Option 0 Option 1 Option 2 Option 3	GPIO[93] DCU_B7 — —	FP0	SIUL DCU — —	I/O	M1	None, None	16	16	H4
PG[8]	PCR[94]	Option 0 Option 1 Option 2 Option 3	GPIO[94] DCU_VSYNC — —	BP0	SIUL DCU — —	I/O	M2	Input, None	17	17	J3
PG[9]	PCR[95]	Option 0 Option 1 Option 2 Option 3	GPIO[95] DCU_HSYNC — —	BP1	SIUL DCU — —	I/O	M1	Input, None	18	18	K3
PG[10]	PCR[96]	Option 0 Option 1 Option 2 Option 3	GPIO[96] DCU_DE — —	BP2	SIUL DCU — —	I/O	M2	None, None	19	19	J4
PG[11]	PCR[97]	Option 0 Option 1 Option 2 Option 3	GPIO[97] DCU_PCLK — —	BP3	SIUL DCU — —	I/O	M1	None, None	20	20	K4
PG[12]	PCR[98]	Option 0 Option 1 Option 2 Option 3	GPIO[98] eMIOA[23] SOUND eMIOA[8]	FP30	SIUL PWM/Timer SGL PWM/Timer	I/O	S	None, None	126	156	D10
PG[13]	—	—	Reserved	—	—	—	—	—	—	—	—
PG[14]	—	—	Reserved	—	—	—	—	—	—	—	—
PG[15]	—	—	Reserved	—	—	—	—	—	—	—	—
PH[0] ⁷	PCR[99]	Option 0 Option 1 Option 2 Option 3	GPIO[99] TCK — —	—	SIUL JTAG — —	I/O	S	Input, Pullup	36	43	R1

Table 8. Port pin summary (continued)

Port pin	PCR register	Alternate function ¹	Function	Special function ²	Peripheral ³	I/O direction	Pad type ⁴	RESET config. ⁵	Pin number		
									144 LQFP	176 LQFP	208 MAPBGA
PH[1] ⁷	PCR[100]	Option 0 Option 1 Option 2 Option 3	GPIO[100] TDI — —	—	SIUL JTAG — —	I/O	S	Input, Pullup	33	36	P2
PH[2] ⁷	PCR[101]	Option 0 Option 1 Option 2 Option 3	GPIO[101] TDO — —	—	SIUL JTAG — —	I/O	M1	Output, None	34	39	N3
PH[3] ⁷	PCR[102]	Option 0 Option 1 Option 2 Option 3	GPIO[102] TMS — —	—	SIUL JTAG — —	I/O	S	Input, Pullup	35	41	M3
PH[4]	PCR[103]	Option 0 Option 1 Option 2 Option 3	GPIO[103] PCSO_0 eMIO[B16] CLKOUT	—	SIUL DSPL_0 PWM/Timer Control	I/O	F	None, None	47	61	R5
PH[5]	PCR[104]	Option 0 Option 1 Option 2 Option 3	GPIO[104] VLCD ⁸ — —	—	SIUL LCD — —	I/O	S	None, None	21	21	N2
PH[6]	—	—	Reserved	—	—	—	—	—	—	—	—
PH[7]	—	—	Reserved	—	—	—	—	—	—	—	—
PH[8]	—	—	Reserved	—	—	—	—	—	—	—	—
PH[9]	—	—	Reserved	—	—	—	—	—	—	—	—
PH[10]	—	—	Reserved	—	—	—	—	—	—	—	—
PH[11]	—	—	Reserved	—	—	—	—	—	—	—	—
PH[12]	—	—	Reserved	—	—	—	—	—	—	—	—
PH[13]	—	—	Reserved	—	—	—	—	—	—	—	—
PH[14]	—	—	Reserved	—	—	—	—	—	—	—	—
PH[15]	—	—	Reserved	—	—	—	—	—	—	—	—

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Table 8. Port pin summary (continued)

Port pin	PCR register	Alternate function ¹	Function	Special function ²	Peripheral ³	I/O direction	Pad type ⁴	RESET config. ⁵	Pin number		
									144 LQFP	176 LQFP	208 MAPBGA
PJ[0]	PCR[105]	Option 0 Option 1 Option 2 Option 3	GPIO[105] PDI_DE — —	—	SIUL PDI — —	I/O	S	None, None	—	119	A2
PJ[1]	PCR[106]	Option 0 Option 1 Option 2 Option 3	GPIO[106] PDI_HSYNC — —	—	SIUL PDI — —	I/O	S	None, None	—	120	A3
PJ[2]	PCR[107]	Option 0 Option 1 Option 2 Option 3	GPIO[107] PDI_VSYNC — —	—	SIUL PDI — —	I/O	S	None, None	—	121	B3
PJ[3]	PCR[108]	Option 0 Option 1 Option 2 Option 3	GPIO[108] PDI_PCLK — —	—	SIUL PDI — —	I/O	M1	None, None	—	122	A4
PJ[4]	PCR[109]	Option 0 Option 1 Option 2 Option 3	GPIO[109] PDI[0] CANRX_0 —	—	SIUL PDI FlexCAN_0 —	I/O	S	None, None	—	57	B4
PJ[5]	PCR[110]	Option 0 Option 1 Option 2 Option 3	GPIO[110] PDI[1] CANTX_0 —	—	SIUL PDI FlexCAN_0 —	I/O	M1	None, None	—	58	A5
PJ[6]	PCR[111]	Option 0 Option 1 Option 2 Option 3	GPIO[111] PDI[2] CANRX_1 eMIOA[22]	—	SIUL PDI FlexCAN_1 PWM/Timer	I/O	S	None, None	—	59	B5
PJ[7]	PCR[112]	Option 0 Option 1 Option 2 Option 3	GPIO[112] PDI[3] CANTX_1 eMIOA[21]	—	SIUL PDI FlexCAN_1 PWM/Timer	I/O	M1	None, None	—	60	A6

Table 8. Port pin summary (continued)

Port pin	PCR register	Alternate function ¹	Function	Special function ²	Peripheral ³	I/O direction	Pad type ⁴	RESET config. ⁵	Pin number		
									144 LQFP	176 LQFP	208 MAPBGA
PJ[8]	PCR[113]	Option 0 Option 1 Option 2 Option 3	GPIO[113] PDI[4] — —	—	SIUL PDI — —	I/O	S	None, None	—	125	B6
PJ[9]	PCR[114]	Option 0 Option 1 Option 2 Option 3	GPIO[114] PDI[5] — —	—	SIUL PDI — —	I/O	S	None, None	—	126	C4
PJ[10]	PCR[115]	Option 0 Option 1 Option 2 Option 3	GPIO[115] PDI[6] — —	—	SIUL PDI — —	I/O	S	None, None	—	127	C5
PJ[11]	PCR[116]	Option 0 Option 1 Option 2 Option 3	GPIO[116] PDI[7] — —	—	SIUL PDI — —	I/O	S	None, None	—	128	D5
PJ[12]	PCR[117]	Option 0 Option 1 Option 2 Option 3	GPIO[117] PDI[8] eMIOSB[17] —	—	SIUL PDI PWM/Timer —	I/O	M1	None, None	—	135	C6
PJ[13]	PCR[118]	Option 0 Option 1 Option 2 Option 3	GPIO[118] PDI[9] eMIOSB[20] —	—	SIUL PDI PWM/Timer —	I/O	M1	None, None	—	136	D6
PJ[14]	PCR[119]	Option 0 Option 1 Option 2 Option 3	GPIO[119] PDI[10] eMIOSA[20] —	—	SIUL PDI PWM/Timer —	I/O	M1	None, None	—	137	A7
PJ[15]	PCR[120]	Option 0 Option 1 Option 2 Option 3	GPIO[120] PDI[11] eMIOSA[19] —	—	SIUL PDI PWM/Timer —	I/O	M1	None, None	—	138	B7

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Table 8. Port pin summary (continued)

Port pin	PCR register	Alternate function ¹	Function	Special function ²	Peripheral ³	I/O direction	Pad type ⁴	RESET config. ⁵	Pin number		
									144 LQFP	176 LQFP	208 MAPBGA
PK[0]	PCR[121]	Option 0 Option 1 Option 2 Option 3	GPIO[121] PDI[12] eMIOA[18] DCU_TAG	—	SIUL PDI PWM/Timer DCU	I/O	M1	None, None	—	141	C7
PK[1]	PCR[122]	Option 0 Option 1 Option 2 Option 3	GPIO[122] PDI[13] eMIOA[17] —	—	SIUL PDI PWM/Timer —	I/O	M1	None, None	—	142	D7
PK[2]	PCR[123]	Option 0 Option 1 Option 2 Option 3	GPIO[123] MCKO PDI[10] —	—	SIUL Nexus PDI —	I/O	F	None, None	—	33	B12
PK[3]	PCR[124]	Option 0 Option 1 Option 2 Option 3	GPIO[124] MSEO PDI[11] —	—	SIUL Nexus PDI —	I/O	M1	None, None	—	34	C12
PK[4]	PCR[125]	Option 0 Option 1 Option 2 Option 3	GPIO[125] EVTO PDI[12] —	—	SIUL Nexus PDI —	I/O	M1	None, None	—	35	D12
PK[5]	PCR[126]	Option 0 Option 1 Option 2 Option 3	GPIO[126] EVTI PDI[13] —	—	SIUL Nexus PDI —	I/O	M1	None, None	—	37	A11
PK[6]	PCR[127]	Option 0 Option 1 Option 2 Option 3	GPIO[127] MDO0 PDI[14] —	—	SIUL Nexus PDI —	I/O	M1	None, None	—	38	B11
PK[7]	PCR[128]	Option 0 Option 1 Option 2 Option 3	GPIO[128] MDO1 PDI[15] —	—	SIUL Nexus PDI —	I/O	M1	None, None	—	40	C11

Table 8. Port pin summary (continued)

Port pin	PCR register	Alternate function ¹	Function	Special function ²	Peripheral ³	I/O direction	Pad type ⁴	RESET config. ⁵	Pin number		
									144 LQFP	176 LQFP	208 MAPBGA
PK[8]	PCR[129]	Option 0 Option 1 Option 2 Option 3	GPIO[129] MDO2 PDI[16] —	—	SIUL Nexus PDI —	I/O	M1	None, None	—	42	D11
PK[9]	PCR[130]	Option 0 Option 1 Option 2 Option 3	GPIO[130] MDO3 PDI[17] —	—	SIUL Nexus PDI —	I/O	M1	None, None	—	44	A10
PK[10]	PCR[131]	Option 0 Option 1 Option 2 Option 3	GPIO[131] SDA_1 eMIOA[15] —	—	SIUL I ² C_1 PWM/Timer —	I/O	S	None, None	—	52	N6
PK[11]	PCR[132]	Option 0 Option 1 Option 2 Option 3	GPIO[132] SCL_1 eMIOA[14] —	—	SIUL I ² C_1 PWM/Timer —	I/O	S	None, None	—	53	N5
PK[12]	—	—	Reserved	—	—	—	—	—	—	—	—
PK[13]	—	—	Reserved	—	—	—	—	—	—	—	—
PK[14]	—	—	Reserved	—	—	—	—	—	—	—	—
PK[15]	—	—	Reserved	—	—	—	—	—	—	—	—

¹ Alternate functions are chosen by setting the values of the PCR[n].PA bitfields inside the SIUL module. PCR[n].PA = 00 -> Option 0; PCR[n].PA = 01 -> Option 1; PCR[n].PA = 10 -> Option 2; PCR[n].PA = 11 -> Option 3. This is intended to select the output functions; to use one of the input functions, the PCR[n].IBE bit must be written to '1', regardless of the values selected in the PCR[n].PA bitfields. For this reason, the value corresponding to an input only function is reported as "—".

² Special functions are enabled independently from the standard digital pin functions. Enabling standard I/O functions in the PCR registers may interfere with their functionality. ADC functions are enabled using the PCR[APC] bit; other functions are enabled by enabling the respective module.

³ Using the PSMI registers in the System Integration Unit Lite (SIUL), different pads can be multiplexed to the same peripheral input. Please see the SIUL chapter of the *MPC5606S Microcontroller Reference Manual* for details.

⁴ See [Table 9](#).

⁵ Reset configuration is given as I/O direction and pull, e.g., "Input, Pullup".

⁶ This option on this pin has alternate functions that depend on whether the QuadSPI is in SPI mode or in serial flash mode (SFM).

⁷ Out of reset pins PH[0:3] are available as JTAG pins (TCK, TDI, TDO and TMS respectively). It is up to the user to configure pins PH[0:3] when needed.

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⁸ This pin can be used for LCD supply pin VLCD. Refer to the voltage supply pin descriptions in the MPC5606S data sheet for details.

Table 9. Pad type descriptions

Abbreviation ¹	Description
F	Fast (with GPIO and digital alternate function)
J	Slow pads with analog muxing (built for ADC channels)
M1	Medium (with GPIO and digital alternate function)
M2	Programmable medium/slow pad (programmed via the slew rate control in the PCR): Slew rate disabled: Slow driver configuration (AC/DC parameters same as for a slow pad) Slew rate enabled: Medium driver configuration (AC/DC parameters same as for a medium pad)
S	Slow (with GPIO and digital alternate function)
SMD	Stepper motor driver (with slew rate control)
X	Oscillator

¹ The pad descriptions refer to the different Pad Configuration Register (PCR) types. Refer to the SIUL chapter in the device reference manual for the features available for each pad type.

Table 10. Signal details

Signal	Peripheral	Description
ABS[0]	BAM	Alternate Boot Select. Gives an option to boot by downloading code via CAN or LIN.
ANS[0:15]	ADC	Inputs used to bring into the device sensor-based signals for A/D conversion. ANS[0:15] connect to ATD channels [32:47].
MA[0:2]	ADC	These three control bits are output to enable the selection for an external Analog Mux for expansion channels. The available 8 multiplexed channels connect to ATD channels [64:71].
FABM		Force Alternate Boot mode. Forces the device to boot from the external bus (Can or LIN). If not asserted, the device boots up from the lowest flash sector containing a valid boot signature.
DCU_DE	DCU	Indicates that valid pixels are present.
DCU_HSYNC	DCU	Horizontal sync pulse for TFT-LCD display
DCU_PCLK	DCU	Output pixel clock for TFT-LCD display
DCU_R[0:7], DCU_G[0:7], DCU_B[0:7]	DCU	Red, green and blue color 8-bit Pixel values for TFT-LCD displays
DCU_TAG	DCU	Indicates when a tagged pixel is present in safety mode
DCU_VSYNC	DCU	Vertical sync pulse for TFT-LCD display
PCS[0..2]_0, PCS[0..2]_1	DSPI	Peripheral chip selects when device is in Master mode; not used in slave modes.
SCK_0, SCK_1	DSPI	SPI clock signal—bidirectional
SIN_0, SIN_1	DSPI	SPI data input signal
SOUT_0, SOUT_1	DSPI	SPI data output signal
PCS0_2	QuadSPI	Peripheral chip select for serial flash mode or chip select 0 for SPI master mode
IO2/PCS1_2	QuadSPI	Chip select 1 for SPI master mode and bidirectional IO2 for serial flash mode
IO3/PCS2_2	QuadSPI	Chip select 2 for SPI master mode and bidirectional IO3 for serial flash mode
IO0/SIN_2	QuadSPI	Data input signal for SPI master and slave modes and bidirectional IO0 for serial flash mode
IO1/SOUT_2	QuadSPI	Data output signal for SPI master and slave modes and bidirectional IO1 for serial flash mode
SCK_2	QuadSPI	Clock output signal for SPI master and serial flash modes and clock input signal for SPI slave mode
eMIOA[8:23], eMIOSB[16:23]	eMIOS	Enhanced Modular Input Output System. 16+8 channel eMIOS for timed input or output functions.

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Table 10. Signal details (continued)

Signal	Peripheral	Description
CANRX_0, CANRX_1	FlexCAN	Receive (RX) pins for the CAN bus transceiver
CANTX_0, CANTX_1	FlexCAN	Transmit (TX) pins for the CAN bus transceiver
SCL_0, SCL_1, SCL_2, SCL_3	I ² C	Bidirectional serial clock compatible with I ² C specifications
SDA_0, SDA_1, SDA_2, SDA_3	I ² C	Bidirectional serial data compatible with I ² C specifications
TCK	JTAG	Debug port serial clock as per JTAG specifications
TDI	JTAG	Debug port serial data input port as per JTAG standards specifications
TDO	JTAG	Debug port serial data output port as per JTAG standards specifications
TMS	JTAG	Debug port Test Mode Select signal for the JTAG TAP controller state machine and indicates various state transitions for the TAP controller in the device
BP[0:3]	LCD	Backplane signals from the LCD controlling the backplane reference voltage for the LCD display
FP[0:39]	LCD	Frontplane signals for LCD segments
$\overline{\text{EVTI}}$	Nexus	Nexus2+ event input trigger
$\overline{\text{EVTO}}$	Nexus	Nexus2+ event output trigger
MCKO	Nexus	Output clock for the development tool
MDO[0:3]	Nexus	Message output port pins that send information bits to the development tools for messages such as Branch Trace Message (BTM), Ownership Trace Message (OTM), Data Trace Message (DTM). Only available in reduced port mode.
$\overline{\text{MSEO}}$	Nexus	Output pin—Indicates the start or end of the variable length message on the MDO pins
PDI[0:17]	DCU (PDI)	Video/graphic data in various RGB modes input to the DCU
PDI_DE	DCU (PDI)	Input signal indicates the validity of pixel data on the Input PDI data bus.
PDI_HSYNC	DCU (PDI)	Input indicates the timing reference for the start of each frame line for the PDI Input data.
PDI_PCLK	DCU (PDI)	Input pixel clock from PDI
PDI_VSYNC	DCU (PDI)	Input indicates the timing reference for the start of a frame for the PDI input data.
RXD_0	LINFlex	SCI/LIN Receive data signal—This port is used to download the code for the BAM boot sequence.

Table 10. Signal details (continued)

Signal	Peripheral	Description
RXD_1	LINFlex	SCI/LIN Receive data signal. Input pad for the LIN SCI module. Connects to the internal LIN second port.
TXD_0	LINFlex	SCI/LIN Transmit data signal. This port is used to download the code for the BAM boot sequence.
TXD_1	LINFlex	SCI/LIN Transmit data signal—Transmit (output) port for the second LIN module in the chip
SOUND	SGL	Sound signal to the speaker/buzzer
SSD[0:5]_0 SSD[0:5]_1 SSD[0:5]_2 SSD[0:5]_3	SSD	Bidirectional control of stepper motors using stall detection module
M[0:5]C0M M[0:5]C0P M[0:5]C1M M[0:5]C1P	SMC	Controls stepper motors in various configuration
CLKOUT	MC_CGM	Output clock—It can be selected from several internal clocks of the device from the clock generation module.

3 Electrical characteristics

3.1 Introduction

This section contains electrical characteristics of the device as well as temperature and power considerations.

This product contains devices to protect the inputs against damage due to high static voltages. However, it is advisable to take precautions to avoid application of any voltage higher than the specified maximum rated voltages.

To enhance reliability, unused inputs can be driven to an appropriate logic voltage level (V_{DD} or V_{SS}). This could be done by internal pull up and pull down, which is provided by the product for most general purpose pins.

The parameters listed in the following tables represent the characteristics of the device and its demands on the system.

In the tables where the device logic provides signals with their respective timing characteristics, the symbol “CC” for Controller Characteristics is included in the Symbol column.

In the tables where the external system must provide signals with their respective timing characteristics to the device, the symbol “SR” for System Requirement is included in the Symbol column.

3.2 Parameter classification

The electrical parameters shown in this supplement are guaranteed by various methods. To give the customer a better understanding, the classifications listed in [Table 11](#) are used and the parameters are tagged accordingly in the tables where appropriate.

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Table 11. Parameter Classifications

Classification tag	Tag description
P	Those parameters are guaranteed during production testing on each individual device.
C	Those parameters are achieved by the design characterization by measuring a statistically relevant sample size across process variations.
T	Those parameters are achieved by design characterization on a small sample size from typical devices under typical conditions unless otherwise noted. All values shown in the typical column are within this category.
D	Those parameters are derived mainly from simulations.

NOTE

The classification is shown in the column labeled “C” in the parameter tables where appropriate.

3.3 NVUSRO register

Portions of the device configuration, such as high voltage supply, oscillator margin, and watchdog enable/disable after reset are controlled via bit values in the Nonvolatile User Options (NVUSRO) register. For a detailed description of the NVUSRO register, please see the chip reference manual.

3.3.1 NVUSRO[PAD3V5V] field description

Table 12 shows how NVUSRO[PAD3V5V] controls the device configuration.

Table 12. PAD3V5V field description¹

Value ²	Description
0	High voltage supply is 5.0 V
1	High voltage supply is 3.3 V

¹ See the device reference manual for more information on the NVUSRO register.

² Default manufacturing value before Flash initialization is ‘1’ (3.3 V)

The DC electrical characteristics are dependent on the PAD3V5V bit value.

3.3.2 NVUSRO[OSCILLATOR_MARGIN] field description

Table 12 shows how NVUSRO[OSCILLATOR_MARGIN] controls the device configuration.

Table 13. OSCILLATOR_MARGIN field description¹

Value ²	Description
0	Low consumption configuration (4 MHz/8 MHz)
1	High margin configuration (4 MHz/16 MHz)

¹ See the device reference manual for more information on the NVUSRO register.

² Default manufacturing value before Flash initialization is ‘1’

The 4–16 MHz fast external crystal oscillator consumption is dependent on the OSCILLATOR_MARGIN bit value.

3.4 Absolute maximum ratings

Table 14. Absolute maximum ratings

Symbol	C	Parameter	Conditions	Value		Unit
				Min	Max	
V_{DDA}	SR	C Voltage on VDDA pin (ADC reference) with respect to ground (V_{SSA})	—	−0.3	5.5	V
			Relative to V_{DD}	$V_{DD} - 0.3$	$V_{DD} + 0.3$	
V_{SSA}	SR	C Voltage on VSSA (ADC reference) pin with respect to V_{SS}	—	$V_{SS} - 0.1$	$V_{SS} + 0.1$	V
V_{DDPLL}	CC	C Voltage on VDDPLL (1.2 V PLL supply) pin with respect to ground (V_{SSPLL})	—	1.08	1.4	V
			Relative to V_{DD}	$V_{DD} - 0.1$	$V_{DD} + 0.1$	
V_{SSPLL}	SR	C Voltage on VSSPLL pin with respect to V_{SS}	—	$V_{SS} - 0.1$	$V_{SS} + 0.1$	V
V_{DDR}	SR	C Voltage on VDDR pin (regulator supply) with respect to ground (V_{SSR})	—	−0.3	5.5	V
			Relative to V_{DD}	$V_{DD} - 0.3$	$V_{DD} + 0.3$	
V_{SSR}	SR	C Voltage on VSSR (regulator ground) pin with respect to V_{SS}	—	$V_{SS} - 0.1$	$V_{SS} + 0.1$	V
V_{DD12}	CC	C Voltage on VDD12 pin with respect to ground (V_{SS12})	—	1.08	1.4	V
V_{SS12}	CC	C Voltage on VSS12 pin with respect to V_{SS}	—	$V_{SS} - 0.1$	$V_{SS} + 0.1$	V
$V_{DDE_A}^1$	SR	C Voltage on VDDE_A (I/O supply) pin with respect to ground (V_{SSE_A})	—	−0.3	5.5	V
$V_{DDE_B}^1$	SR	C Voltage on VDDE_B (I/O supply) pin with respect to ground (V_{SSE_B})	—	−0.3	5.5	V
$V_{DDE_C}^1$	SR	C Voltage on VDDE_C (I/O supply) pin with respect to ground (V_{SSE_C})	—	−0.3	5.5	V
$V_{DDE_E}^1$	SR	C Voltage on VDDE_E (I/O supply) pin with respect to ground (V_{SSE_E})	—	−0.3	5.5	V
V_{DDMA}^1	SR	C Voltage on VDDMA (stepper motor supply) pin with respect to ground (V_{SSMA})	—	−0.3	5.5	V
V_{DDMB}^1	SR	C Voltage on VDDMB (stepper motor supply) pin with respect to ground (V_{SSMB})	—	−0.3	5.5	V
V_{DDMC}^1	SR	C Voltage on VDDMC (stepper motor supply) pin with respect to ground (V_{SSMC})	—	−0.3	5.5	V
V_{SS}^2	SR	C I/O supply ground	—	0	0	V
V_{SSOSC}	SR	C Voltage on VSSOSC (oscillator ground) pin with respect to V_{SS}	—	$V_{SS} - 0.1$	$V_{SS} + 0.1$	V
V_{LCD}	SR	C Voltage on VLCD (LCD supply) pin with respect to V_{SS}	—	0	$V_{DDE_A} + 0.3$	V
V_{IN}	SR	C Voltage on any GPIO pin with respect to ground (V_{SS})	—	−0.3	5.5	V
			Relative to V_{DD}	−0.3	$V_{DD} + 0.3$	

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Table 14. Absolute maximum ratings (continued)

Symbol		C	Parameter	Conditions	Value		Unit
					Min	Max	
I _{INJPAD}	SR	C	Injected input current on any pin during overload condition	—	–10	10	mA
I _{INJSUM}	SR	C	Absolute sum of all injected input currents during overload condition	—	–50	50	
I _{MAX}	CC	D	Absolute maximum current drive rating	—	—	45	
T _{STORAGE}	SR	C	Storage temperature	—	–55	150	°C

¹ Throughout the remainder of this document V_{DD} refers collectively to I/O voltage supplies, i.e., V_{DDE_A} , V_{DDE_B} , V_{DDE_C} , V_{DDE_E} , V_{DDMA} , V_{DDMB} and V_{DDMC} , unless otherwise noted.

² Throughout the remainder of this document V_{SS} refers collectively to I/O voltage supply grounds, i.e., V_{SSE_A} , V_{SSE_B} , V_{SSE_C} , V_{SSE_E} , V_{SSMA} , V_{SSMB} and V_{SSMC} , unless otherwise noted.

NOTE

Stresses exceeding the recommended absolute maximum ratings may cause permanent damage to the device. This is a stress rating only and functional operation of the device at these or any other conditions above those indicated in the operational sections of this specification are not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability. During overload conditions ($V_{IN} > V_{DD}$ or $V_{IN} < V_{SS}$), the voltage on pins with respect to ground (V_{SS}) must not exceed the recommended values.

3.4.1 Recommended operating conditions

NOTE

Maximum slew time for the supplies to ramp up should be 1 second, which is slowest ramp-up time.

CAUTION

V_{DDE_C} and V_{DDA} must be the same voltage.

V_{DDMB} and V_{DDMC} must be the same voltage.

Table 15. Recommended operating conditions (3.3 V)

Symbol	C	Parameter	Conditions	Value		Unit
				Min	Max	
V_{DDA}^1	SR	Voltage on VDDA pin (ADC reference) with respect to ground (V_{SS})	—	3.0	3.6	V
	C		Relative to V_{DDE_C}	$V_{DD} - 0.1$	$V_{DD} + 0.1$	
V_{SSA}	SR	C Voltage on VSSA (ADC reference) pin with respect to V_{SS}	—	$V_{SS} - 0.1$	$V_{SS} + 0.1$	V
V_{SSPLL}	SR	C Voltage on VSSPLL pin with respect to V_{SS12}	—	0	0	V
V_{DDR}^2	SR	C Voltage on VDDR pin (regulator supply) with respect to ground (V_{SSR})	—	3.0	3.6	V
V_{SSR}	SR	C Voltage on VSSR (regulator ground) pin with respect to V_{SS12}	—	0	0	V
V_{SS12}	CC	C Voltage on VSS12 pin with respect to V_{SS}	—	$V_{SS} - 0.1$	$V_{SS} + 0.1$	V
$V_{DD}^{3,4,5}$	SR	C Voltage on VDD pins (VDDE_A, VDDE_B, VDDE_C, VDDE_E, VDDMA, VDDMB, VDDMC) with respect to ground (V_{SS})	—	3.0	3.6	V
V_{SS}^6	SR	C I/O supply ground	—	0	0	V
V_{DDE_A}	SR	C Voltage on VDDE_A (I/O supply) pin with respect to ground (V_{SSE_A})	—	3.0	3.6	V
V_{DDE_B}	SR	C Voltage on VDDE_B (I/O supply) pin with respect to ground (V_{SSE_B})	—	3.0	3.6	V
V_{DDE_C}	SR	C Voltage on VDDE_C (I/O supply) pin with respect to ground (V_{SSE_C})	—	3.0	3.6	V
V_{DDE_E}	SR	C Voltage on VDDE_E (I/O supply) pin with respect to ground (V_{SSE_E})	—	3.0	3.6	V
V_{DDMA}	SR	C Voltage on VDDMA (stepper motor supply) pin with respect to ground (V_{SSMA})	—	3.0	3.6	V
V_{DDMB}	SR	C Voltage on VDDMB (stepper motor supply) pin with respect to ground (V_{SSMB})	—	3.0	3.6	V
V_{DDMC}	SR	C Voltage on VDDMC (stepper motor supply) pin with respect to ground (V_{SSMC})	—	3.0	3.6	V
V_{SSOSC}	SR	C Voltage on VSSOSC (oscillator ground) pin with respect to V_{SS}	—	0	0	V

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Table 15. Recommended operating conditions (3.3 V) (continued)

Symbol		C	Parameter	Conditions	Value		Unit
					Min	Max	
V _{LCD}	SR	C	Voltage on VLCD (LCD supply) pin with respect to V _{SS}	—	0	V _{DDE_A} + 0.3	V
TV _{DD}	SR	C	V _{DD} slope to ensure correct power up	—	5×10 ^{−6}	0.25	V/μs
T _A	SR	C	Ambient temperature under bias	—	−40	105	°C
T _J	SR	C	Junction temperature under bias		−40	150	

¹ 100 nF capacitance needs to be provided between V_{DDA}/V_{SSA} pair.

² At least 10 μF capacitance must be connected between V_{DDR} and V_{SS12}. This is required because of sharp surge due to external ballast.

³ V_{DD} refers collectively to I/O voltage supplies, i.e., V_{DDE_A}, V_{DDE_B}, V_{DDE_C}, V_{DDE_E}, V_{DDMA}, V_{DDMB} and V_{DDMC}.

⁴ 100 nF capacitance needs to be provided between each V_{DD}/V_{SS} pair

⁵ Full electrical specification cannot be guaranteed when voltage drops below 3.0 V. In particular, ADC electrical characteristics and I/O's DC electrical specification may not be guaranteed.

When voltage drops below V_{LVDHVL} device is reset.

⁶ V_{SS} refers collectively to I/O voltage supply grounds, i.e., V_{SSE_A}, V_{SSE_B}, V_{SSE_C}, V_{SSE_E}, V_{SSMA}, V_{SSMB} and V_{SSMC} unless otherwise noted.

Table 16. Recommended operating conditions (5.0 V)

Symbol		C	Parameter	Conditions	Value		Unit
					Min	Max	
V_{DDA}^1	SR	C	Voltage on VDDA pin (ADC reference) with respect to ground (V_{SS})	—	4.5	5.5	V
		C		Voltage drop ²	3.0	5.5	
		C		Relative to V_{DDE_C}	$V_{DD} - 0.1$	$V_{DD} + 0.1$	
V_{SSA}	SR	C	Voltage on VSSA (ADC reference) pin with respect V_{SS}	—	$V_{SS} - 0.1$	$V_{SS} + 0.1$	V
V_{SSPLL}	SR	C	Voltage on VSSPLL pin with respect to V_{SS12}	—	0	0	V
V_{DDR}^3	SR	C	Voltage on VDDR pin (regulator supply) with respect to ground (V_{SSR})	—	4.5	5.5	V
		C		Voltage drop ²	3.0	5.5	
		C		Relative to V_{DD}	$V_{DD} - 0.1$	$V_{DD} + 0.1$	
V_{SSR}	SR	C	Voltage on VSSR (regulator ground) pin with respect to V_{SS12}	—	0	0	V
V_{SS12}	CC	C	Voltage on VSS12 pin with respect to V_{SS}	—	$V_{SS} - 0.1$	$V_{SS} + 0.1$	V
$V_{DD}^{4,5}$	SR	C	Voltage on VDD pins (VDDE_A, VDDE_B, VDDE_C, VDDE_E, VDDMA, VDDMB, VDDMC) with respect to ground (V_{SS})	Voltage drop ²	4.5	5.5	V
V_{SS}^6	SR	C	I/O supply ground	—	0	0	V
V_{DDE_A}	SR	C	Voltage on VDDE_A (I/O supply) pin with respect to ground (V_{SSE_A})	—	4.5	5.5	V

Table 16. Recommended operating conditions (5.0 V) (continued)

Symbol		C	Parameter	Conditions	Value		Unit
					Min	Max	
V _{DDE_B}	SR	C	Voltage on VDDE_B (I/O supply) pin with respect to ground (V _{SSE_B})	—	4.5	5.5	V
V _{DDE_C} ⁷	SR	C	Voltage on VDDE_C (I/O supply) pin with respect to ground (V _{SSE_C})	—	4.5	5.5	V
V _{DDE_E}	SR	C	Voltage on VDDE_E (I/O supply) pin with respect to ground (V _{SSE_E})	—	4.5	5.5	V
V _{DDMA}	SR	C	Voltage on VDDMA (stepper motor supply) pin with respect to ground (V _{SSMA})	—	4.5	5.5	V
V _{DDMB}	SR	C	Voltage on VDDMB (stepper motor supply) pin with respect to ground (V _{SSMB})	—	4.5	5.5	V
V _{DDMC}	SR	C	Voltage on VDDMC (stepper motor supply) pin with respect to ground (V _{SSMC})	—	4.5	5.5	V
V _{SSOSC}	SR	C	Voltage on VSSOSC (oscillator ground) pin with respect to V _{SS}	—	0	0	V
V _{LCD}	SR	C	Voltage on VLCD (LCD supply) pin with respect to V _{SS}	—	0	V _{DDE_A} + 0.3	V
TV _{DD}	SR	C	V _{DD} slope to ensure correct power up	—	3×10 ⁻⁶	0.25	V/μs
T _A	SR	C	Ambient temperature under bias	—	-40	105	°C
T _J	SR	C	Junction temperature under bias	—	-40	150	°C

¹ 100 nF capacitance needs to be provided between V_{DDA}/V_{SSA} pair.

² Full functionality cannot be guaranteed when voltage drops below 4.5 V. In particular, I/O DC and ADC electrical characteristics may not be guaranteed below 4.5 V during the voltage drop sequence.

³ 10 μF capacitance must be connected between V_{DDR} and V_{SS12}. This is required because of sharp surge due to external ballast.

⁴ V_{DD} refers collectively to I/O voltage supplies, i.e., V_{DDE_A}, V_{DDE_B}, V_{DDE_C}, V_{DDE_E}, V_{DDMA}, V_{DDMB} and V_{DDMC}.

⁵ 100 nF capacitance needs to be provided between each V_{DD}/V_{SS} pair

⁶ V_{SS} refers collectively to I/O voltage supply grounds, i.e., V_{SSE_A}, V_{SSE_B}, V_{SSE_C}, V_{SSE_E}, V_{SSMA}, V_{SSMB} and V_{SSMC}) unless otherwise noted.

⁷ V_{DDE_C} should be the same as V_{DDA} with a 100 mV variation, i.e., V_{DDE_C} = V_{DDA} ±100 mV.

3.4.2 Connecting power supply pins: What to do and what not to do

- Do:
 - Have all power/ground supplies connected on the board from a strong supply source rather than weak voltage divider sources unless there is “NO IO activity” in the section
 - Meet the supply specifications for max / typical operating conditions to guarantee correct operation
 - Place the decoupling near the supply/ground pin pair for EMI emissions reduction
 - Route high-noise supply/ground away from sensitive signals (for example, ADC channels must be away from SMD supply/motor pads)
 - Use star routing for the ballast supply from the VDDR supply to avoid ballast startup noise injected to VDDR supply of the device
 - Use LC inductive filtering for ADC, OSC, and PLL supplies if these are generated from common board regulators

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Do not:

- Ground or hand a power/ground supply
- Violate injection current limit per IO/All IO pins as per specifications
- Connect sensitive supplies/ground on noisy supplies/ground (that is, ADC, PLL, and OSC)
- Use SMD supply for generation of noise free supply as these are most noisy lines in the system
- Connect different VDD pins (connected together inside the device) to different potential (that is, VDDE_A)

3.5 Thermal characteristics

Table 17. LQFP thermal characteristics¹

Symbol	C	Parameter	Conditions	Value		Unit
				144-pin	176-pin	
R _{θJA}	CC	D Thermal resistance, junction-to-ambient natural convection ²	Single layer board—1s	50	43	°C/W
	CC		Four layer board—2s2p	41	35	°C/W
R _{θJMA}	CC	D Thermal resistance, junction-to-moving-air ambient ²	@ 200 ft./min., single layer board—1s	41	35	°C/W
	CC		@ 200 ft./min., four layer board—2s2p	35	30	°C/W
R _{θJB}	CC	D Thermal resistance, junction-to-board ³	—	29	24	°C/W
R _{θJCTop}	CC	D Thermal resistance, junction-to-case (top) ⁴	—	10	9	°C/W
Ψ _{JT}	CC	D Junction-to-package top thermal characterization parameter, natural convection ⁵	—	2	2	°C/W

¹ Thermal characteristics are targets based on simulation that are subject to change per device characterization.

² Junction-to-ambient thermal resistance determined per JEDEC JESD51-3 and JESD51-6. Thermal test board meets JEDEC specification for this package.

³ Junction-to-board thermal resistance determined per JEDEC JESD51-8. Thermal test board meets JEDEC specification for the specified package.

⁴ Junction-to-case at the top of the package determined using MIL-STD 883 Method 1012.1. The cold plate temperature is used for the case temperature. Reported value includes the thermal resistance of the interface layer.

⁵ Thermal characterization parameter indicating the temperature difference between the package top and the junction temperature per JEDEC JESD51-2. When Greek letters are not available, the thermal characterization parameter is written as Psi-JT.

3.5.1 General notes for specifications at maximum junction temperature

An estimate of the chip junction temperature, T_J, can be obtained from Equation 1:

$$T_J = T_A + (R_{\theta JA} \times P_D) \quad \text{Eqn. 1}$$

where:

T_A = ambient temperature for the package (°C)

R_{θJA} = junction to ambient thermal resistance (°C/W)

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P_D = power dissipation in the package (W)

The thermal resistance values used are based on the JEDEC JESD51 series of standards to provide consistent values for estimations and comparisons. The difference between the values determined for the single-layer (1s) board compared to a four-layer board that has two signal layers, a power and a ground plane (2s2p), demonstrate that the effective thermal resistance is not a constant. The thermal resistance depends on the:

- Construction of the application board (number of planes)
- Effective size of the board which cools the component
- Quality of the thermal and electrical connections to the planes
- Power dissipated by adjacent components

Connect all the ground and power balls to the respective planes with one via per ball. Using fewer vias to connect the package to the planes reduces the thermal performance. Thinner planes also reduce the thermal performance. When the clearance between the vias leave the planes virtually disconnected, the thermal performance is also greatly reduced.

As a general rule, the value obtained on a single-layer board is within the normal range for the tightly packed printed circuit board. The value obtained on a board with the internal planes is usually within the normal range if the application board has:

- One oz. (35 micron nominal thickness) internal planes
- Components are well separated
- Overall power dissipation on the board is less than 0.02 W/cm²

The thermal performance of any component depends on the power dissipation of the surrounding components. In addition, the ambient temperature varies widely within the application. For many natural convection and especially closed box applications, the board temperature at the perimeter (edge) of the package is approximately the same as the local air temperature near the device. Specifying the local ambient conditions explicitly as the board temperature provides a more precise description of the local ambient conditions that determine the temperature of the device.

At a known board temperature, the junction temperature is estimated using [Equation 2](#):

$$T_J = T_B + (R_{\theta JB} \times P_D) \quad \text{Eqn. 2}$$

where:

T_B = board temperature for the package perimeter (°C)

$R_{\theta JB}$ = junction-to-board thermal resistance (°C/W) per JESD51-8S

P_D = power dissipation in the package (W)

When the heat loss from the package case to the air does not factor into the calculation, an acceptable value for the junction temperature is predictable. Ensure the application board is similar to the thermal test condition, with the component soldered to a board with internal planes.

The thermal resistance is expressed as the sum of a junction-to-case thermal resistance plus a case-to-ambient thermal resistance:

$$R_{\theta JA} = R_{\theta JC} + R_{\theta CA} \quad \text{Eqn. 3}$$

where:

$R_{\theta JA}$ = junction to ambient thermal resistance (°C/W)

$R_{\theta JC}$ = junction to case thermal resistance (°C/W)

$R_{\theta CA}$ = case to ambient thermal resistance (°C/W)

$R_{\theta JC}$ is device related and is not affected by other factors. The thermal environment can be controlled to change the case-to-ambient thermal resistance, $R_{\theta CA}$. For example, change the air flow around the device, add a heat sink, change the mounting arrangement on the printed circuit board, or change the thermal dissipation on the printed circuit board surrounding the device. This description is most useful for packages with heat sinks where 90% of the heat flow is through the case to heat sink to ambient. For most packages, a better model is required.

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A more accurate two-resistor thermal model can be constructed from the junction-to-board thermal resistance and the junction-to-case thermal resistance. The junction-to-case thermal resistance describes when using a heat sink or where a substantial amount of heat is dissipated from the top of the package. The junction-to-board thermal resistance describes the thermal performance when most of the heat is conducted to the printed circuit board. This model can be used to generate simple estimations and for computational fluid dynamics (CFD) thermal models.

To determine the junction temperature of the device in the application on a prototype board, use the thermal characterization parameter (Ψ_{JT}) to determine the junction temperature by measuring the temperature at the top center of the package case using Equation 4:

$$T_J = T_T + (\Psi_{JT} \times P_D) \quad \text{Eqn. 4}$$

where:

- T_T = thermocouple temperature on top of the package ($^{\circ}\text{C}$)
- Ψ_{JT} = thermal characterization parameter ($^{\circ}\text{C}/\text{W}$)
- P_D = power dissipation in the package (W)

The thermal characterization parameter is measured in compliance with the JESD51-2 specification using a 40-gauge type T thermocouple epoxied to the top center of the package case. Position the thermocouple so that the thermocouple junction rests on the package. Place a small amount of epoxy on the thermocouple junction and approximately 1 mm of wire extending from the junction. Place the thermocouple wire flat against the package case to avoid measurement errors caused by the cooling effects of the thermocouple wire.

References:

Semiconductor Equipment and Materials International
805 East Middlefield Rd.
Mountain View, CA 94043 USA
(415) 964-5111

MIL-SPEC and EIA/JESD (JEDEC) specifications are available from Global Engineering Documents at 800-854-7179 or 303-397-7956.

JEDEC specifications are available on the WEB at <http://www.jedec.org>.

3.6 Electromagnetic compatibility (EMC) characteristics

Susceptibility tests are performed on a sample basis during product characterization.

3.6.1 EMC requirements on board

The following practices help minimize noise in applications.

- Place a 100 nF capacitor between each of the V_{DD12}/V_{SS12} supply pairs and also between the V_{DDPLL}/V_{SSPLL} pair. The voltage regulator also requires stability capacitors for these supply pairs.
- Place a 10 μF capacitor on VDDR.
- Isolate VDDR with ballast emitter to avoid voltage droop during STANDBY mode exit.
- Enable pad slew rate only as necessary to eliminate I/O noise:
 - Enabling slew rate for SMC pads will reduce noise on motors.
 - Disabling slew rate for non-SMC pads will reduce noise on non-SMC IOs.
- Enable PLL modulation ($\pm 2\%$) for system clock.
- Place decoupling capacitors for all HV supplies close to the pins.

3.6.2 Designing hardened software to avoid noise problems

EMC characterization and optimization are performed at component level with a typical application environment and simplified MCU software. It should be noted that good EMC performance is highly dependent on the user application and the software in particular.

Therefore it is recommended that the user apply EMC software optimization and prequalification tests in relation with the EMC level requested for his application.

- Software recommendations – The software flowchart must include the management of runaway conditions such as:
 - Corrupted program counter
 - Unexpected reset
 - Critical data corruption (control registers...)
- Prequalification trials – Most of the common failures (unexpected reset and program counter corruption) can be reproduced by manually forcing a low state on the reset pin or the oscillator pins for 1 second.
To complete these trials, ESD stress can be applied directly on the device. When unexpected behavior is detected, the software can be hardened to prevent unrecoverable errors occurring.

3.6.3 Electromagnetic interference (EMI)

Table 18. EMI testing specifications¹

Symbol		C	Parameter	Conditions	Value			Unit
					Min	Typ	Max	
—	SR	T	Scan range	150 kHz – 30 MHz: RBW 9 kHz, step size 5 kHz 30 MHz – 1 GHz: RBW 120 kHz, step size 80 kHz	0.15	—	1000	MHz
—	SR	T	Operating frequency	Crystal frequency 8 MHz	—	64	—	MHz
—	SR	T	VDD12, VDDPLL operating voltages	—	—	1.2	—	V
—	SR	T	VDD, VDDA operating voltages	—	—	5	—	V
—	SR	T	Maximum amplitude	No PLL frequency modulation	—	33	—	dBμV
				±2% PLL frequency modulation	—	30	—	
—	SR	T	Operating temperature	—	—	25	—	°C

¹ EMI testing and I/O port waveforms per SAE J1752/3 issued 1995-03.

3.6.4 Absolute maximum ratings (electrical sensitivity)

Based on two different tests (ESD and LU) using specific measurement methods, the product is stressed in order to determine its performance in terms of electrical sensitivity.

3.6.4.1 Electrostatic discharge (ESD)

Electrostatic discharges (a positive then a negative pulse separated by 1 second) are applied to the pins of each sample according to each pin combination. The sample size depends on the number of supply pins in the device (3 parts*(n+1) supply pin). This test conforms to the AEC-Q100-002/-003/-011 standard.

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Table 19. ESD absolute maximum ratings^{1 2}

Symbol	C		Ratings	Conditions	Class	Max value	Unit
$V_{ESD(HBM)}$	CC	T	Electrostatic discharge voltage (Human Body Model)	$T_A = 25\text{ }^{\circ}\text{C}$ conforming to AEC-Q100-002	H1C	2000	V
$V_{ESD(MM)}$	CC	T	Electrostatic discharge voltage (Machine Model)	$T_A = 25\text{ }^{\circ}\text{C}$ conforming to AEC-Q100-003	M2	200	
$V_{ESD(CDM)}$	CC	T	Electrostatic discharge voltage (Charged Device Model)	$T_A = 25\text{ }^{\circ}\text{C}$ conforming to AEC-Q100-011	C3A	500 750 (corners)	

¹ All ESD testing is in conformity with CDF-AEC-Q100 Stress Test Qualification for Automotive Grade Integrated Circuits.

² A device will be defined as a failure if after exposure to ESD pulses the device no longer meets the device specification requirements. Complete DC parametric and functional testing shall be performed per applicable device specification at room temperature followed by hot temperature, unless specified otherwise in the device specification.

3.6.4.2 Static latch-up (LU)

Two complementary static tests are required on six parts to assess the latch-up performance:

- A supply overvoltage is applied to each power supply pin.
- A current injection is applied to each input, output and configurable I/O pin.

These tests are compliant with the EIA/JESD 78 IC latch-up standard.

Table 20. Latch-up results

Symbol	C		Parameter	Conditions	Class
LU	CC	T	Static latch-up class	$T_A = 105\text{ }^{\circ}\text{C}$ conforming to JESD 78	II level A

3.7 Power management electrical characteristics

3.7.1 Voltage regulator electrical characteristics

The internal high power or main regulator (HPREG) requires an external NPN ballast transistor (see Table 21 and Table 22) to be connected as shown in Figure 7 as well as an external capacitance (C_{REG}) to be connected to the device in order to provide a stable low voltage digital supply to the device. Capacitances should be placed on the board as near as possible to the associated pins. Care should also be taken to limit the serial inductance of the board to less than 15 nH.

For the MPC5606S microcontroller, 100 nF should be placed between each of the V_{DD12}/V_{SS12} supply pairs and also between the V_{DDPLL}/V_{SSPLL} pair. These decoupling capacitors are in addition to the required stability capacitance. Additionally, 10 μF should be placed between the V_{DDR} pin and the adjacent V_{SS} pin.

$V_{DDR} = 3.0\text{ V to }3.6\text{ V} / 4.5\text{ V to }5.5\text{ V}$, $T_A = -40\text{ to }105\text{ }^{\circ}\text{C}$, unless otherwise specified.

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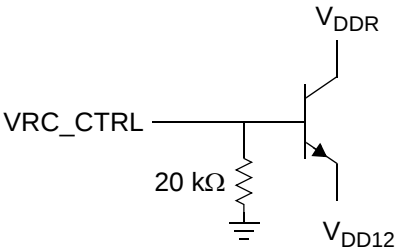


Figure 7. External NPN ballast connections

Table 21. Allowed ballast components

Part	Manufacturer	Recommended derivative
BCP68	ON, IFX, NXP, Fairchild, ST, etc.	BCP68
BCX68	IFX	BCX68-10 BCX68-16
BC817	ON, IFX, NXP, Fairchild, etc.	BC817Su BC817-25
BCP56	ON, IFX, NXP, Fairchild, ST, etc.	BCP68-10 BCP68-16

Table 22. Ballast component parameters

Parameter	Specification
Capacitance on VDDR	10 μ F (minimum) Place close to NPN collector
Stability capacitance on VDD12	40 μ F (minimum) Place close to NPN emitter
Decoupling capacitance on VDD12	100 nF $\times$ number of pins (minimum) Place on each VDD12/VSS12 pair and on the PLL supply/ground pair
Base resistor	20 k Ω

The capacitor values listed in [Table 22](#) include a de-rating factor of 40%, covering tolerance, temperature, and aging effects. These factors are taken into account to assure proper operation under worst-case conditions. X7R type materials are recommended for all capacitors, based on ESR characteristics.

Large capacitors are for regulator stability and should be located near the external ballast transistor. The number of capacitors is not important — only the overall capacitance value and the overall ESR value are important.

Small capacitors are for power supply decoupling, although they do contribute to the overall capacitance values. They should be located close to the device pin.

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Table 23. Voltage regulator electrical characteristics¹

Symbol	C	Parameter	Conditions	Value		Unit
				Min	Max	
T _J	SR	C	Junction temperature	—	—	°C
I _{REG}	CC	C	Current consumption	Reference included, @ 55 °C No load @ Full load	— 2 11	mA
I _L	CC	C	Output current capacity	DC load current	— 200	mA
V _{DD12}	CC	C	Output voltage	Pre-trimming sigma < 7 mV	— 1.330	V
			Post-trimming	1.145	1.32	
	SR	C	External decoupling/stability capacitor	4 capacitances of 10 µF each	— 10 × 4	µF
	C		ESR of external cap	0.05	0.2	Ω
	C		1 bond wire R + 1 pad R	0.2	1	Ω
L _{BOND}	CC	D	Bonding Inductance for Bipolar Base Control pad	—	0 15	nH
	CC	D	Power supply rejection	@ DC @ no load	— —30	dB
		D	@ 200 kHz @ no load		—100	
		D	@ DC @ 400 mA		—30	
		D	@ 200 kHz @ 400 mA		—30	
	CC	D	Load current transient	C _L = 10 µF × 4	—	10% to 90% of I _L (max) in 100 ns
t _{SU}	CC	C	Start-up time after input supply stabilizes ²	C _L = 10 µF × 4	—	100 µs

¹ All values in this table are subject to change pending characterization results.² Time after the input supply to the voltage regulator has ramped up (V_{DDR}).Table 24. Low-power voltage regulator electrical characteristics¹

Symbol	C	Parameter	Conditions	Value		Unit
				Min	Max	
T _J	SR	C	Junction temperature	—	—	°C
I _{REG}	CC	C	Current consumption	Reference included, @ 55 °C No load @ Full load	— 5 600	µA
I _L	CC	C	Output current capacity ²	DC load current	— 15	mA
V _{DD12}	CC	C	Output voltage	Pre-trimming sigma < 7 mV	— 1.33	V
			Post-trimming	1.13	1.32	

Table 24. Low-power voltage regulator electrical characteristics (continued)¹

Symbol		C	Parameter		Conditions	Value		Unit
						Min	Max	
	SR	C	External decoupling/stability capacitor		4 capacitances of 10 μ F each	10 $\times$ 4	10 $\times$ 4	μ F
		C			ESR of external cap	0.1	0.6	ohm
		C			1 bond wire R + 1 pad R	0.2	1	ohm
L _{BOND}	CC	D	Bonding Inductance for Bipolar Base Control pad		—	0	15	nH
	CC	D	Power supply rejection	@ DC @ no load	C _L = 10 μ F $\times$ 4	—	55	dB
		D		any frequency @ no load			32	
		D		@ DC @ max load			24	
		D		any frequency @ max load			12	
	CC	D	Load current transient		C _L = 10 μ F $\times$ 4	—	10% to 90% of I _L in 10 μ s	
t _{SU}	CC	C	Start-up time after input supply stabilizes ³		C _L = 10 μ F $\times$ 4	—	700	μ s

¹ All values in this table are subject to change pending characterization results.

² On this device, the ultra-low-power regulator is always enabled when the low-power regulator is enabled. Therefore, the total low-power current capacity is the sum of I_L values for the two regulators.

³ Time after the input supply to the voltage regulator has ramped up (V_{DDR}) and the voltage regulator has asserted the Power OK signal.

Table 25. Ultra-low-power voltage regulator electrical characteristics ¹

Symbol		C	Parameter	Conditions	Value		Unit
					Min	Max	
T _J	SR	C	Junction temperature	—	–40	150	°C
I _{REG}	CC	C	Current consumption	Reference included, @ 55 °C No load @ Full load	—	2 100	μA
I _L	CC	C	Output current capacity	DC load current	—	5	mA
V _{DD12}	CC	C	Output voltage (value @ I _L = 0 @ 27 °C)	Pre-trimming sigma < 7 mV	—	1.33	V
			Post-trimming	1.13	1.32		

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Table 25. Ultra-low-power voltage regulator electrical characteristics (continued)¹

Symbol	C		Parameter	Conditions	Value		Unit
					Min	Max	
	CC	D	Power supply rejection	@ DC @ no load	—	25	dB
		D		any frequency @ no load		7	
		D		@ DC @ max load		25	
		D		any frequency @ max load		8	
	CC	D	Load current transient	—	—	10 to 90 μ A in 70 μ s	

¹ All values in this table are subject to change pending characterization results.

3.7.2 Voltage monitor electrical characteristics

The device implements a Power-on Reset (POR) module to ensure correct power-up initialization, as well as four low voltage detectors (LVDs) to monitor the V_{DD} and the V_{DD12} voltage while device is supplied:

- POR monitors V_{DD} during the power-up phase to ensure device is maintained in a safe reset state
- LVDHV3 monitors V_{DD} to ensure device reset below minimum functional supply
- LVDHV5 monitors V_{DD} when application uses device in the 5.0 V $\pm$ 10% range
- LVDLVCOR monitors power domain No. 1
- LVDLVBKP monitors power domain No. 0

Table 26. Low voltage monitor electrical characteristics

Symbol	C		Parameter	Conditions ¹	Value ²			Unit
					Min	Typ	Max	
V_{PORH}	CC	C	Power-on reset threshold	—	1.5	—	2.6	V
$V_{LVDHV3H}$	CC	C	LVDHV3 low voltage detector high threshold	—	—	—	2.9	
$V_{LVDHV5H}$	CC	C	LVDHV5 low voltage detector high threshold	—	—	—	4.37	
$V_{LVDHV3L}$	CC	C	LVDHV3 low voltage detector low threshold	—	2.6	—	—	
$V_{LVDHV5L}$	CC	C	LVDHV5 low voltage detector low threshold	—	4.0	—	—	
$V_{LVDLVCORH}$	CC	C	LVDLVCOR low voltage detector high threshold	$T_A = 25^\circ\text{C}$, after trimming	—	—	1.13	
$V_{LVDLVCORL}$	CC	C	LVDLVCOR low voltage detector low threshold		1.085	—	—	

¹ $V_{DD} = 3.3\text{ V} \pm 10\%$ / $5.0\text{ V} \pm 10\%$, $T_A = -40$ to 105°C , unless otherwise specified² All values need to be confirmed during device characterization.

3.7.3 Low voltage domain power consumption

Table 27 provides DC electrical characteristics for significant application modes. These values are indicative values; actual consumption depends on the application.

Table 27. DC electrical characteristics

Symbol	C	Parameter	Conditions ¹	Value ²			Unit
				Min	Typ	Max	
I _{DDMAX}	SR	C	Maximum current	—	135	—	mA
I _{DDRUN} ³	CC	C	RUN mode current	—	130	180	mA
I _{DDWAIT}	CC	C	WAIT mode current	—	30	—	mA
I _{DDHALT}	CC	C	HALT mode current	—	4	25	mA
I _{DDSTOP}	CC	C	STOP mode current	16 MHz fast internal RC oscillator off	—	1.5	mA
			HPVREG off	—	800	—	μA
			16 MHz fast internal RC oscillator on	—	4	—	mA
I _{DDSTDBY}	CC	C	STANDBY mode current	See Table 28			

¹ V_{DD} = 3.3 V ± 10% / 5.0 V ± 10%, T_A = -40 to 105 °C

² All values need to be confirmed during device characterization.

³ Value is for maximum peripherals turned on. May vary significantly based on different configurations, active peripherals, operating frequency, etc.

Table 28. IDDSTDBY specification¹

Temperature (°C)	FIRC off, 8 KB RAM on		FIRC on, 8 KB RAM on		32 kHz SXOSC on, 8 KB RAM on		32 kHz SXOSC on, all RAM on	
	3.3 V	5.5 V	3.3 V	5.5 V	3.3 V	5.5 V	3.3 V	5.5 V
-40	16 μA	25 μA	326 μA	340 μA	16 μA	26 μA	22 μA	32 μA
0	18 μA	29 μA	334 μA	347 μA	19 μA	29 μA	26 μA	37 μA
25	23 μA	33 μA	342 μA	355 μA	24 μA	34 μA	34 μA	45 μA
55	41 μA	51 μA	363 μA	377 μA	42 μA	53 μA	69 μA	80 μA
85	93 μA	104 μA	421 μA	435 μA	100 μA	110 μA	182 μA	195 μA
105	173 μA	185 μA	502 μA	517 μA	181 μA	194 μA	344 μA	358 μA
125 ²	320 μA	334 μA	648 μA	667 μA	321 μA	335 μA	620 μA	638 μA
150 ²	681 μA	698 μA	1005 μA	1028 μA	654 μA	677 μA	1270 μA	1300 μA

¹ All current values are typical values.

² Values provided for reference only. The permitted temperature range of the chip is specified separately.

3.7.4 Recommended power-up and power-down order

Figure 8 shows the recommended order for powering up the power supplies on this device.

The 1.2 V regulator output starts after the device's internal POR (VDDREG HV) is deasserted at approximately 2.7 V on VDDREG.

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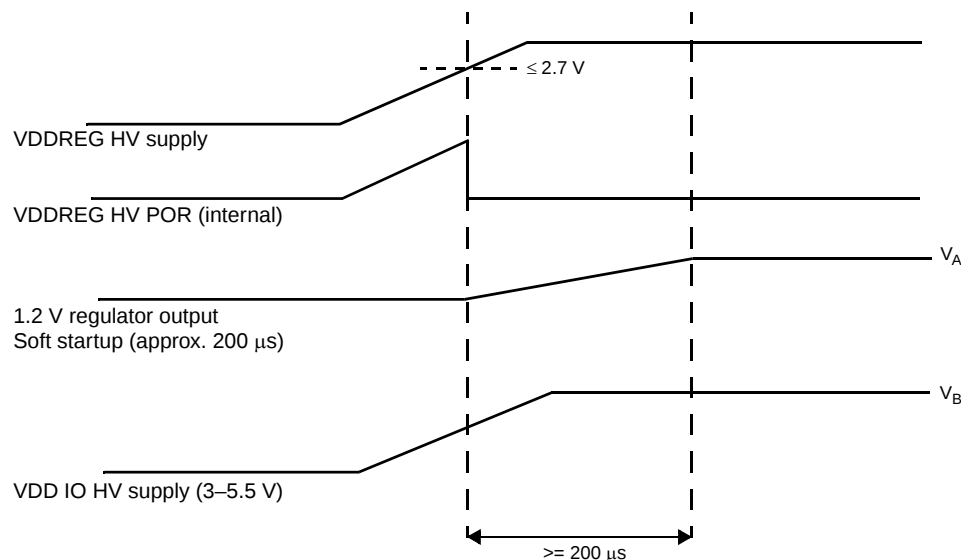


Figure 8. Recommended order for powering up the power supplies

CAUTION

The voltages V_A and V_B in Figure 8 must always obey the relation $V_B \geq V_A - 0.7$ V. Otherwise, currents from the 1.2 V supply to the 3.3 V supply may result.

Figure 9 shows the recommended order for powering down the power supplies on this device.

It is acceptable for the VDD IO HV supply to ramp down faster than the 1.2 V regulator output, even if the latter takes time to discharge the high 40 μ F capacitance. (The capacitor will ultimately discharge.)

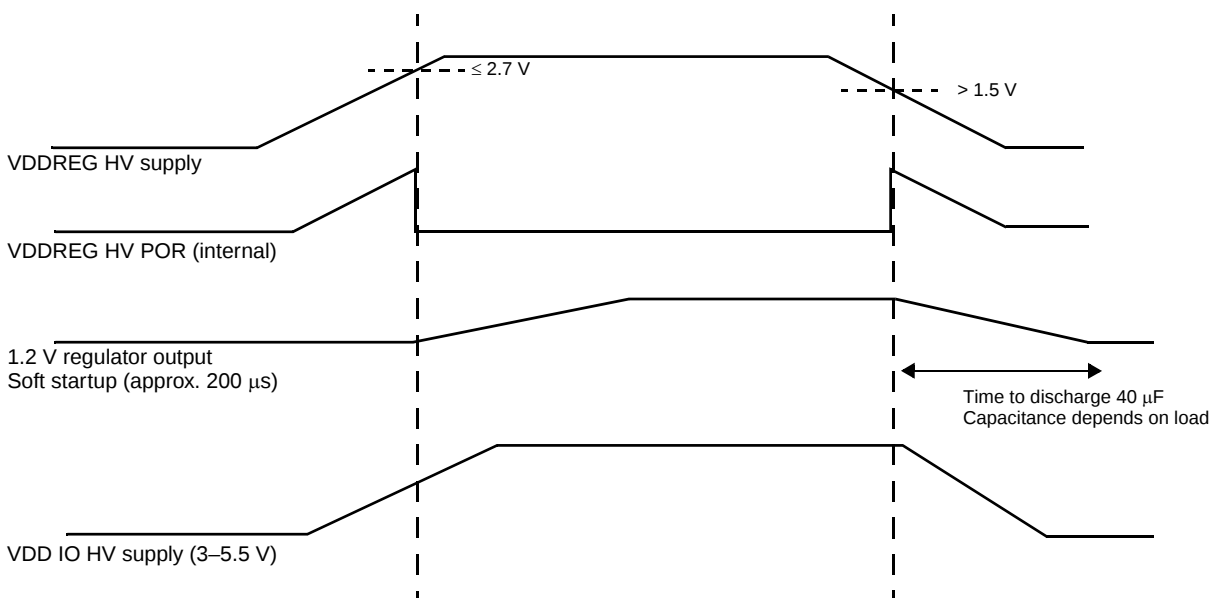


Figure 9. Recommended order for powering down the power supplies

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CAUTION

The VDD IO HV supply must be disabled after the VDDREG HV supply voltage drops below 1.5 V. This is to ensure that the 1.2 V regulator shuts down before the 3.3 V regulator shuts down.

3.7.5 Power-up inrush current profile

Figure 10 shows the power up inrush current profile of the ballast transistor under the worst possible startup condition (fastest PVT and fastest power ramp time).

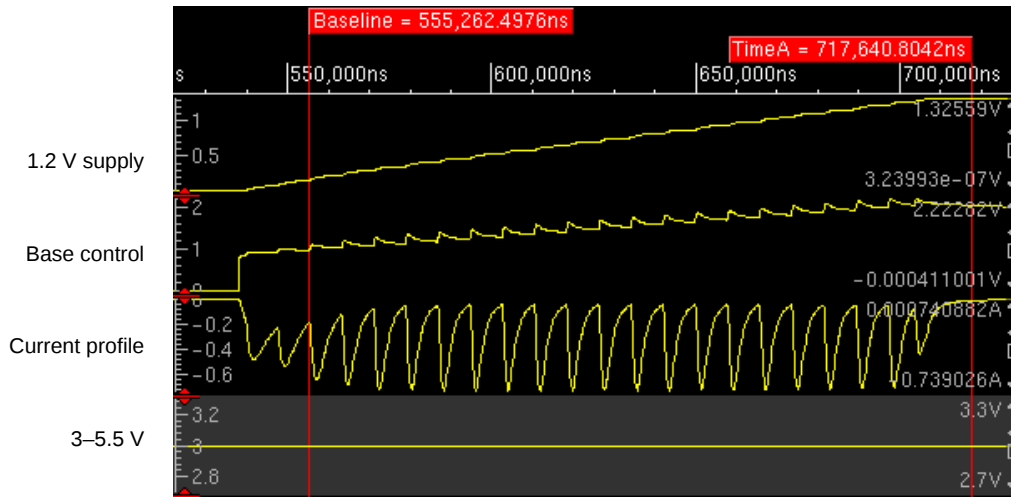


Figure 10. Power-up inrush current profile

The HPREG has a “soft startup” profile which increases the supply in steps of approximately 50 mV in a series of approximately 25 steps. Therefore, the peak current is within 750 mA of the maximum current during startup. This eliminates any noise on the VDDR supply during startup and charging of NPN emitter stability capacitance of 40 μ F (minimum).

Soft startup also occurs when waking up from standby mode to limit noise on the VDDR supply.

In case VDDR is shared between the device and the ballast, it must be star routed on the board or isolated as much as possible to avoid any noise injected by the ballast. Soft startup will help to limit this noise but a VDDR capacitor close to the ballast pin is critical here. A minimum capacitance of 10 μ F is needed.

Table 29 shows the typical and maximum startup currents.

Table 29. Startup current

Symbol		C	Parameter	Value		Unit
				Typ	Max	
I _{START}	CC	P	Startup current	300	800	mA

3.7.6 HPREG load regulation characteristics

The HPREG exhibits a very strong load-regulation behavior (the transition from low- to high-current state is regulated quickly). This is illustrated in Figure 12, which shows a 10–150 mA jump over 10 ns. Under any case of load transition, the HPREG responds within 100 ns and stabilizes within 5 μ s. This helps improve the stability of the 1.2 V supply and settling time.

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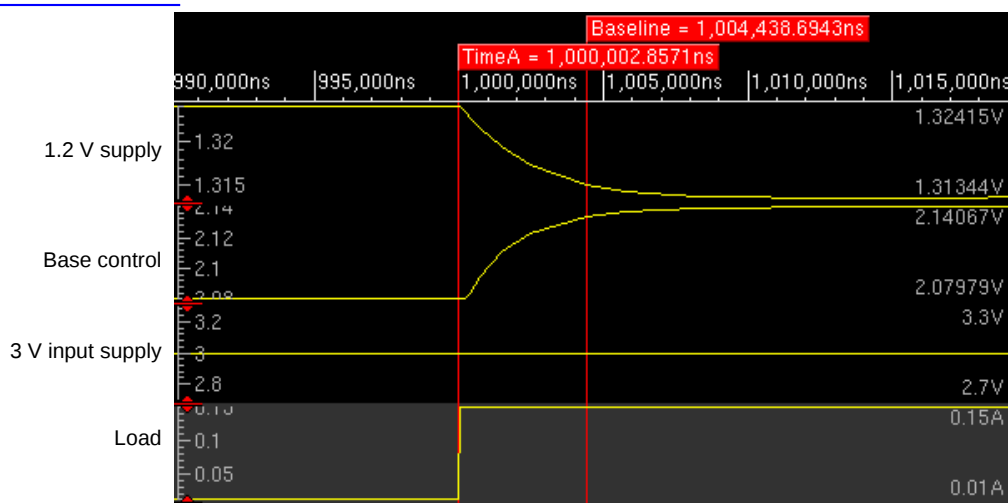


Figure 11. HPREG load regulation

3.8 I/O pad electrical characteristics

3.8.1 I/O pad types

The device provides five main I/O pad types:

- Slow pads — These are the most common pads, providing a good compromise between transition time and low electromagnetic emission.
- Medium pads — These are provided in two types (M1 and M2) and provide transitions fast enough for the serial communication channels. M2 pads include slew rate control.
- Fast pads — These provide maximum speed. There are used for improved NEXUS debugging capability.
- SMD pads — These provide additional current capability to drive stepper motor loads.
- Digital I/O with analog (J) pad — These provide input and output digital features and analog input for ADC.

M2 and Fast pads can disable slew rate to reduce electromagnetic emission, at the cost of reducing AC performance.

3.8.2 I/O input DC characteristics

Table 30 provides input DC electrical characteristics as described in Figure 12.

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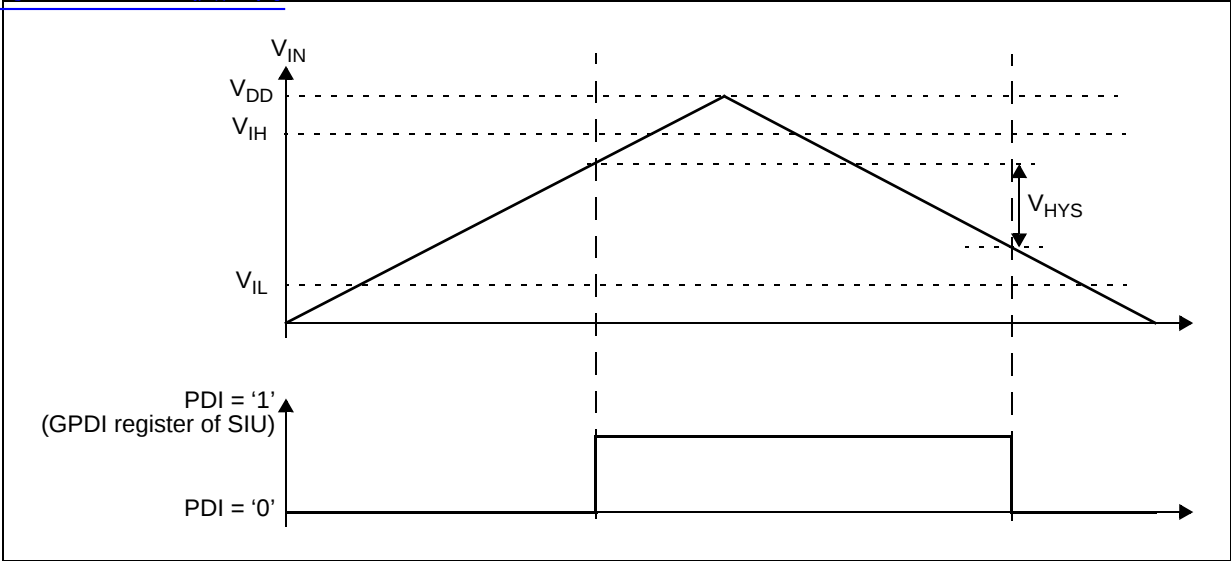


Figure 12. I/O Input DC electrical characteristics definition

Table 30. I/O input DC electrical characteristics

Symbol	C		Parameter	Conditions ¹	Value ²			Unit
					Min	Typ	Max	
V_{IH}	SR	P	Input high level CMOS Schmitt trigger	—	$0.65V_{DD}$	—	$V_{DD} + 0.4$	V
V_{IL}	SR	P	Input low level CMOS Schmitt trigger	—	-0.4	—	$0.35V_{DD}$	
V_{HYS}	CC	D	Input hysteresis CMOS Schmitt trigger	—	$0.1V_{DD}$	—	—	
I_{LKG}	CC	P	Input leakage current	—	-1	—	1	μA
R_{ON}	CC	P	Resistance of the analog switch inside the J pad type ³	Supply range 3.3–5 V	—	—	1	$k\Omega$

¹ $V_{DD} = 3.3\text{ V} \pm 10\% / 5.0\text{ V} \pm 10\%$, $T_A = -40$ to $105\text{ }^\circ\text{C}$.

² All values need to be confirmed during device characterization.

³ Applies to the J pad type only.

3.8.3 I/O output DC characteristics

The following tables provide DC characteristics for bidirectional pads:

- [Table 31](#) provides weak pull figures. Both pullup and pulldown resistances are supported.
- [Table 32](#) provides output driver characteristics for I/O pads when in SLOW configuration.
- [Table 33](#) provides output driver characteristics for I/O pads when in MEDIUM configuration (applies to both M1 and M2 type pads).
- [Table 34](#) provides output driver characteristics for I/O pads when in FAST configuration.
- [Table 35](#) provides SMD pad characteristics.

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Table 31. I/O pullup/pulldown DC electrical characteristics

Symbol	C	Parameter	Conditions ¹	Value ²			Unit
				Min	Typ	Max	
I_{WPU}	CC	P	Weak pullup current absolute value	—	10	—	150
I_{WPD}	CC	P	Weak pulldown current absolute value	—	10	—	150
I_{LKG}	CC	P	Input leakage current	Output programmed low Weak pullup disabled	—1	—	1

¹ $V_{DD} = 3.3 \text{ V} \pm 10\% / 5.0 \text{ V} \pm 10\%$, $T_A = -40$ to 105°C , unless otherwise specified.

² All values need to be confirmed during device characterization.

Table 32. SLOW configuration output buffer electrical characteristics

Symbol	C	Parameter	Conditions ¹	Value ²			Unit
				Min	Typ	Max	
V_{OH}	CC	P	Output high level SLOW configuration	Push Pull, $I_{OH} = -2 \text{ mA}$, $V_{DD} = 5.0 \text{ V} \pm 10\%$, PAD3V5V = 0 (recommended)	$0.8V_{DD}$	—	V
		D		Push Pull, $I_{OH} = -2 \text{ mA}$, $V_{DD} = 5.0 \text{ V} \pm 10\%$, PAD3V5V = 1 ³	$0.8V_{DD}$	—	
		C		Push Pull, $I_{OH} = -1 \text{ mA}$, $V_{DD} = 3.3 \text{ V} \pm 10\%$, PAD3V5V = 1 (recommended)	$V_{DD} - 0.8$	—	
V_{OL}	CC	P	Output low level SLOW configuration	Push Pull, $I_{OL} = 2 \text{ mA}$, $V_{DD} = 5.0 \text{ V} \pm 10\%$, PAD3V5V = 0 (recommended)	—	$0.1V_{DD}$	V
		D		Push Pull, $I_{OL} = 2 \text{ mA}$, $V_{DD} = 5.0 \text{ V} \pm 10\%$, PAD3V5V = 1 ³	—	$0.1V_{DD}$	
		C		Push Pull, $I_{OL} = 1 \text{ mA}$, $V_{DD} = 3.3 \text{ V} \pm 10\%$, PAD3V5V = 1 (recommended)	—	0.5	

Table 32. SLOW configuration output buffer electrical characteristics (continued)

Symbol	C	Parameter	Conditions ¹	Value ²			Unit
				Min	Typ	Max	
T _{tr}	CC	T Output transition time output pin ⁴ SLOW configuration	C _L = 25 pF, V _{DD} = 5.0 V ± 10%, PAD3V5V = 0	—	—	50	ns
			C _L = 50 pF, V _{DD} = 5.0 V ± 10%, PAD3V5V = 0	—	—	100	
			C _L = 100 pF, V _{DD} = 5.0 V ± 10%, PAD3V5V = 0	—	—	125	
			C _L = 25 pF, V _{DD} = 3.3 V ± 10%, PAD3V5V = 1	—	—	40	
			C _L = 50 pF, V _{DD} = 3.3 V ± 10%, PAD3V5V = 1	—	—	50	
			C _L = 100 pF, V _{DD} = 3.3 V ± 10%, PAD3V5V = 1	—	—	75	
ΔI _{tr50}	CC	D Current slew at C _L = 50 pF SLOW configuration	recommended configuration at V _{DD} = 5.0 V ± 10%, PAD3V5V = 0 V _{DD} = 3.3 V ± 10%, PAD3V5V = 1	—	—	2	mA/ns
			V _{DD} = 5.0 V ± 10%, PAD3V5V = 1	—	—	7	

¹ V_{DD} = 3.3 V ± 10% / 5.0 V ± 10%, T_A = -40 to 105 °C, unless otherwise specified

² All values need to be confirmed during device characterization.

³ This is a transient configuration during power-up. All pads but $\overline{\text{RESET}}$ and NEXUS output (MDOx, EVTO, MCK) are configured in input or in high impedance state.

⁴ C_L calculation should include device and package capacitances (C_{PKG} < 5 pF).

Table 33. MEDIUM configuration output buffer electrical characteristics

Symbol	C	Parameter	Conditions ¹	Value ²			Unit
				Min	Typ	Max	
V _{OH}	CC	P Output high level MEDIUM configuration	Push Pull, I _{OH} = -2 mA, V _{DD} = 5.0 V ± 10%, PAD3V5V = 0 (recommended)	0.8V _{DD}	—	—	V
			Push Pull, I _{OH} = -1 mA, V _{DD} = 5.0 V ± 10%, PAD3V5V = 1 ³	0.8V _{DD}	—	—	
			Push Pull, I _{OH} = -1 mA, V _{DD} = 3.3 V ± 10%, PAD3V5V = 1 (recommended)	V _{DD} - 0.8	—	—	
V _{OL}	CC	P Output low level MEDIUM configuration	Push Pull, I _{OL} = 2 mA, V _{DD} = 5.0 V ± 10%, PAD3V5V = 0 (recommended)	—	—	0.1V _{DD}	V
			Push Pull, I _{OL} = 1 mA, V _{DD} = 5.0 V ± 10%, PAD3V5V = 1 ³	—	—	0.1V _{DD}	
			Push Pull, I _{OL} = 1 mA, V _{DD} = 3.3 V ± 10%, PAD3V5V = 1 (recommended)	—	—	0.5	

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Table 33. MEDIUM configuration output buffer electrical characteristics (continued)

Symbol	C	Parameter	Conditions ¹	Value ²			Unit
				Min	Typ	Max	
T _{tr}	CC	T Output transition time output pin ⁴ MEDIUM configuration	C _L = 25 pF, V _{DD} = 5.0 V ± 10%, PAD3V5V = 0	—	—	10	ns
			C _L = 50 pF, V _{DD} = 5.0 V ± 10%, PAD3V5V = 0	—	—	20	
			C _L = 100 pF, V _{DD} = 5.0 V ± 10%, PAD3V5V = 0	—	—	40	
			C _L = 25 pF, V _{DD} = 3.3 V ± 10%, PAD3V5V = 1	—	—	12	
			C _L = 50 pF, V _{DD} = 3.3 V ± 10%, PAD3V5V = 1	—	—	25	
			C _L = 100 pF, V _{DD} = 3.3 V ± 10%, PAD3V5V = 1	—	—	40	
ΔI _{tr50}	CC	D Current slew at C _L = 50 pF MEDIUM configuration	recommended configuration at V _{DD} = 5.0 V ± 10%, PAD3V5V = 0 V _{DD} = 3.3 V ± 10%, PAD3V5V = 1	—	—	7	mA/ns
			V _{DD} = 5.0 V ± 10%, PAD3V5V = 1	—	—	16	

¹ V_{DD} = 3.3 V ± 10% / 5.0 V ± 10%, T_A = -40 to 105 °C, unless otherwise specified

² All values need to be confirmed during device characterization.

³ This is a transient configuration during power-up. All pads but $\overline{\text{RESET}}$ and NEXUS output (MDOx, EVTO, MCK) are configured in input or in high impedance state.

⁴ C_L includes device and package capacitance (C_{PKG} < 5 pF).

Table 34. FAST configuration output buffer electrical characteristics

Symbol	C	Parameter	Conditions ¹	Value ²			Unit
				Min	Typ	Max	
V _{OH}	CC	P Output high level FAST configuration	Push Pull, I _{OH} = -14 mA, V _{DD} = 5.0 V ± 10%, PAD3V5V = 0 (recommended)	0.8V _{DD}	—	—	V
			Push Pull, I _{OH} = -7 mA, V _{DD} = 5.0 V ± 10%, PAD3V5V = 1 ³	0.8V _{DD}	—	—	
			Push Pull, I _{OH} = -11 mA, V _{DD} = 3.3 V ± 10%, PAD3V5V = 1 (recommended)	V _{DD} - 0.8	—	—	
V _{OL}	CC	P Output low level FAST configuration	Push Pull, I _{OL} = 14 mA, V _{DD} = 5.0 V ± 10%, PAD3V5V = 0 (recommended)	—	—	0.1V _{DD}	V
			Push Pull, I _{OL} = 7 mA, V _{DD} = 5.0 V ± 10%, PAD3V5V = 1 ³	—	—	0.1V _{DD}	
			Push Pull, I _{OL} = 11 mA, V _{DD} = 3.3 V ± 10%, PAD3V5V = 1 (recommended)	—	—	0.5	

Table 34. FAST configuration output buffer electrical characteristics (continued)

Symbol	C	Parameter	Conditions ¹	Value ²			Unit
				Min	Typ	Max	
T _{tr}	CC	T Output transition time output pin ⁴ FAST configuration	C _L = 25 pF, V _{DD} = 5.0 V ± 10%, PAD3V5V = 0	—	—	4	ns
			C _L = 50 pF, V _{DD} = 5.0 V ± 10%, PAD3V5V = 0	—	—	6	
			C _L = 100 pF, V _{DD} = 5.0 V ± 10%, PAD3V5V = 0	—	—	12	
			C _L = 25 pF, V _{DD} = 3.3 V ± 10%, PAD3V5V = 1	—	—	4	
			C _L = 50 pF, V _{DD} = 3.3 V ± 10%, PAD3V5V = 1	—	—	7	
			C _L = 100 pF, V _{DD} = 3.3 V ± 10%, PAD3V5V = 1	—	—	12	
ΔI _{tr50}	CC	D Current slew at C _L = 50 pF FAST configuration	V _{DD} = 5.0 V ± 10%, PAD3V5V = 0 (recommended configuration)	—	—	55	mA/ns
			V _{DD} = 3.3 V ± 10%, PAD3V5V = 1 (recommended configuration)	—	—	40	
			V _{DD} = 5.0 V ± 10%, PAD3V5V = 1	—	—	100	

¹ V_{DD} = 3.3 V ± 10% / 5.0 V ± 10%, T_A = -40 to 105 °C, unless otherwise specified

² All values need to be confirmed during device characterization.

³ This is a transient configuration during power-up. All pads but $\overline{\text{RESET}}$ and NEXUS output (MDOx, EVTO, MCK) are configured in input or in high impedance state.

⁴ C_L includes device and package capacitance (C_{PKG} < 5 pF).

Table 35. SMC pad electrical characteristics

Symbol	C	Parameter	Conditions	Value			Unit
				Min	Typ	Max	
V _{IL}	CC	P	Low level input voltage	—	—	0.35×V _{DDM}	V
V _{IH}	CC	P	High level input voltage	—	—	V _{DDM} +0.4	
V _{HYST}	CC	C	Schmitt trigger hysteresis	—	—	—	
V _{OL}	CC	P	Low level output voltage	I _{OL} = 20 mA ¹	—	0.32	
				I _{OL} = 30 mA ²	—	0.48	
V _{OH}	CC	P	High level output voltage	I _{OH} = -20 mA ¹	V _{DDM} -0.32	—	
				I _{OH} = -30 mA ²	V _{DDM} -0.48	—	

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Table 35. SMC pad electrical characteristics (continued)

Symbol	C	Parameter	Conditions	Value			Unit
				Min	Typ	Max	
I_{PU}	CC	P	Internal pullup device current	$V_{in}=V_{IL}$	—	—	μA
				$V_{in}=V_{IH}$	—	—10	
I_{PD}	CC	P	Internal pulldown device current	$V_{in}=V_{IL}$	—	—	
				$V_{in}=V_{IH}$	—	130	
I_{IN}	CC	P	Input leakage current	—	TBD	TBD	
R_{DSONH}	CC	C	SMC pad driver active high impedance	$I_{OH} \leq -30 \text{ mA}$	—	—	Ω
R_{DSONL}	CC	C	SMC pad driver active low impedance	$I_{OL} \leq 30 \text{ mA}$	—	—	Ω
V_{OMATCH}	CC	P	Output driver matching V_{OH} / V_{OL}	$I_{OH} / I_{OL} \leq 30 \text{ mA}$	—	—	mV

¹ For temperature range -40 – 150 °C.² For temperature range -40 – 130 °C.

3.8.4 I/O pad current specification

The I/O pads are distributed across the I/O supply segment. Each I/O supply segment is associated to a V_{DD}/V_{SS} supply pair as described in Table 36.

Table 37 provides I/O consumption figures.

In order to ensure device reliability, the average current of the I/O on a single segment should remain below the I_{AVGSEG} maximum value.

In order to ensure device functionality, the sum of the dynamic and static current of the I/O on a single segment should remain below the I_{DYNSEG} maximum value.

Table 36. I/O supply segment

Package	Supply segment				
	A ¹	B ²	C ^{3,4}	D ⁵	E ⁶
144 LQFP	pins 1–21 pins 113–144	pins 22– 52	pins 53–72	pins 73–102	pins 103–112
176 LQFP	pins 1–21 pins 143–176	pins 22–68	pins 69–88	pins 89–118	pins 119–142

¹ LCD pad segment containing pad supplies V_{DDE_A} ² Miscellaneous pad segment containing pad supplies V_{DDE_B} ³ ADC pad segment containing pad supplies V_{DDE_C} ⁴ V_{DDE_C} should be the same as V_{DDA} with a 100 mV variation, i.e., $V_{DDE_C} = V_{DDA} \pm 100 \text{ mV}$.⁵ Stepper Motor pad segment containing I/O supplies V_{DDMA} , V_{DDMB} , V_{DDMC} ⁶ Miscellaneous pad segment containing pad supplies V_{DDE_E}

Table 37. I/O consumption

Symbol		C	Parameter	Conditions ¹	Value ²			Unit
					Min	Typ	Max	
I _{SWTSLW}	CC	D	Dynamic I/O current for SLOW configuration	C _L = 25 pF, V _{DD} = 5.0 V ± 10%, PAD3V5V = 0	—	—	20	mA
		D		C _L = 25 pF, V _{DD} = 3.3 V ± 10%, PAD3V5V = 1	—	—	16	
I _{SWTMED}	CC	D	Dynamic I/O current for MEDIUM configuration	C _L = 25 pF, V _{DD} = 5.0 V ± 10%, PAD3V5V = 0	—	—	29	mA
		D		C _L = 25 pF, V _{DD} = 3.3 V ± 10%, PAD3V5V = 1	—	—	17	
I _{SWTFST}	CC	D	Dynamic I/O current for FAST configuration	C _L = 25 pF, V _{DD} = 5.0 V ± 10%, PAD3V5V = 0	—	—	110	mA
		D		C _L = 25 pF, V _{DD} = 3.3 V ± 10%, PAD3V5V = 1	—	—	50	
I _{RMSSLW}	CC	D	Root medium square I/O current for SLOW configuration	C _L = 25 pF, 2 MHz V _{DD} = 5.0 V ± 10%, PAD3V5V = 0	—	—	2.3	mA
		D		C _L = 25 pF, 4 MHz V _{DD} = 5.0 V ± 10%, PAD3V5V = 0	—	—	3.2	
		D		C _L = 100 pF, 2 MHz V _{DD} = 5.0 V ± 10%, PAD3V5V = 0	—	—	6.6	
		D		C _L = 25 pF, 2 MHz V _{DD} = 3.3 V ± 10%, PAD3V5V = 1	—	—	1.6	
		D		C _L = 25 pF, 4 MHz V _{DD} = 3.3 V ± 10%, PAD3V5V = 1	—	—	2.3	
		D		C _L = 100 pF, 2 MHz V _{DD} = 3.3 V ± 10%, PAD3V5V = 1	—	—	4.7	
I _{RMSMED}	CC	D	Root medium square I/O current for MEDIUM configuration	C _L = 25 pF, 2 MHz V _{DD} = 5.0 V ± 10%, PAD3V5V = 0	—	—	6.6	mA
		D		C _L = 25 pF, 4 MHz V _{DD} = 5.0 V ± 10%, PAD3V5V = 0	—	—	13.4	
		D		C _L = 100 pF, 2 MHz V _{DD} = 5.0 V ± 10%, PAD3V5V = 0	—	—	18.3	
		D		C _L = 25 pF, 2 MHz V _{DD} = 3.3 V ± 10%, PAD3V5V = 1	—	—	5.0	
		D		C _L = 25 pF, 4 MHz V _{DD} = 3.3 V ± 10%, PAD3V5V = 1	—	—	8.5	
		D		C _L = 100 pF, 2 MHz V _{DD} = 3.3 V ± 10%, PAD3V5V = 1	—	—	11.0	

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Table 37. I/O consumption (continued)

Symbol	C	Parameter	Conditions ¹	Value ²			Unit
				Min	Typ	Max	
I _{RMSFST}	CC	D Root medium square I/O current for FAST configuration	C _L = 25 pF, 2 MHz V _{DD} = 5.0 V ± 10%, PAD3V5V = 0	—	—	22.0	mA
			C _L = 25 pF, 4 MHz V _{DD} = 5.0 V ± 10%, PAD3V5V = 0	—	—	33.0	
			C _L = 100 pF, 2 MHz V _{DD} = 5.0 V ± 10%, PAD3V5V = 0	—	—	56.0	
			C _L = 25 pF, 2 MHz V _{DD} = 3.3 V ± 10%, PAD3V5V = 1	—	—	14.0	
			C _L = 25 pF, 4 MHz V _{DD} = 3.3 V ± 10%, PAD3V5V = 1	—	—	20.0	
			C _L = 100 pF, 2 MHz V _{DD} = 3.3 V ± 10%, PAD3V5V = 1	—	—	25.0	
I _{DYNSEG}	SR	D Sum of all the dynamic and static I/O current within a supply segment	V _{DD} = 5.0 V ± 10%, PAD3V5V = 0	—	—	110	mA
			V _{DD} = 3.3 V ± 10%, PAD3V5V = 1	—	—	65	
I _{AVGSEG}	SR	D Sum of all the static I/O current within a supply segment	V _{DD} = 5.0 V ± 10%, PAD3V5V = 0	—	—	70	mA
			V _{DD} = 3.3 V ± 10%, PAD3V5V = 1	—	—	65	
I _{DDMXAVG}	SR	D Sum of currents of two motors assigned to segment V _{DDMX} , V _{SSMX} pair	V _{DD} = 5.0 V ± 10%, PAD3V5V = 0 T _J = 130 °C	—	—	90	
			V _{DD} = 5.0 V ± 10%, PAD3V5V = 0 T _J = -40 °C	—	—	120	

¹ V_{DD} = 3.3 V ± 10% / 5.0 V ± 10%, T_A = -40 to 105 °C, unless otherwise specified² All values need to be confirmed during device characterization.

3.9 SSD specifications

3.9.1 Electrical characteristics

Table 38. SSD electrical characteristics

Symbol	C	Parameter	Value			Unit
			Min	Typ	Max	
V _{VREF}	CC	P Reference voltage (I _{VREF} = 0)	V _{DDM} /2 - 0.02	V _{DDM} /2	V _{DDM} /2 + 0.02	V
I _{VREF}	CC	P Reference voltage output current	2.5	—	—	mA
R _{IN}	CC	D Input resistance (against V _{DDM} /2)	0.8	1.0	1.2	MΩ
V _{IN}	CC	C Input common mode range	V _{SSM}	—	V _{DDM}	V
SSD _{CONST}	CC	C SSD constant	0.549	0.572	0.597	—

Table 38. SSD electrical characteristics (continued)

Symbol	C	Parameter	Value			Unit
			Min	Typ	Max	
SSD _{OFFSET}	CC	C SSD offset (unipolar, N _{sample} = 256)	−9	—	9	counts
		SSD offset (bipolar, N _{sample} = 256)	−8	—	8	
		SSD offset (bipolar with offset cancellation, N _{sample} = 256)	−5	—	5	
f _{SSDSMP}	CC	D SSD cmpout sample rate	0.5	—	2.0	MHz

3.9.2 Accumulator values

Equation 5 describes the accumulator value in unipolar configuration. The voltage V_{in} is applied between the integrator input and V_{DDM} . The internal generated reference voltage is not connected. The accumulator value is a function of V_{DDM} , the number of samples (N_{sample}) taken and the SSD constant (SSDconst). The SSD constant and offset (SSDconst, SSDoffset) vary with temperature and process.

$$ACCval = \frac{V_{in} - (V_{DDM})/2}{V_{DDM} \cdot SSDconst} \cdot Nsample + SSDoffset$$

Eqn. 5

Equation 6 describes the accumulator value in bipolar configuration. The voltage V_{in} is applied between the integrator input and the reference output. The accumulator value depends on the same parameters as in the unipolar case but the inaccuracy of the voltage reference (V_{vref}) is compensated.

$$ACCval = \frac{V_{in}}{V_{DDM} \cdot SSDconst} \cdot Nsample + SSDoffset$$

Eqn. 6

3.10 $\overline{\text{RESET}}$ electrical characteristics

The device implements a dedicated bidirectional $\overline{\text{RESET}}$ pin.

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Figure 13. Start-up reset requirements

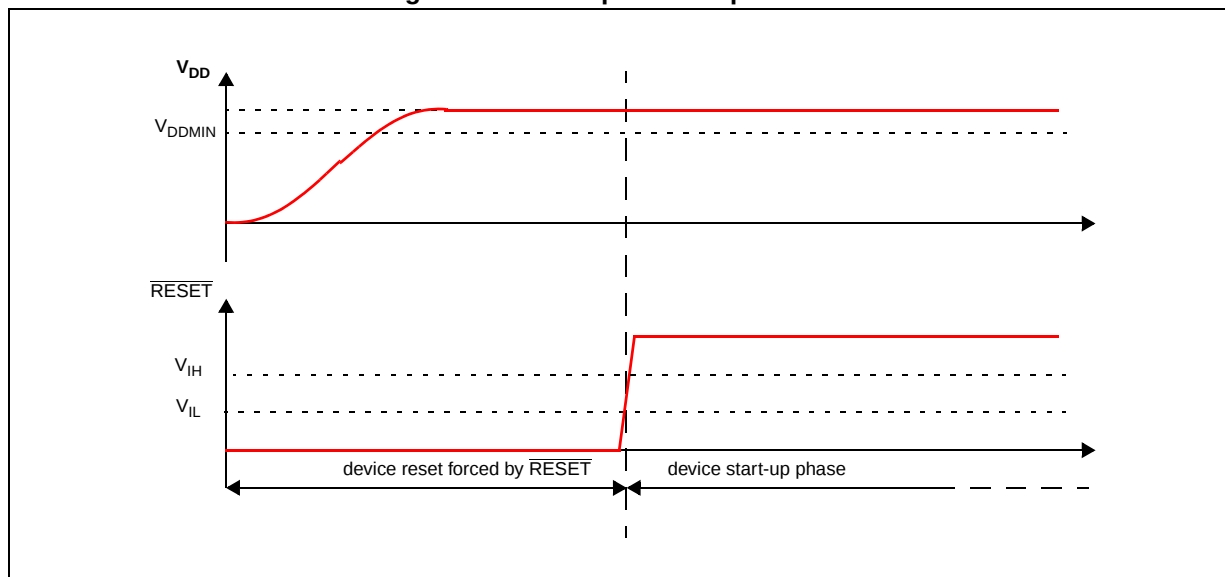


Figure 14. Noise filtering on reset signal

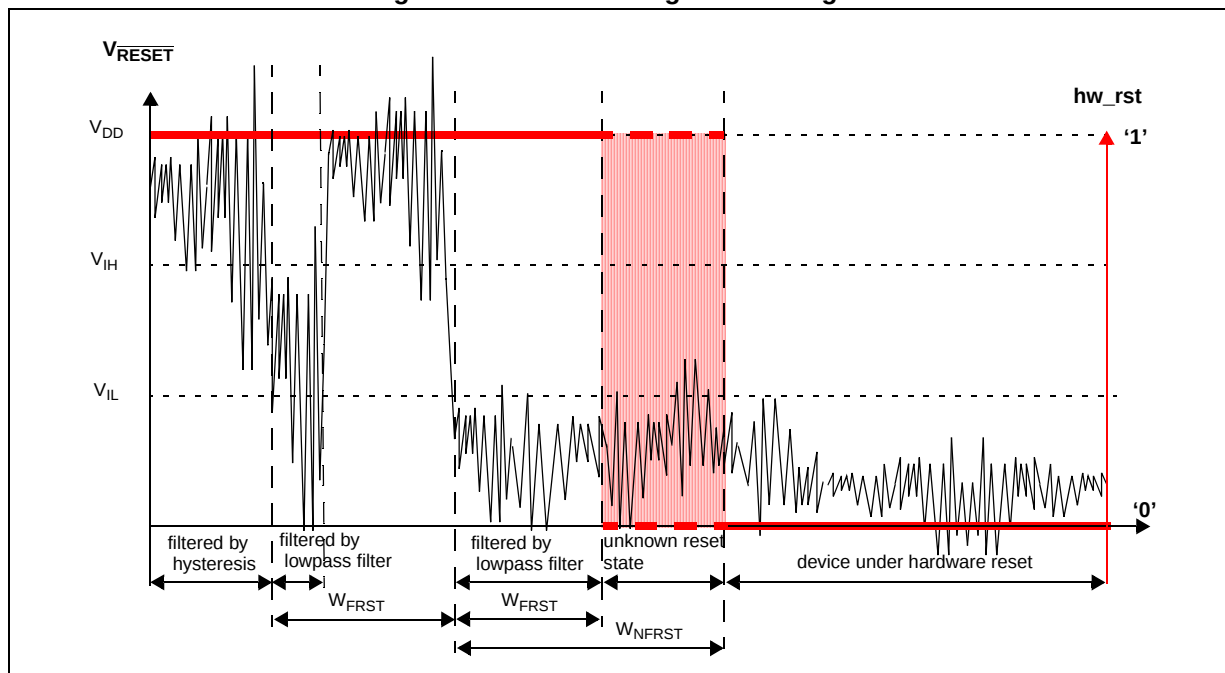


Table 39. Reset electrical characteristics

Symbol	C	Parameter	Conditions ¹	Value ²			Unit
				Min	Typ	Max	
V _{IH}	SR	P	Input high level CMOS Schmitt Trigger	—	—	V _{DD} + 0.4	V
V _{IL}	SR	P	Input low level CMOS Schmitt Trigger	—	—	0.35V _{DD}	V
V _{HYS}	CC	D	Input hysteresis CMOS Schmitt Trigger	—	—	—	V
V _{OL}	CC	P	Output low level Push Pull, I _{OL} = 2 mA, V _{DD} = 5.0 V ± 10%, PAD3V5V = 0 (recommended)	—	—	0.1V _{DD}	V
		D	Push Pull, I _{OL} = 1 mA, V _{DD} = 5.0 V ± 10%, PAD3V5V = 1 ³	—	—	0.1V _{DD}	
		C	Push Pull, I _{OL} = 1 mA, V _{DD} = 3.3 V ± 10%, PAD3V5V = 1 (recommended)	—	—	0.5	
T _{tr}	CC	T	Output transition time output pin ⁴ MEDIUM configuration C _L = 25 pF, V _{DD} = 5.0 V ± 10%, PAD3V5V = 0	—	—	10	ns
		T	C _L = 50 pF, V _{DD} = 5.0 V ± 10%, PAD3V5V = 0	—	—	20	
		T	C _L = 100 pF, V _{DD} = 5.0 V ± 10%, PAD3V5V = 0	—	—	40	
		T	C _L = 25 pF, V _{DD} = 3.3 V ± 10%, PAD3V5V = 1	—	—	12	
		T	C _L = 50 pF, V _{DD} = 3.3 V ± 10%, PAD3V5V = 1	—	—	25	
		T	C _L = 100 pF, V _{DD} = 3.3 V ± 10%, PAD3V5V = 1	—	—	40	
W _{FRST}	SR	P	$\overline{\text{RESET}}$ input filtered pulse	—	—	40	ns
W _{NFRST}	SR	P	$\overline{\text{RESET}}$ input not filtered pulse	—	1000	—	ns
I _{WPU}	CC	P	Weak pullup current absolute value	—	10	150	μA

¹ V_{DD} = 3.3 V ± 10% / 5.0 V ± 10%, T_A = -40 to 105 °C, unless otherwise specified

² All values need to be confirmed during device characterization.

³ This is a transient configuration during power-up, up to the end of reset PHASE2 (refer to reset generation module (RGM) section of the device reference manual).

⁴ C_L includes device and package capacitance (C_{PKG} < 5 pF).

3.11 Fast external crystal oscillator (4–16 MHz) electrical characteristics

The device provides an oscillator/resonator driver. Figure 15 describes a simple model of the internal oscillator driver and provides an example of a connection for an oscillator or a resonator.

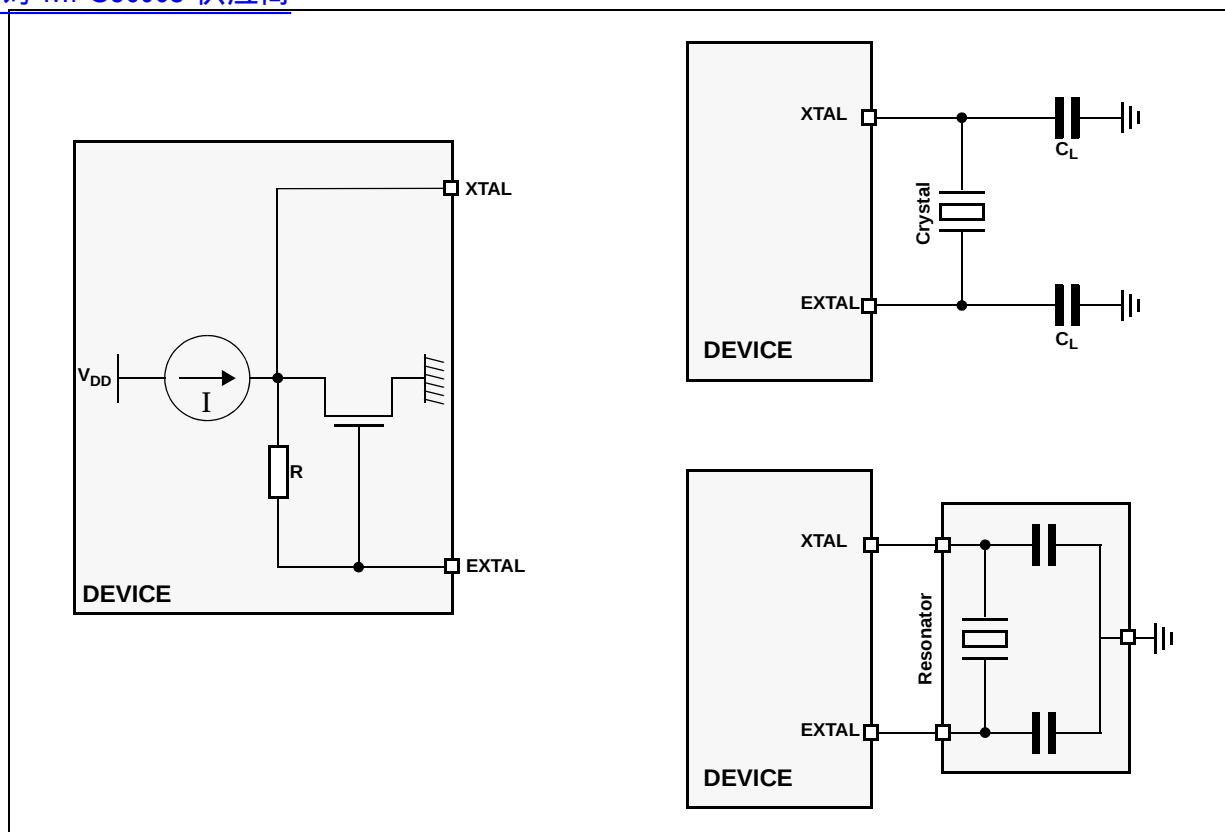
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Figure 15. Crystal oscillator and resonator connection scheme

NOTE

XTAL/EXTAL must not be directly used to drive external circuits.

Table 40. Crystal description

Nominal frequency (MHz)	NDK crystal reference	Crystal equivalent series resistance ESR Ω	Crystal motional capacitance (C_m) fF	Crystal motional inductance (L_m) mH	Load on xtalin/xtalout $C1 = C2$ (pF) ¹	Shunt capacitance between xtalout and xtalin $C0^2$ (pF)
4	NX8045GB	300	2.68	591.0	21	2.93
8	NX5032GA	300	2.46	160.7	17	3.01
10		150	2.93	86.6	15	2.91
12		120	3.11	56.5	15	2.93
16		120	3.90	25.3	10	3.00

¹ The values specified for C1 and C2 are the same as used in simulations. It should be ensured that the testing includes all the parasitics (from the board, probe, crystal, etc.) as the AC / transient behavior depends upon them.

² The value of C0 specified here includes 2 pF additional capacitance for parasitics (to be seen with bond-pads, package, etc.).

Table 41. Resonator description

	CSTCR4M00G53-R0	CSTCR4M00G55-R0
Vibration	Fundamental	
Fr (kHz)	3929.50	3898.00
Fa (kHz)	4163.25	4123.00
Fa–Fr (dF) (kHz)	233.75	225.00
Ra (k Ω)	372.41	465.03
R1 (Ω)	12.78	11.38
L1 (mH)	0.84443	0.88244
C1 (pF)	1.94268	1.88917
Co (pF)	15.85730	15.90537
Qm	1630.93	1899.77
CL1 (nominal) (pF)	15	39
CL2 (nominal) (pF)	15	39

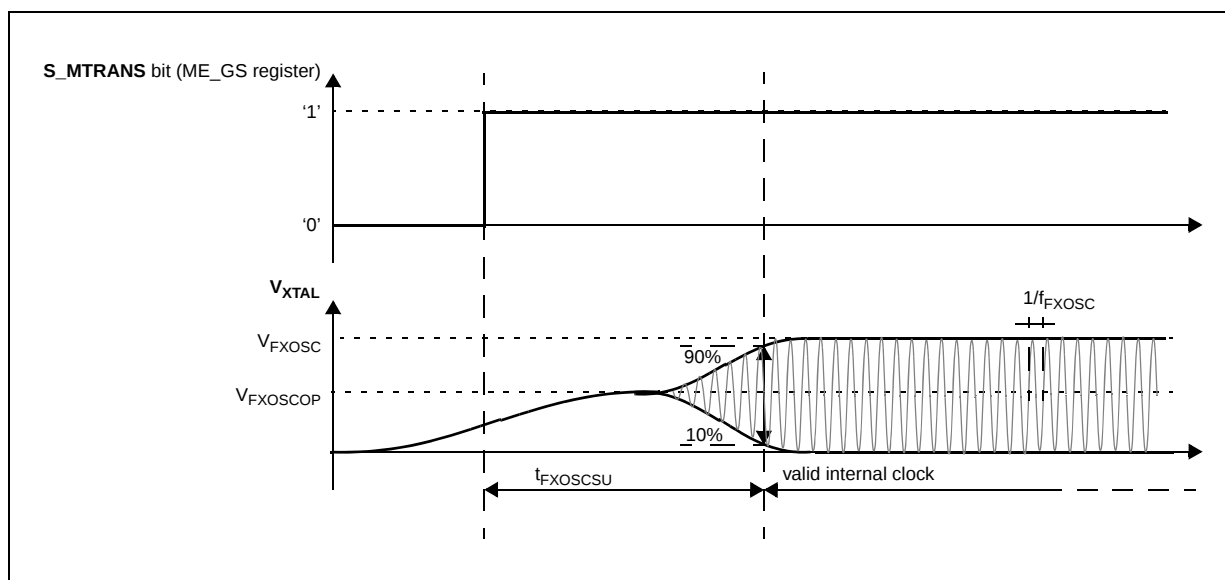


Figure 16. Fast external crystal oscillator (4–16 MHz) electrical characteristics

Table 42. Fast external crystal oscillator (4 to 16 MHz) electrical characteristics

Symbol	C	Parameter	Conditions ¹	Value ²			Unit
				Min	Typ	Max	
f _{FXOSC}	SR	Fast external crystal oscillator frequency	—	4.0	—	16.0	MHz

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Table 42. Fast external crystal oscillator (4 to 16 MHz) electrical characteristics (continued)

Symbol		C	Parameter	Conditions ¹	Value ²			Unit
					Min	Typ	Max	
g _{mFXOSC}	CC	C	Fast external crystal oscillator transconductance	V _{DD} = 3.3 V ± 10%, PAD3V5V = 1 OSCILLATOR_MARGIN = 0	2.2	—	8.2	mA/V
	CC	P		V _{DD} = 5.0 V ± 10%, PAD3V5V = 0 OSCILLATOR_MARGIN = 0	2.0	—	7.4	
	CC	C		V _{DD} = 3.3 V ± 10%, PAD3V5V = 1 OSCILLATOR_MARGIN = 1	2.7	—	9.7	
	CC	C		V _{DD} = 5.0 V ± 10%, PAD3V5V = 0 OSCILLATOR_MARGIN = 1	2.5	—	9.2	
V _{FXOSC}	CC	T	Oscillation amplitude at EXTAL	f _{OSC} = 4 MHz, OSCILLATOR_MARGIN = 0	1.3	—	—	V
				f _{OSC} = 16 MHz, OSCILLATOR_MARGIN = 1	1.3	—	—	
V _{FXOSCOPI}	CC	P	Oscillation operating point	—	—	0.95	—	V
I _{FXOSC} ³	CC	T	Fast external crystal oscillator consumption	—	—	2	3	mA
T _{FXOSCSU}	CC	T	Fast external crystal oscillator start-up time	f _{OSC} = 4 MHz, OSCILLATOR_MARGIN = 0	—	—	6	ms
				f _{OSC} = 16 MHz, OSCILLATOR_MARGIN = 1	—	—	1.8	
V _{IH}	SR	P	Input high level CMOS (Schmitt Trigger)	Oscillator bypass mode	0.65V _{DD}	—	V _{DD} +0.4	V
V _{IL}	SR	P	Input low level CMOS (Schmitt Trigger)	Oscillator bypass mode	−0.4	—	0.35V _{DD}	V

¹ V_{DD} = 3.3 V ± 10% / 5.0 V ± 10%, T_A = −40 to 105 °C, unless otherwise specified² All values need to be confirmed during device characterization.³ Stated values take into account only analog module consumption but not the digital contributor (clock tree and enabled peripherals)

3.12 Slow external crystal oscillator (32 KHz) electrical characteristics

The device provides a low power oscillator/resonator driver.

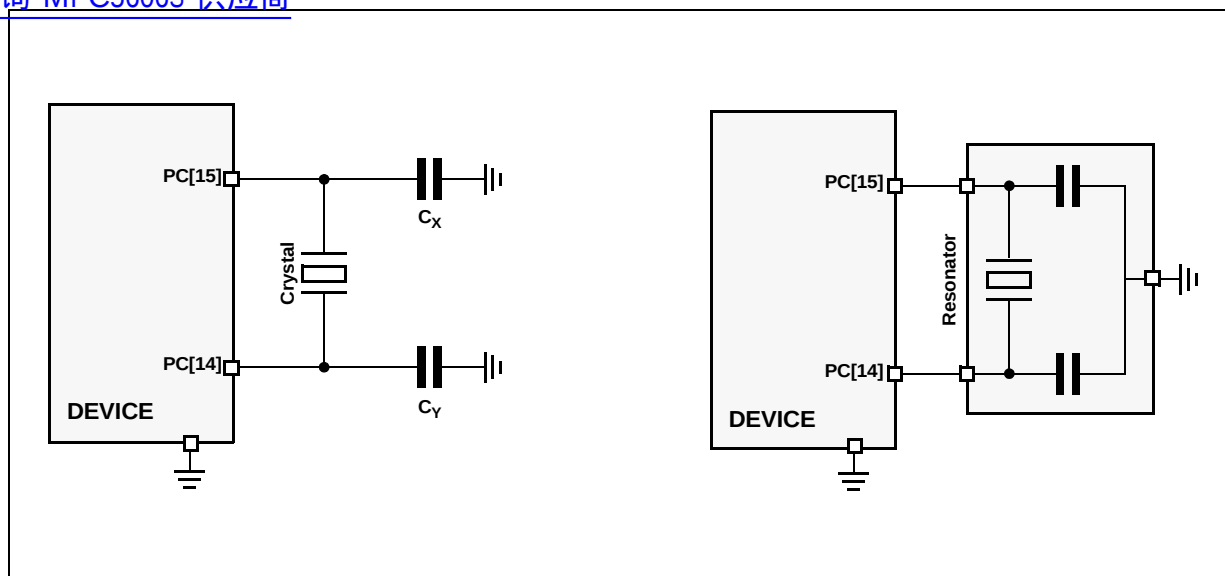


Figure 17. Crystal oscillator and resonator connection scheme

NOTE

PC[14]/PC[15] must not be directly used to drive external circuits.

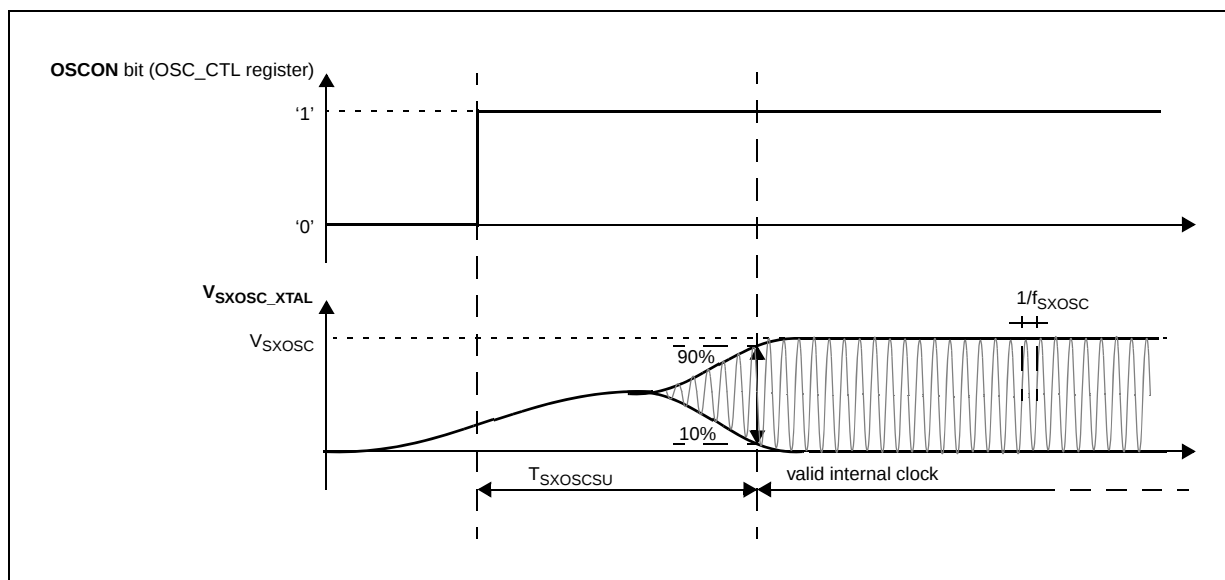


Figure 18. Slow external crystal oscillator (32 KHz) timing

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Table 43. Slow external crystal oscillator (32 KHz) electrical characteristics

Symbol		C	Parameter	Conditions ¹	Value ²			Unit
					Min	Typ	Max	
f _{SXOSC}	SR	T	Slow external crystal oscillator frequency	—	32	—	40	kHz
V _{SXOSC}	CC	T	Oscillation amplitude	V _{DD} = 3.3 V ± 10%	1.12	1.33	1.74	V
		T		V _{DD} = 5.0 V ± 10%	1.12	1.37	1.74	
I _{SXOSC}	CC	D	Slow external crystal oscillator consumption	—	—	—	5	μA
T _{SXOSCSU}	CC	T	Slow external crystal oscillator start-up time	—	—	—	2 ³	s
V _{IH}	SR	D	Input high level CMOS Schmitt Trigger	Oscillator bypass mode	0.65V _{DD}	—	V _{DD} + 0.4	V
V _{IL}	SR	D	Input low level CMOS Schmitt Trigger	Oscillator bypass mode	−0.4	—	0.35V _{DD}	V

¹ V_{DD} = 3.3 V ± 10% / 5.0 V ± 10%, T_A = −40 to 105 °C, unless otherwise specified

² All values need to be confirmed during device characterization.

³ The quoted figure is based on a board that is properly laid out and has no stray capacitances.

3.13 FMPLL electrical characteristics

The device provides a frequency-modulated phase-locked loop (FMPLL) module to generate a fast system clock from the main oscillator driver.

Table 44. FMPLL electrical characteristics

Symbol		C	Parameter	Conditions ¹	Value ²			Unit
					Min	Typ	Max	
f _{PLLIN}	SR	T	FMPLL reference clock ³	—	4	—	64	MHz
Δ _{PLLIN}	SR	T	FMPLL reference clock duty cycle ³	—	40	—	60	%
f _{PLLOUT}	CC	T	FMPLL output clock frequency	—	16	—	64	MHz
f _{CPU}	CC	T	System clock frequency	—	—	—	64 ⁴	MHz
t _{LOCK}	CC	T	FMPLL lock time	Stable oscillator (f _{PLLIN} = 16 MHz)	—	—	200	μs
Δt _{PKJIT}	CC	T	FMPLL jitter (peak to peak)	f _{PLLIN} = 16 MHz (resonator)	—	—	500	ps
Δt _{LTJIT}	CC	T	FMPLL long term jitter	f _{PLLIN} = 16 MHz (resonator)	—	—	1.5	ns
I _{PLL}	CC	D	FMPLL consumption	T _A = 25 °C	—	—	4	mA

¹ V_{DDPLL} = 1.2 V ± 10%, T_A = −40 to 105 °C, unless otherwise specified.

² All values need to be confirmed during device characterization.

³ PLLIN clock retrieved directly from FXOSC clock. Input characteristics are granted when oscillator is used in functional mode. When bypass mode is used, oscillator input clock should verify f_{PLLIN} and Δ_{PLLIN}.

⁴ f_{CPU} 64 MHz can be achieved only at temperatures up to 105 °C with a maximum FM depth of 2%.

3.14 Fast internal RC oscillator (16 MHz) electrical characteristics

The device provides a 16 MHz fast internal RC oscillator. This is used as the default clock at the power-up of the device.

Table 45. Fast internal RC oscillator (16 MHz) electrical characteristics

Symbol		C	Parameter	Conditions ¹		Value ²			Unit
						Min	Typ	Max	
f _{FIRC}	CC	P	Fast internal RC oscillator high frequency	T _A = 25 °C, trimmed	—	-2%	16	+2%	MHz
Δ _{FIRCVAR}	CC	C	Fast internal RC oscillator variation in temperature and supply with respect to f _{FIRC} at T _A = 25 °C in high-frequency configuration	T _A = -40 to 105 °C, trimmed	—	-5	—	+5	%
I _{FIRCRUN}	CC	D	Fast internal RC oscillator high frequency current in running mode	T _A = 25 °C, trimmed	—	—	—	200	μA
I _{FIRCPWD}	CC	D	Fast internal RC oscillator high frequency current in power down mode	T _A = 25 °C	—	—	—	1	μA
I _{FIRCSTOP}	CC	D	Fast internal RC oscillator high frequency and system clock current in stop mode	T _A = 25 °C	sysclk = off	—	0.3	—	mA
		sysclk = 2 MHz			—	2	—		
		sysclk = 4 MHz			—	2.5	—		
		sysclk = 8 MHz			—	3.3	—		
		sysclk = 16 MHz			—	5.2	—		
t _{FIRCSU}	CC	C	Fast internal RC oscillator start-up time	T _A = 25 °C	V _{DD} = 5.0 V ± 10%	—	—	—	μs
		V _{DD} = 3.3 V ± 10%			—	—	—		
		C		T _A = -40 to 105 °C	V _{DD} = 5.0 V ± 10%	—	—	—	
		V _{DD} = 3.3 V ± 10%			—	—	—		

¹ $V_{\text{DD}} = 3.3\text{ V} \pm 10\% / 5.0\text{ V} \pm 10\%$, $T_A = -40\text{ to }105\text{ }^{\circ}\text{C}$, unless otherwise specified.

² All values need to be confirmed during device characterization.

3.15 Slow internal RC oscillator (128 kHz) electrical characteristics

The device provides a 128 kHz slow internal RC oscillator. This can be used as the reference clock for the RTC module.

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Table 46. Slow internal RC oscillator (128 kHz) electrical characteristics

Symbol		C	Parameter	Conditions ¹	Value ²			Unit
					Min	Typ	Max	
f _{SIRC}	CC	C	Slow internal RC oscillator low frequency	T _A = 25 °C, trimmed	-2%	128	+2%	kHz
Δ _{SIRCVAR}	CC	C	Slow internal RC oscillator variation in temperature and supply with respect to f _{SIRC} at T _A = 25 °C in high frequency configuration	Trimmed	-10%	128	+10%	kHz
I _{SIRC}	CC	D	Slow internal RC oscillator low frequency current	T _A = 25 °C, trimmed	—	—	5	μA
t _{SIRCSU}	CC	C	Slow internal RC oscillator start-up time	T _A = 25 °C, V _{DD} = 5.0 V ± 10%	—	—	—	μs

¹ $V_{DD} = 3.3\text{ V} \pm 10\%$ / $5.0\text{ V} \pm 10\%$, $T_A = -40$ to $105\text{ }^{\circ}\text{C}$, unless otherwise specified.

² All values need to be confirmed during device characterization.

3.16 Flash memory electrical characteristics

Table 47. Program and erase specifications

Symbol		C	Parameter	Value			Unit
				Typ ¹	Initial max ²	Max ³	
T _{dwprogram}	CC	C	Double word (64 bits) program time ⁴	22	50	500	μs
T _{16kpperase}	CC	C	16 KB block pre-program and erase time	300	500	5000	ms
T _{32kpperase}	CC	C	32 KB block pre-program and erase time	400	600	5000	ms
T _{128kpperase}	CC	C	128 KB block pre-program and erase time	800	1300	7500	ms
T _{eslat}	CC	D	Erase suspend latency	—	30	30	μs

¹ Typical program and erase times assume nominal supply values and operation at $25\text{ }^{\circ}\text{C}$. All times are subject to change pending device characterization.

² Initial factory condition: < 100 program/erase cycles, $25\text{ }^{\circ}\text{C}$, typical supply voltage.

³ The maximum program and erase times occur after the specified number of program/erase cycles. These maximum values are characterized but not guaranteed.

⁴ Actual hardware programming times. This does not include software overhead.

Table 48. Flash module life

Symbol	C	Parameter	Conditions	Value		Unit
				Min	Typ	
P/E	CC	C	Number of program/erase cycles per block for 16 KB blocks over the operating temperature range (T_J)	100000	—	cycles
P/E	CC	C	Number of program/erase cycles per block for 32 KB blocks over the operating temperature range (T_J)	10000	100000	cycles
P/E	CC	C	Number of program/erase cycles per block for 128 KB blocks over the operating temperature range (T_J)	1000	100000	cycles
Retention	CC	C	Minimum data retention at 85 °C average ambient temperature ¹			
			Blocks with 0–1,000 P/E cycles	20	—	years
			Blocks with 10,000 P/E cycles	10	—	years
			Blocks with 100,000 P/E cycles	5	—	years

¹ Ambient temperature averaged over duration of application, not to exceed recommended product operating temperature range.

Table 49. Flash memory read access timing

Symbol	C	Parameter	Condition ¹	Max value	Unit
f_{READ}	CC	P	Maximum frequency for flash memory reading	2 wait states	MHz
				1 wait state	
				0 wait states	

¹ $V_{DD} = 3.3 \text{ V} \pm 10\% / 5.0 \text{ V} \pm 10\%$, $T_A = -40$ to $105 \text{ }^\circ\text{C}$, unless otherwise specified

3.17 ADC electrical characteristics

The device provides a 10-bit Successive Approximation Register (SAR) Analog to Digital Converter.

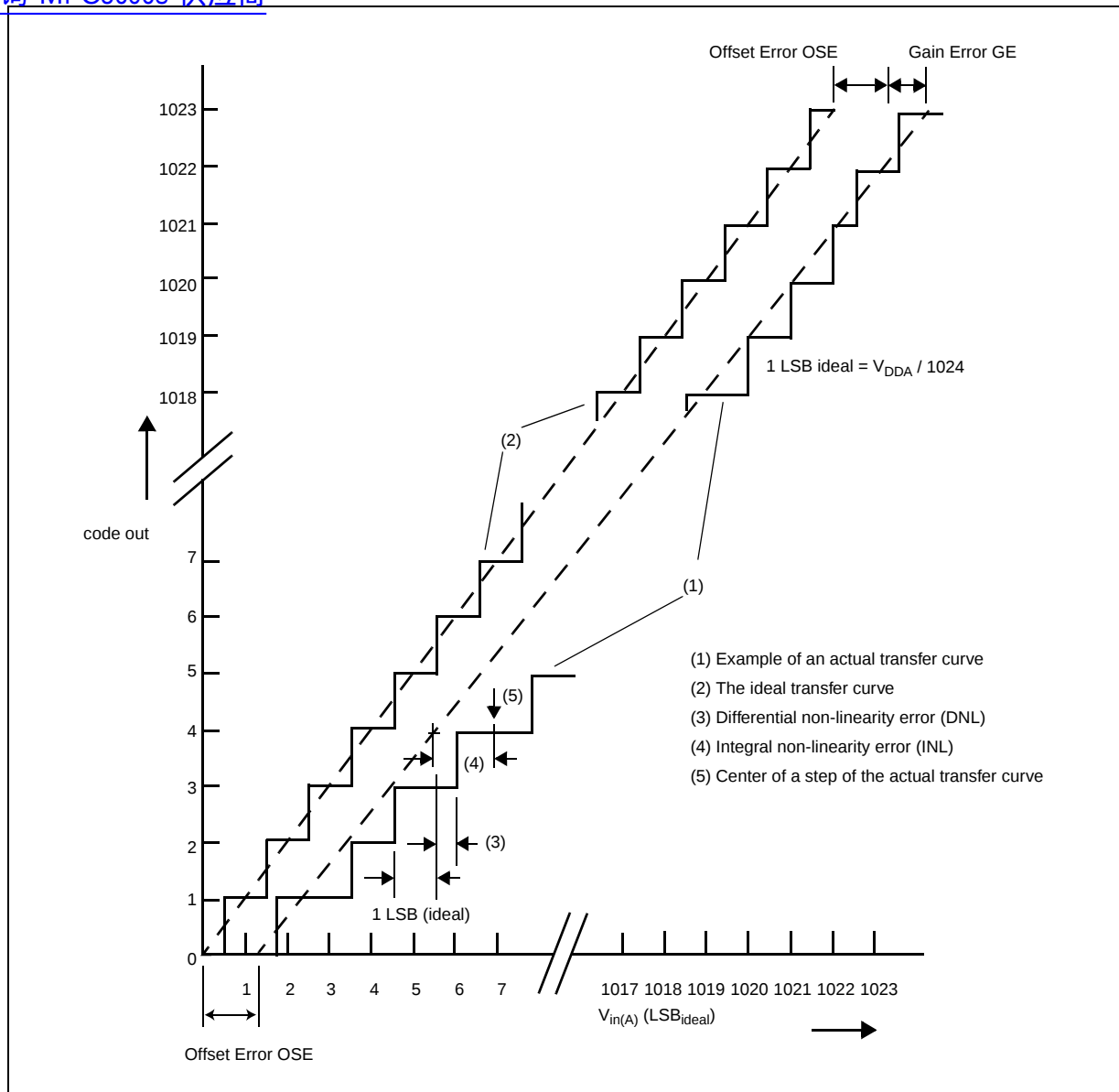
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Figure 19. ADC Characteristics and Error Definitions

3.17.1 Input impedance and ADC accuracy

In the following analysis, the input circuit corresponding to the precise channels is considered.

To preserve the accuracy of the A/D converter, it is necessary that analog input pins have low AC impedance. Placing a capacitor with good high frequency characteristics at the input pin of the device can be effective: the capacitor should be as large as possible, ideally infinite. This capacitor contributes to attenuating the noise present on the input pin; furthermore, it sources charge during the sampling phase, when the analog signal source is a high-impedance source.

A real filter can typically be obtained by using a series resistance with a capacitor on the input pin (simple RC filter). The RC filtering may be limited according to the value of source impedance of the transducer or circuit supplying the analog signal to be measured. The filter at the input pins must be designed taking into account the dynamic characteristics of the input signal (bandwidth) and the equivalent input impedance of the ADC itself.

Electrical characteristics

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In fact a current sink contributor is represented by the charge sharing effects with the sampling capacitance: C_S being substantially a switched capacitance, with a frequency equal to the conversion rate of the ADC, it can be seen as a resistive path to ground. For instance, assuming a conversion rate of 1 MHz, with C_S equal to 3 pF, a resistance of 330 kΩ is obtained ($R_{EQ} = 1 / (f_c \times C_S)$, where f_c represents the conversion rate at the considered channel). To minimize the error induced by the voltage partitioning between this resistance (sampled voltage on C_S) and the sum of $R_S + R_F + R_L + R_{SW} + R_{AD}$, the external circuit must be designed to respect the Equation 7:

Eqn. 7

$$V_A \cdot \frac{R_S + R_F + R_L + R_{SW} + R_{AD}}{R_{EQ}} < \frac{1}{2} \text{ LSB}$$

Equation 7 generates a constraint for external network design, in particular on resistive path. Internal switch resistances (R_{SW} and R_{AD}) can be neglected with respect to external resistances.

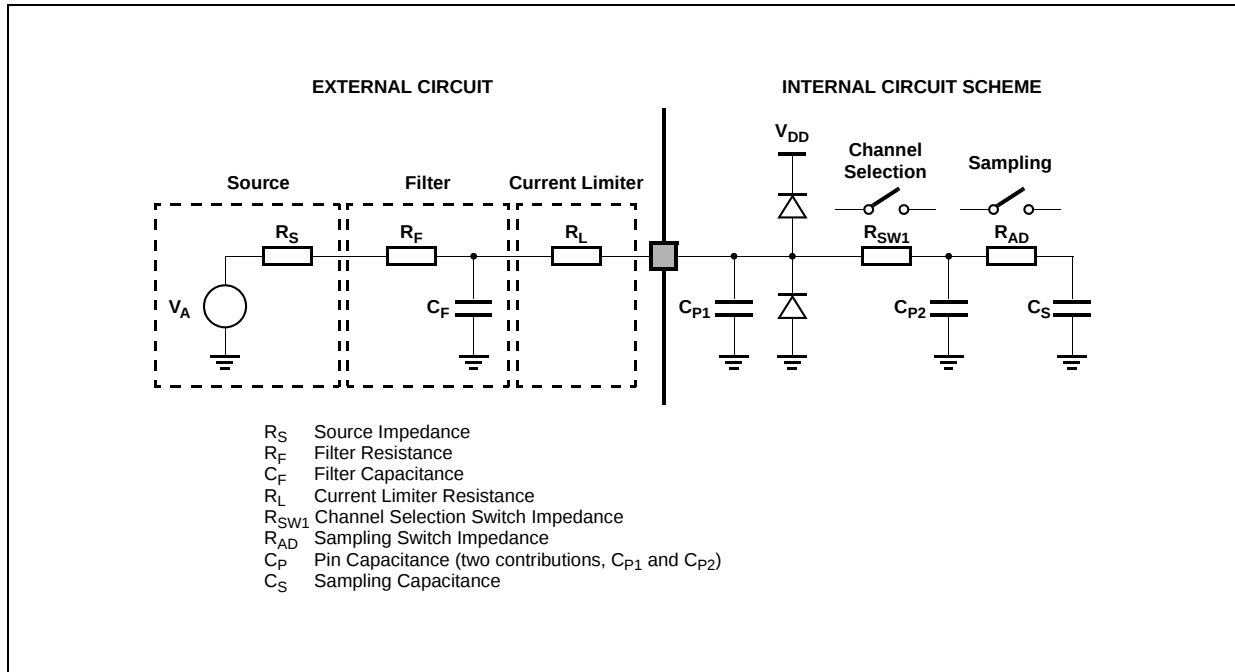


Figure 20. Input equivalent circuit (precise channels)

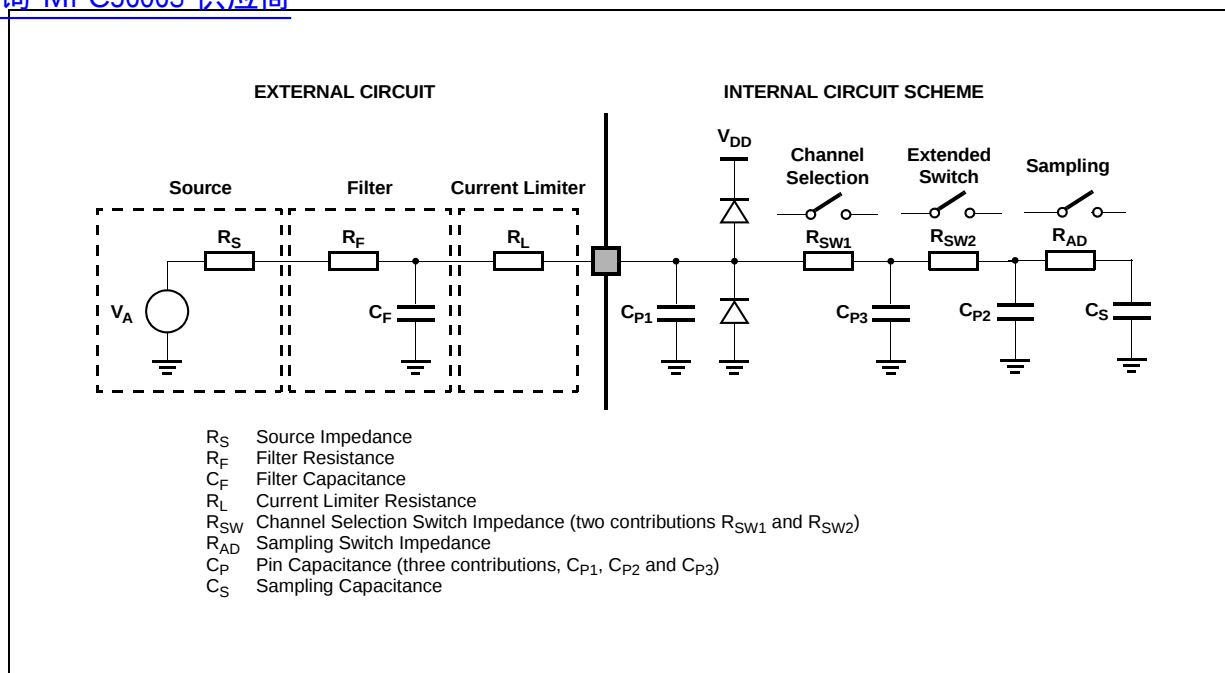
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Figure 21. Input equivalent circuit (extended channels)

A second aspect involving the capacitance network shall be considered. Assuming the three capacitances C_F , C_{P1} and C_{P2} are initially charged at the source voltage V_A (refer to the equivalent circuit reported in Figure 20): A charge sharing phenomenon is installed when the sampling phase is started (A/D switch close).

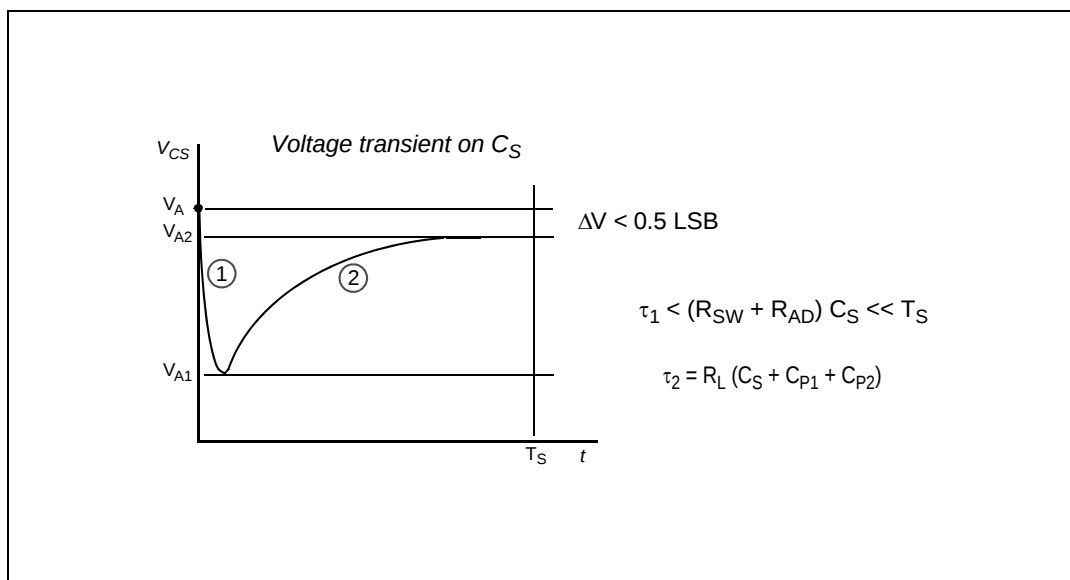


Figure 22. Transient behavior during sampling phase

In particular two different transient periods can be distinguished:

- A first and quick charge transfer from the internal capacitance C_{P1} and C_{P2} to the sampling capacitance C_S occurs (C_S is supposed initially completely discharged): considering a worst case (since the time constant in reality would be faster) in which C_{P2} is reported in parallel to C_{P1} (call $C_P = C_{P1} + C_{P2}$), the two capacitances C_P and C_S are in series, and the time constant is

Eqn. 8

$$\tau_1 = (R_{SW} + R_{AD}) \cdot \frac{C_P \cdot C_S}{C_P + C_S}$$

Equation 8 can again be simplified considering only C_S as an additional worst condition. In reality, the transient is faster, but the A/D converter circuitry has been designed to be robust also in the very worst case: the sampling time T_S is always much longer than the internal time constant:

Eqn. 9

$$\tau_1 < (R_{SW} + R_{AD}) \cdot C_S \ll T_S$$

The charge of C_{P1} and C_{P2} is redistributed also on C_S , determining a new value of the voltage V_{A1} on the capacitance according to Equation 10:

Eqn. 10

$$V_{A1} \cdot (C_S + C_{P1} + C_{P2}) = V_A \cdot (C_{P1} + C_{P2})$$

- A second charge transfer involves also C_F (that is typically bigger than the on-chip capacitance) through the resistance R_L : again considering the worst case in which C_{P2} and C_S were in parallel to C_{P1} (since the time constant in reality would be faster), the time constant is:

Eqn. 11

$$\tau_2 < R_L \cdot (C_S + C_{P1} + C_{P2})$$

In this case, the time constant depends on the external circuit: in particular imposing that the transient is completed well before the end of sampling time T_S , a constraints on R_L sizing is obtained:

Eqn. 12

$$10 \cdot \tau_2 = 10 \cdot R_L \cdot (C_S + C_{P1} + C_{P2}) < T_S$$

Of course, R_L shall be sized also according to the current limitation constraints, in combination with R_S (source impedance) and R_F (filter resistance). Being C_F definitively bigger than C_{P1} , C_{P2} and C_S , then the final voltage V_{A2} (at the end of the charge transfer transient) will be much higher than V_{A1} . Equation 13 must be respected (charge balance assuming now C_S already charged at V_{A1}):

Eqn. 13

$$V_{A2} \cdot (C_S + C_{P1} + C_{P2} + C_F) = V_A \cdot C_F + V_{A1} \cdot (C_{P1} + C_{P2} + C_S)$$

The two transients above are not influenced by the voltage source that, due to the presence of the $R_F C_F$ filter, is not able to provide the extra charge to compensate the voltage drop on C_S with respect to the ideal source V_A ; the time constant $R_F C_F$ of the filter is very high with respect to the sampling time (T_S). The filter is typically designed to act as anti-aliasing.

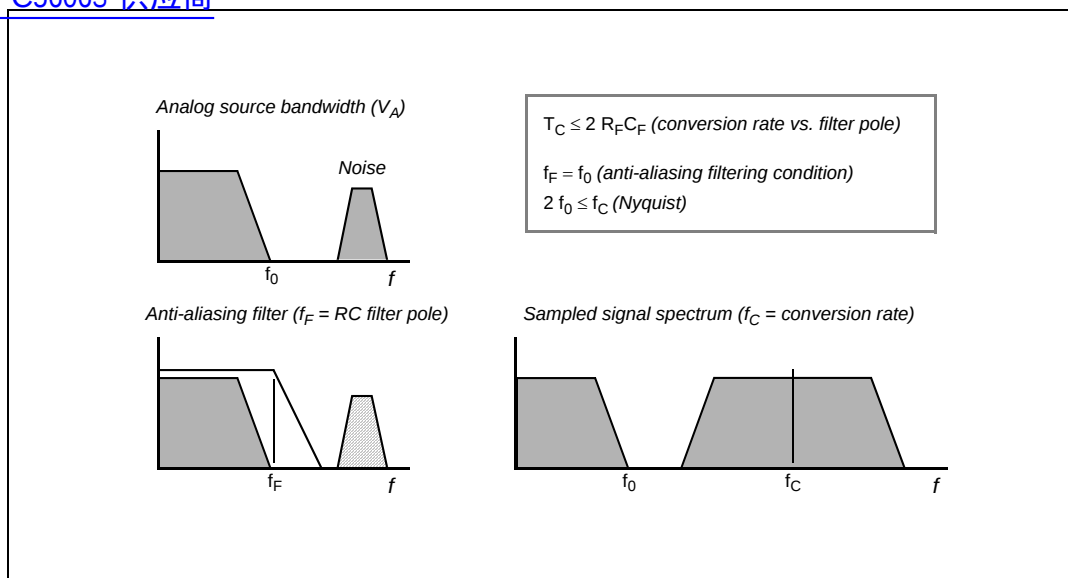
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Figure 23. Spectral representation of input signal

Calling f_0 the bandwidth of the source signal (and as a consequence the cut-off frequency of the anti-aliasing filter, f_F), according to the Nyquist theorem the conversion rate f_C must be at least $2f_0$; it means that the constant time of the filter is greater than or at least equal to twice the conversion period (T_C). Again the conversion period T_C is longer than the sampling time T_S , which is just a portion of it, even when fixed channel continuous conversion mode is selected (fastest conversion rate at a specific channel): in conclusion it is evident that the time constant of the filter $R_F C_F$ is definitively much higher than the sampling time T_S , so the charge level on C_S cannot be modified by the analog signal source during the time in which the sampling switch is closed.

The considerations above lead to impose new constraints on the external circuit, to reduce the accuracy error due to the voltage drop on C_S ; from the two charge balance equations above, it is simple to derive Equation 14 between the ideal and real sampled voltage on C_S :

Eqn. 14

$$\frac{V_A}{V_{A2}} = \frac{C_{P1} + C_{P2} + C_F}{C_{P1} + C_{P2} + C_F + C_S}$$

From this formula, in the worst case (when V_A is maximum, that is for instance 5V), assuming to accept a maximum error of half a count, a constraint is evident on C_F value:

Eqn. 15

$$C_F > 2048 \cdot C_S$$

3.17.2 ADC conversion characteristics

NOTE

For input leakage current specification, see [Table 30](#).

Table 50. ADC conversion characteristics

Symbol	C	Parameter	Conditions ¹	Value ²			Unit
				Min	Typ	Max	
V _{SSA}	SR	D	Voltage on VSSA (ADC reference) pin with respect to ground (V _{SS}) ³	—	—	0.1	V
V _{DDA}	SR	D	Voltage on VDDA pin (ADC reference) with respect to ground (V _{SS})	—	—	V _{DD} + 0.1	V
V _{AINx}	SR	D	Analog input voltage ⁴	—	—	V _{SSA} – 0.1	V
f _{ADC}	SR	D	ADC analog frequency	—	—	32	MHz
t _{ADC_PU}	SR	D	ADC power up delay	—	—	1.5	μs
t _{ADC_S}	CC	T	Sample time ^{5,6}	f _{ADC} = 32 MHz, ADC_conf_sample_input = 17	—	—	μs
				f _{ADC} = 6 MHz, ADC_conf_sample_input = 127	—	21	
t _{ADC_C}	CC	T	Conversion time ⁷	f _{ADC} = 32 MHz, ADC_conf_comp = 2	—	—	μs
C _S	CC	D	ADC input sampling capacitance	—	—	3	pF
C _{P1}	CC	D	ADC input pin capacitance 1	—	—	3	pF
C _{P2}	CC	D	ADC input pin capacitance 2	—	—	1	pF
C _{P3}	CC	D	ADC input pin capacitance 3	—	—	1	pF
R _{SW1}	CC	D	Internal resistance of analog source	—	—	1	kΩ
R _{SW2}	CC	D	Internal resistance of analog source	—	—	1	kΩ
R _{AD}	CC	D	Internal resistance of analog source	—	—	0.1	kΩ
I _{INJ}	SR	T	Input current Injection	Current injection on one ADC input, different from the converted one	—	5	mA
INL	CC	P	Integral Non Linearity	No overload	—	2.5	LSB
DNL	CC	P	Differential Non Linearity	No overload	—	1.0	LSB
OFS	CC	T	Offset error	After offset cancellation	—	0.5	LSB
GNE	CC	T	Gain error		—	0.6	LSB
TUE _x	CC	T	Total unadjusted error for extended channel	Without current injection	—	3	LSB
				With current injection	—	4	

¹ V_{DDA} = 3.3 V ± 10% / 5.0 V ± 10%, T_A = –40 to 105 °C, unless otherwise specified.

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- ² All values need to be confirmed during device characterization.
- ³ Analog and digital V_{SS} **must** be common (to be tied together externally).
- ⁴ V_{AINx} may exceed V_{SSA} and V_{DDA} limits, remaining on absolute maximum ratings, but the results of the conversion will be clamped respectively to 0x000 or 0x3FF
- ⁵ During the sample time the input capacitance C_S can be charged/discharged by the external source. The internal resistance of the analog source must allow the capacitance to reach its final voltage level within t_{ADC_S} . After the end of the sample time t_{ADC_S} , changes of the analog input voltage have no effect on the conversion result. Values for the sample clock t_{ADC_S} depend on programming.
- ⁶ The maximum sample rate is 1million samples per second, provided the source impedance and current limiter(>1 k Ω) are calculated adequately.
- Filter capacitor at analog source output must meet the criteria C_f (filter capacitor) > 2048* C_s (sampling capacitor which is 3 pF)
- ⁷ This parameter does not include the sample time t_{ADC_S} , but only the time for determining the digital result and the time to load the result's register with the conversion result.

3.18 LCD driver electrical characteristics

Table 51. LCD driver specifications

Symbol	C	Parameter	Value ¹			Unit
			Min	Typ	Max	
VLCD	SR	C Voltage on VLCD (LCD supply) pin with respect to VSS	0	—	VDDE + 0.3	V
$Z_{BP/FP}$	CC	T LCD output impedance (BP[n-1:0],FP[m-1:0]) for output levels VLCD, VSS ²	—	—	5.0	k Ω
$I_{BP/FP}$	CC	T LCD output current (BP[n-1:0],FP[m-1:0]) for outputs charge/discharge voltage levels VLCD2/3, VLCD1/2, VLCD1/3) ^{2,3}	—	25	—	μ A

¹ $V_{DD} = 5.0 \text{ V} \pm 10\%$, $T_A = -40\text{--}105^\circ\text{C}$, unless otherwise specified

² Outputs measured one at a time, low impedance voltage source connected to the VLCD pin.

³ With PWR=10, BSTEN=0, and BSTAO=0

3.19 Pad AC specifications

Table 52. Pad AC specifications (5.0 V, PAD3V5V = 0)¹

No.	Pad	Tswitchon ^{1,2} (ns)			Rise/Fall ^{2,3} (ns)			Frequency ² (MHz)			Current slew ² (mA/ns)			Load drive (pF)
		Min	Typ	Max	Min	Typ	Max	Min	Typ	Max	Min	Typ	Max	
1	Slow	1.5	—	30	6	—	50	—	—	4	0.04	—	2	25
		1.5	—	30	9	—	100	—	—	2	0.04	—	2	50
		1.5	—	30	12	—	125	—	—	2	0.04	—	2	100
		1.5	—	30	16	—	150	—	—	2	0.04	—	2	200

Table 52. Pad AC specifications (5.0 V, PAD3V5V = 0)¹ (continued)

No.	Pad	Tswitchon ^{1,2} (ns)			Rise/Fall ^{2,3} (ns)			Frequency ² (MHz)			Current slew ² (mA/ns)			Load drive (pF)
		Min	Typ	Max	Min	Typ	Max	Min	Typ	Max	Min	Typ	Max	
2	Medium	1	—	15	3	—	10	—	—	40	2.5	—	7	25
		1	—	15	5	—	20	—	—	20	2.5	—	7	50
		1	—	15	9	—	40	—	—	13	2.5	—	8	100
		1	—	15	12	—	70	—	—	7	2.5	—	8	200
3	Fast	1	—	6	1	—	4	—	—	100	18	—	55	25
		1	—	6	1.5	—	6	—	—	80	18	—	55	50
		1	—	6	3	—	12	—	—	40	18	—	55	100
		1	—	6	5	—	16	—	—	25	18	—	55	200
4	Symmetric	1	—	5	1	—	4	—	—	50	10	—	25	25
5	Pull Up/Down (5.5 V max)	—	—	—	—	—	5000	—	—	—	—	—	—	50

¹ Propagation delay from V_{DD}/2 of internal signal to Pchannel/Nchannel on condition² Data based on characterization results, not tested in production³ Slope at rising/falling edgeTable 53. Pad AC specifications (3.3 V, PAD3V5V = 1)¹

No.	Pad	Tswitchon ^{1,3} (ns)			Rise/Fall ^{2,3} (ns)			Frequency ³ (MHz)			Current slew ³ (mA/ns)			Load drive (pF)
		Min	Typ	Max	Min	Typ	Max	Min	Typ	Max	Min	Typ	Max	
1	Slow	3	—	40	4	—	40	—	—	4	0.01	—	2	25
		3	—	40	6	—	50	—	—	2	0.01	—	2	50
		3	—	40	10	—	75	—	—	2	0.01	—	2	100
		3	—	40	14	—	100	—	—	2	0.01	—	2	200
2	Medium	1	—	15	2	—	12	—	—	40	2.5	—	7	25
		1	—	15	4	—	25	—	—	20	2.5	—	7	50
		1	—	15	8	—	40	—	—	13	2.5	—	7	100
		1	—	15	14	—	70	—	—	7	2.5	—	7	200
3	Fast	1	—	6	1	—	4	—	—	72	3	—	40	25
		1	—	6	1.5	—	7	—	—	55	3	—	40	50
		1	—	6	3	—	12	—	—	40	3	—	40	100
		1	—	6	5	—	18	—	—	25	3	—	40	200
4	Symmetric	1	—	6	2	—	6	—	—	50	3	—	25	25
5	Pull Up/Down (3.6 V max)	—	—	—	—	—	7500	—	—	—	—	—	—	50

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- ¹ Propagation delay from $V_{DD}/2$ of internal signal to Pchannel/Nchannel on condition
- ² Slope at rising/falling edge
- ³ Data based on characterization results, not tested in production

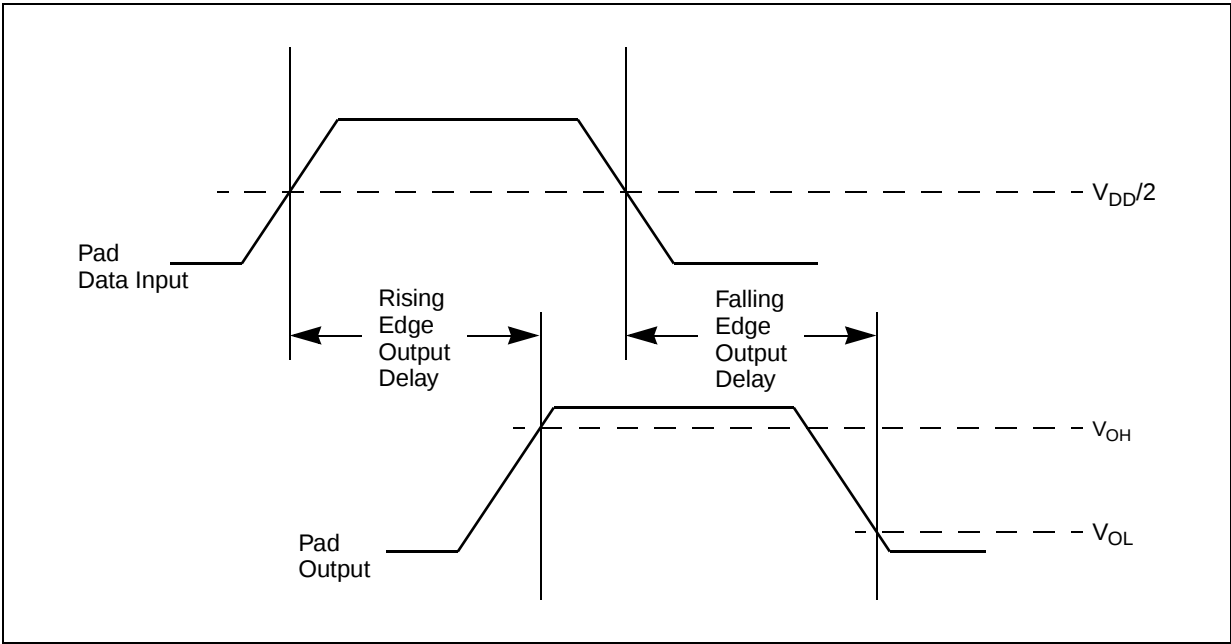


Figure 24. Pad output delay

Table 54. SMC pad delays

Symbol		C	Parameter	Conditions	Value			Unit
					Min	Typ	Max	
—	CC	D	SMC pad delay	CL=50pf V _{DD} =5V±10% SRE=1	—	—	165	ns
				CL=50pf V _{DD} =5V±10% SRE=0	—	—	35	
—	CC	D	SMC pad delay	CL=50pf V _{DD} =3.3V±10% SRE=1	—	—	350	
				CL=50pf V _{DD} =3.3V±10% SRE=0	—	—	50	

3.20 AC timing

3.20.1 IEEE 1149.1 interface timing

Table 55. JTAG interface timing¹

No.	Symbol		C	Parameter	Value		Unit
					Min	Max	
1	t_{JCYC}	CC	D	TCK Cycle Time	100	—	ns
2	t_{JDC}	CC	D	TCK Clock Pulse Width (measured at $V_{DD}/2$)	40	60	
3	$t_{TCKRISE}$	CC	D	TCK Rise and Fall Times (40%–70%)	—	3	
4	t_{TMSS}, t_{TDis}	CC	D	TMS, TDI Data Setup Time	5	—	
5	t_{TMSH}, t_{TDIH}	CC	D	TMS, TDI Data Hold Time	10	—	
6	t_{TDOV}	CC	D	TCK Low to TDO Data Valid	—	40	
7	t_{TDOI}	CC	D	TCK Low to TDO Data Invalid	0	—	
8	t_{TDOHZ}	CC	D	TCK Low to TDO High Impedance	—	30	

¹ These specifications apply to JTAG boundary scan only. JTAG timing specified at $V_{DD} = 3.0\text{ V}$ to 5.5 V , $T_A = -40$ to $105\text{ }^{\circ}\text{C}$, and $C_L = 50\text{ pF}$ with SRC = 0b11.

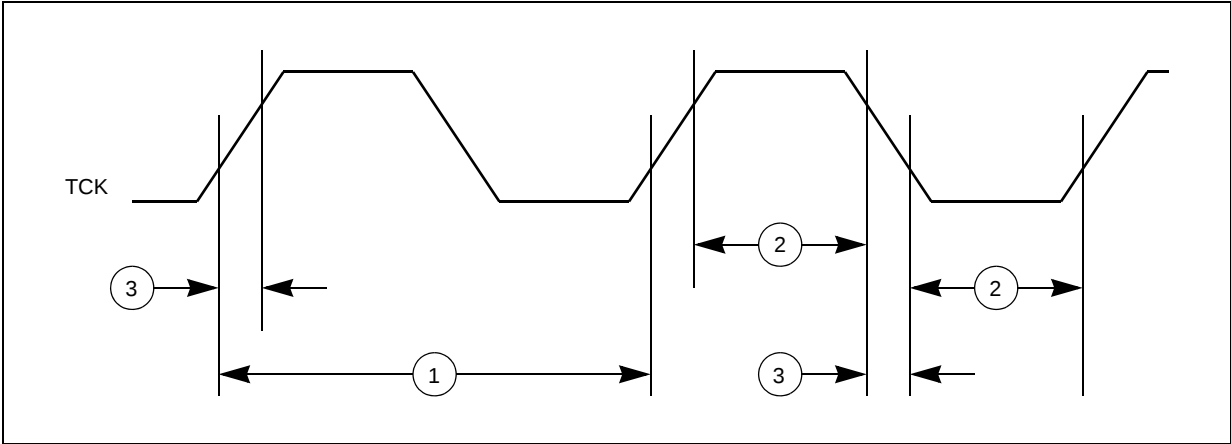


Figure 25. JTAG test clock input timing

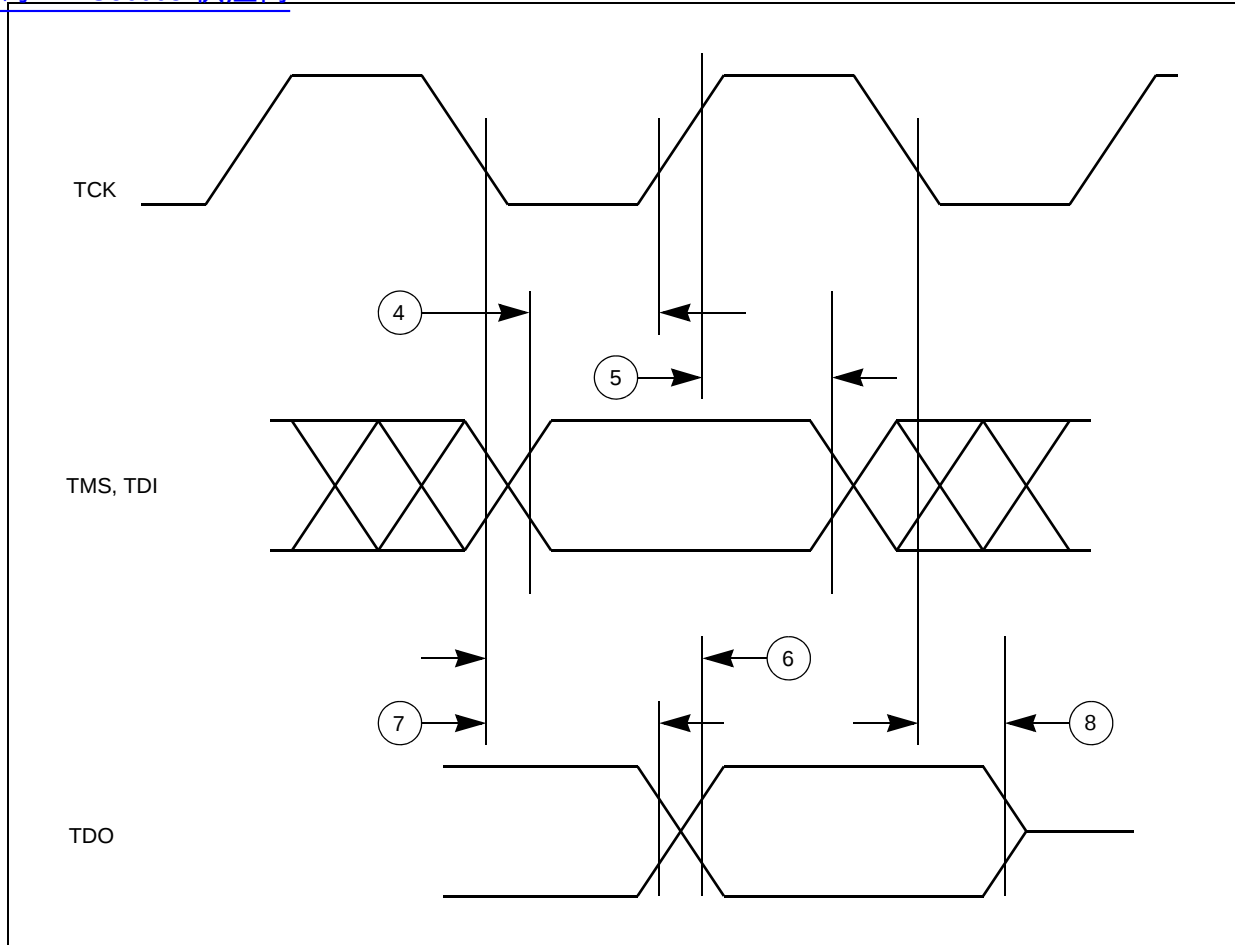
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Figure 26. JTAG test access port timing

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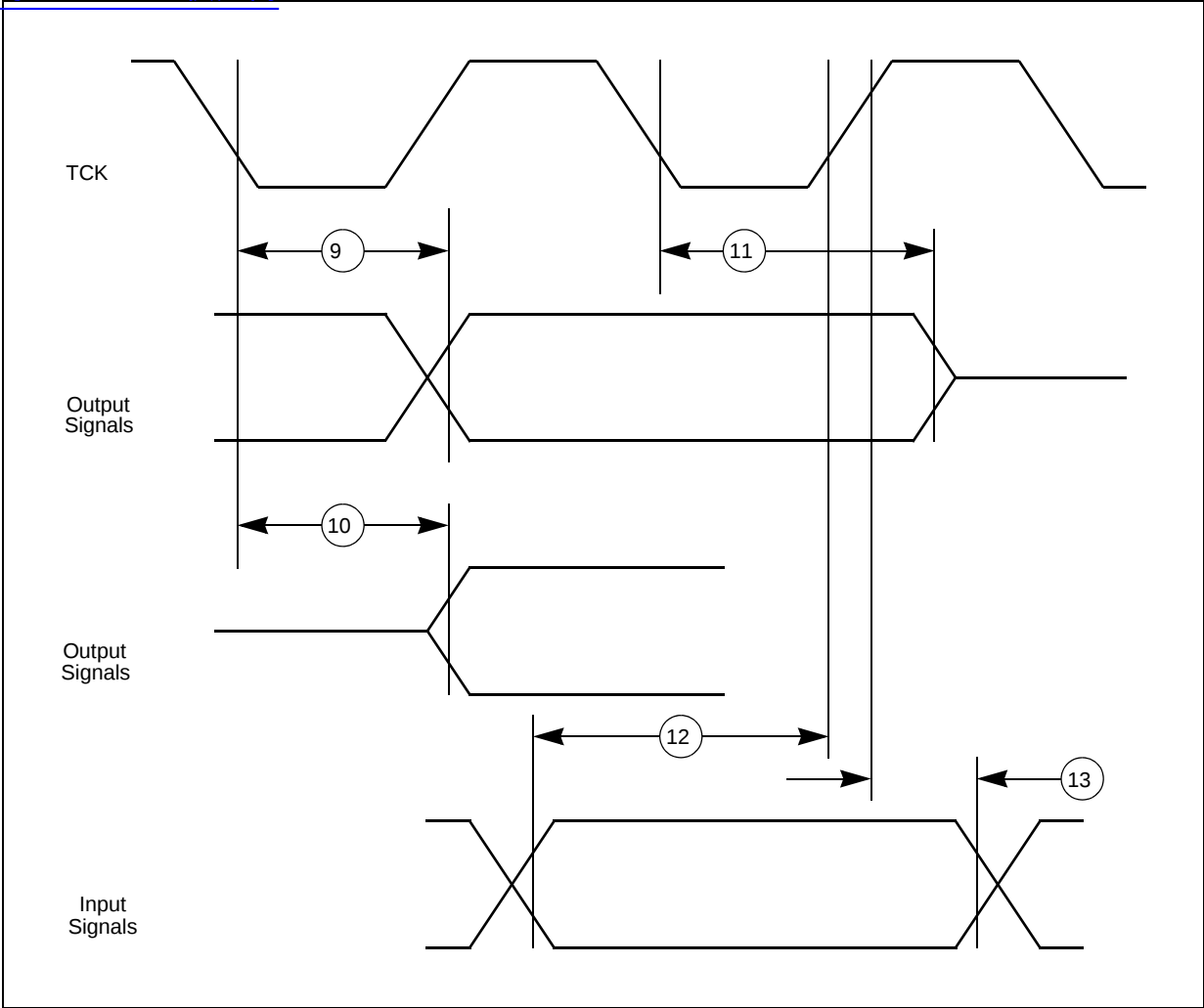


Figure 27. JTAG boundary scan timing

3.20.2 Nexus Debug Interface

Table 56. Nexus debug port timing¹

No.	Symbol	C	Parameter	Value		Unit
				Min	Max	
1	t _{MCYC}	CC	D MCKO Cycle Time	22	—	ns
2	Δ _{MDC}	CC	D MCKO Duty Cycle	40	60	%
3	t _{MDOV}	CC	D MCKO Low to MDO Data Valid ²	−2	14	ns
4	t _{MSEOV}	CC	D MCKO Low to $\overline{\text{MSEO}}$ Data Valid ²	−2	14	ns
5	t _{EVT OV}	CC	D MCKO Low to $\overline{\text{EVT O}}$ Data Valid ²	−2	14	ns
6	t _{EVTIPW}	CC	D $\overline{\text{EVT I}}$ Pulse Width	4	—	t _{TCYC}
7	t _{EVTOPW}	CC	D $\overline{\text{EVT O}}$ Pulse Width	1	—	t _{MCYC}

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No.	Symbol		C	Parameter	Value		Unit
					Min	Max	
8	t_{TCYC}	CC	D	TCK Cycle Time ³	100	—	ns
9	Δ_{TDC}	CC	D	TCK Duty Cycle	40	60	%
10	t_{NTDIS}, t_{NTMSS}	CC	D	TDI, TMS Data Setup Time	10	—	ns
11	t_{NTDIH}, t_{NTMSH}	CC	D	TDI, TMS Data Hold Time	5	—	ns
12	t_{JOV}	CC	D	TCK Low to TDO Data Valid	0	40	ns

¹ JTAG specifications in this table apply when used for debug functionality. All Nexus timing relative to MCKO is measured from 50% of MCKO and 50% of the respective signal. Nexus timing specified at $V_{DD} = 3.0\text{ V}$ to 5.5 V , $T_A = -40$ to $105\text{ }^{\circ}\text{C}$, and $C_L = 50\text{ pF}$ ($C_L = 30\text{ pF}$ on MCKO), with SRC = 0b11.

² MDO, $\overline{\text{MSEO}}$, and $\overline{\text{EVT0}}$ data is held valid until next MCKO low cycle.

³ The system clock frequency needs to be three times faster than the TCK frequency.

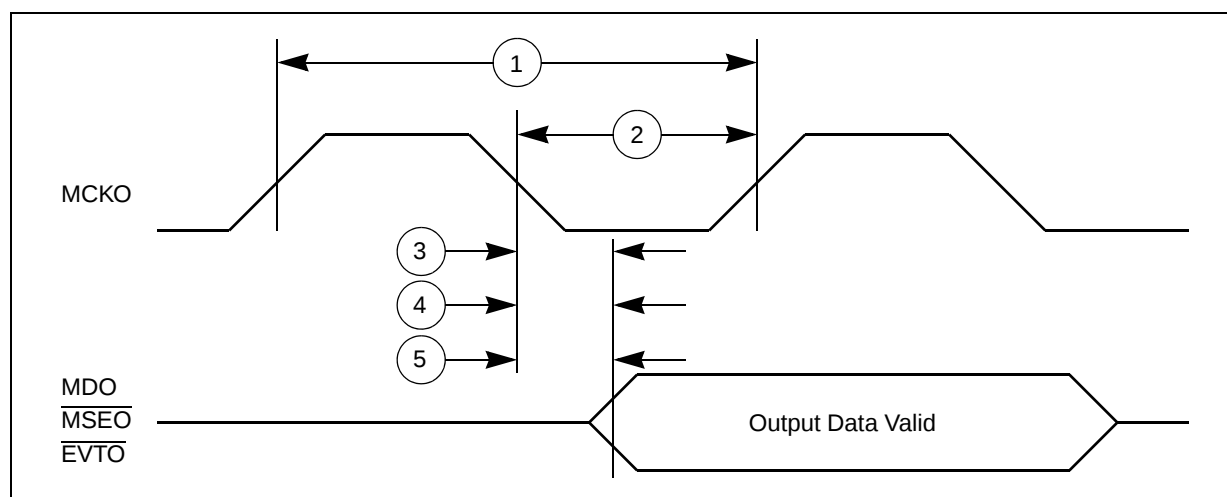


Figure 28. Nexus output timing

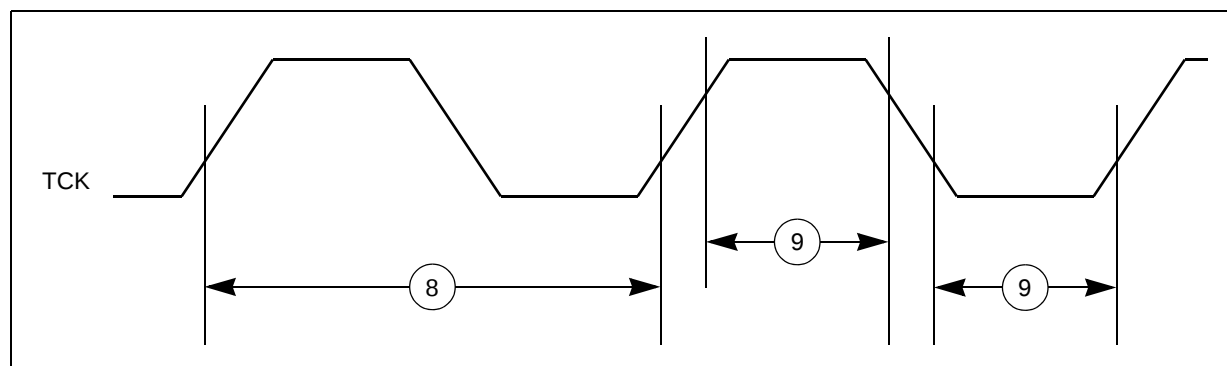


Figure 29. Nexus TCK timing

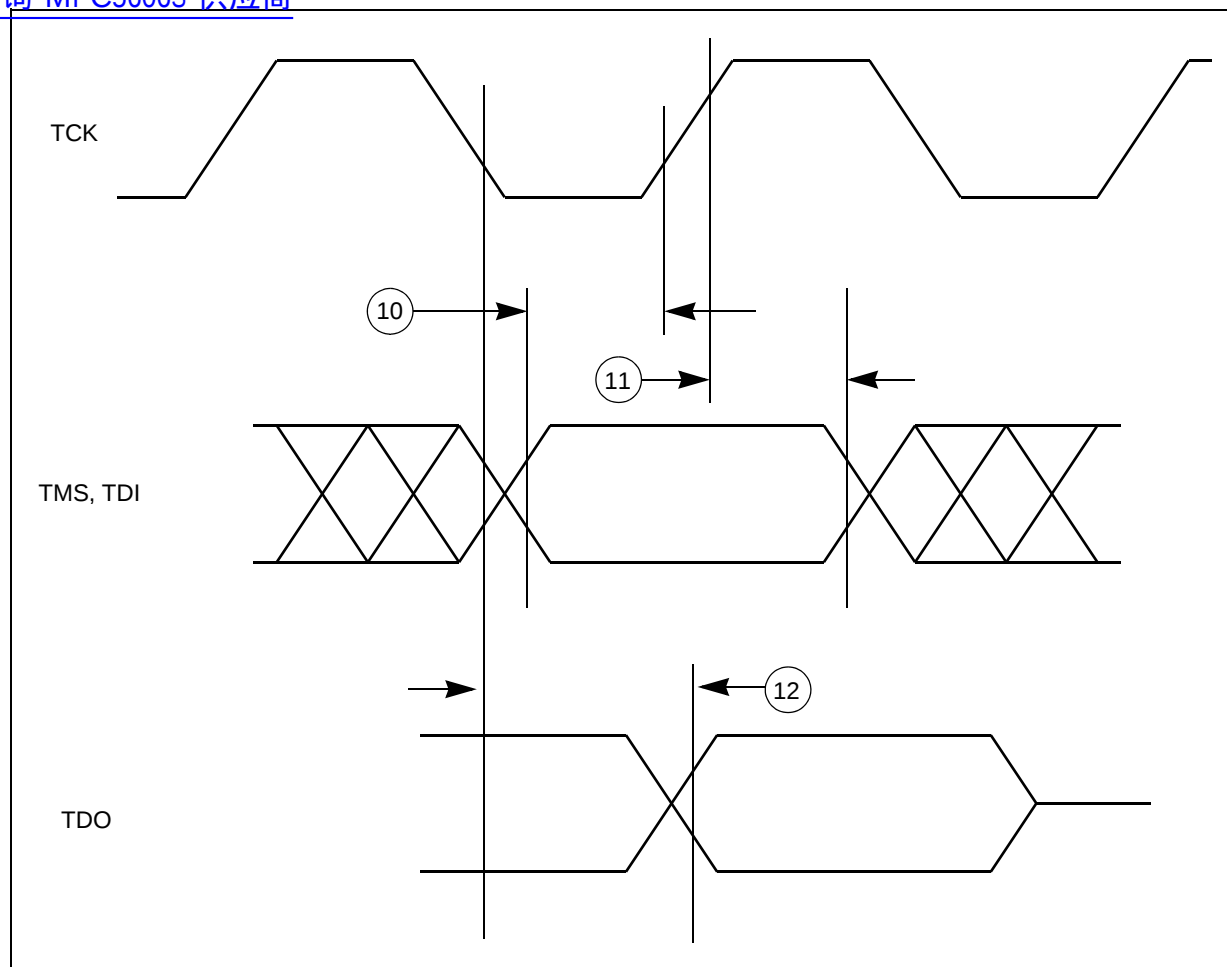
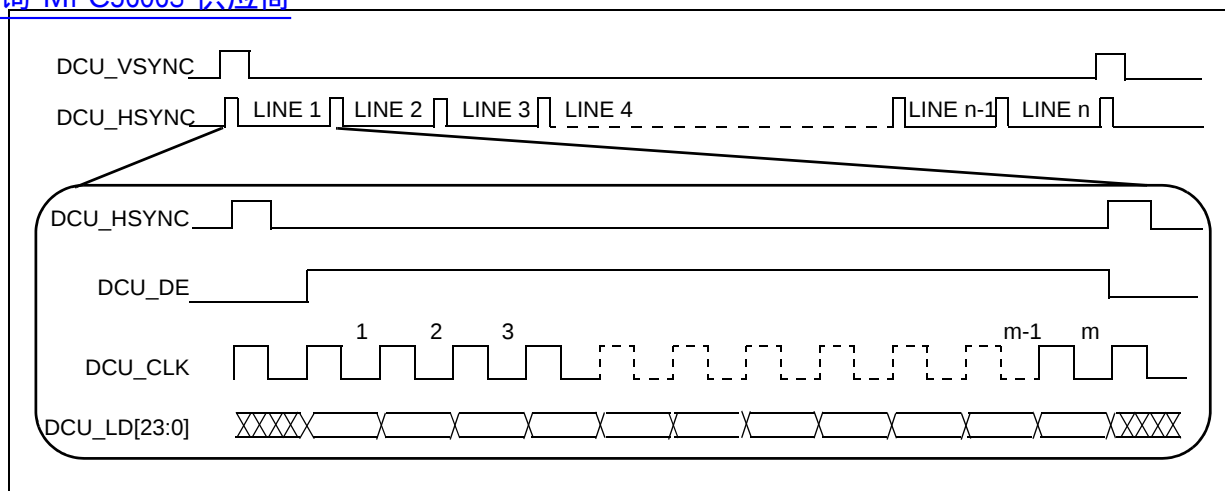


Figure 30. Nexus TDI, TMS, TDO timing

3.20.3 Interface to TFT LCD panels

Figure 31 depicts the LCD interface timing for a generic active matrix color TFT panel. In this figure signals are shown with positive polarity. The sequence of events for active matrix interface timing is:

1. DCU_CLK latches data into the panel on its positive edge (when positive polarity is selected). In active mode, DCU_CLK runs continuously.
2. DCU_HSYNC causes the panel to start a new line. It always encompasses at least one PCLK pulse.
3. DCU_VSYNC causes the panel to start a new frame. It always encompasses at least one HSYNC pulse.
4. DCU_DE acts like an output enable signal to the LCD panel. This output enables the data to be shifted onto the display. When disabled, the data is invalid and the trace is off.

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Figure 31. TFT LCD interface timing overview¹

3.20.3.1 Interface to TFT LCD panels — pixel-level timings

Figure 32 depicts the horizontal timing (timing of one line), including both the horizontal sync pulse and data. All parameters shown in the diagram are programmable. This timing diagram corresponds to positive polarity of the DCU_CLK signal (meaning the data and sync signals change on the rising edge) and active-high polarity of the DCU_HSYNC, DCU_VSYNC and DCU_DE signals. The user can select the polarity of the DCU_HSYNC and DCU_VSYNC signals via the SYN_POL register, whether active-high or active-low. The default is active-high. The DCU_DE signal is always active-high.

Pixel clock inversion and a flexible programmable pixel clock delay are also supported. They are programmed via the DCU Clock Confide Register (DCCR) in the system clock module.

The DELTA_X and DELTA_Y parameters are programmed via the DISP_SIZE register. The PW_H, BP_H and FP_H parameters are programmed via the HSYN PARA register. The PW_V, BP_V and FP_V parameters are programmed via the VSYN_PARA register.

Table 57. LCD Interface timing parameters—horizontal and vertical

Symbol	C	Parameter	Value	Unit
t_{PCP}	CC	D Display pixel clock period	—	ns
t_{PWH}	CC	D HSYNC pulse width	$PW_H \times t_{PCP}$	ns
t_{BPH}	CC	D HSYNC back porch width	$BP_H \times t_{PCP}$	ns
t_{FPH}	CC	D HSYNC front porch width	$FP_H \times t_{PCP}$	ns
t_{SW}	CC	D Screen width	$DELTA_X \times t_{PCP}$	ns
t_{HSP}	CC	D HSYNC (line) period	$(PW_H + BP_H + FP_H + DELTA_X) \times t_{PCP}$	ns
t_{PWV}	CC	D VSYNC pulse width	$PWV \times t_{HSP}$	ns

1. In Figure 31, the "DCU_LD[23:0]" signal is an aggregation of the DCU's RGB signals—DCU_R[0:7], DCU_G[0:7] and DCU_B[0:7].

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Table 57. LCD Interface timing parameters—horizontal and vertical (continued)

Symbol	C		Parameter	Value	Unit
t_{BPV}	CC	D	VSYNC back porch width	$BP_V \times t_{HSP}$	ns
t_{FPV}	CC	D	VSYNC front porch width	$FP_V \times t_{HSP}$	ns
t_{SH}	CC	D	Screen height	$DELTA_Y \times t_{HSP}$	ns
t_{VSP}	CC	D	VSYNC (frame) period	$(PW_V + BP_V + FP_V + DELTA_Y) \times t_{HSP}$	ns

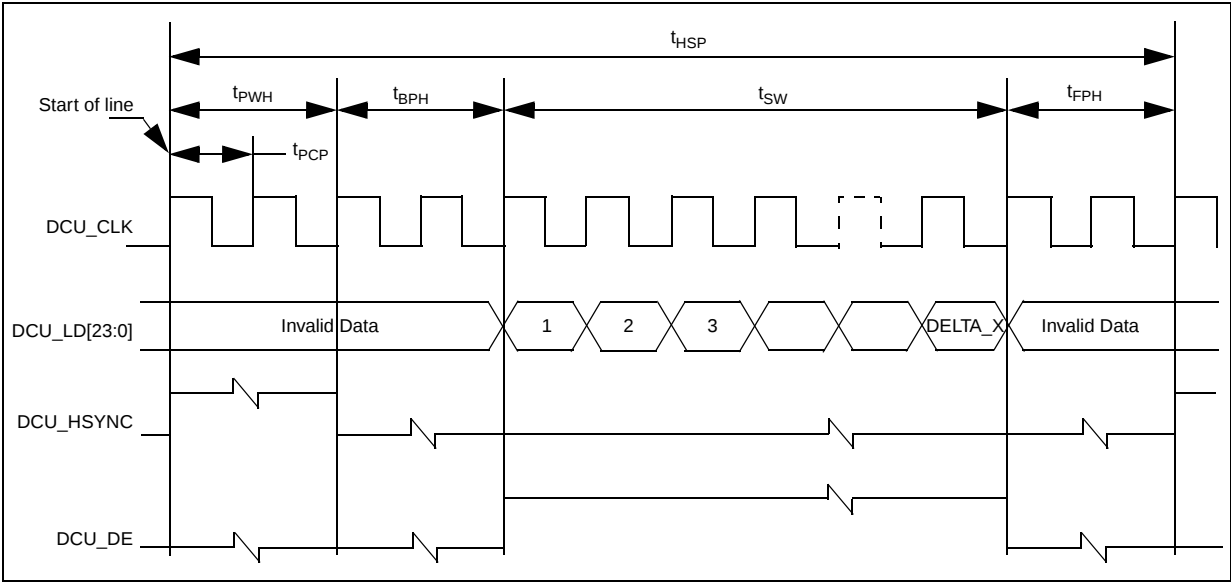


Figure 32. Horizontal sync timing

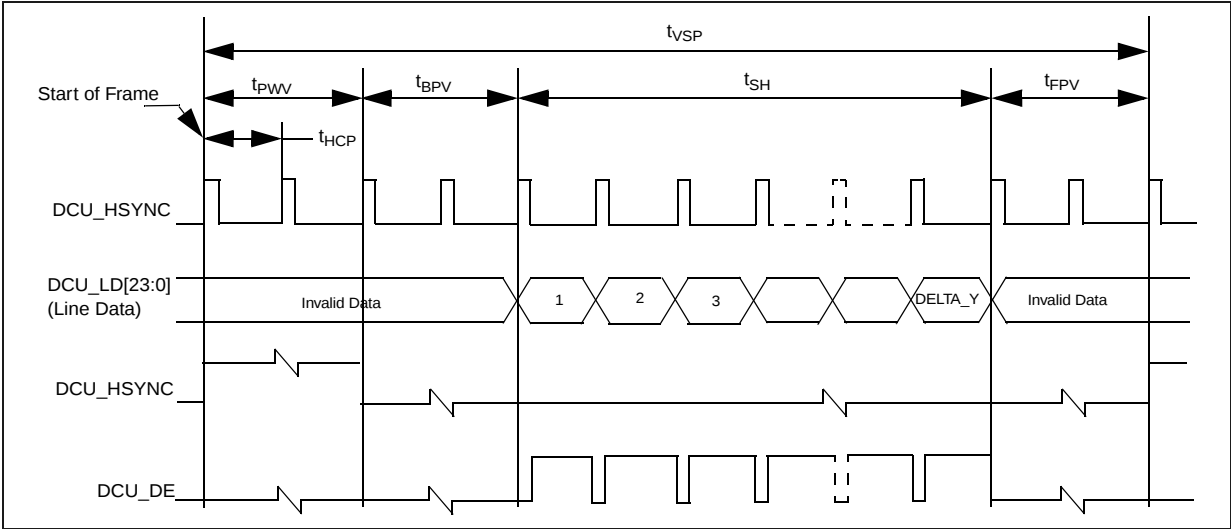


Figure 33. Vertical sync pulse

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3.20.3.2 Interface to TFT LCD panels

Table 58. TFT LCD interface timing parameters^{1,2,3,4}

Symbol	C	Parameter	Value			Unit
			Min	Typ	Max	
t_{CKP}	CC	D PDI clock period	15.25	—	—	ns
Δ_{CK}	CC	D PDI clock duty cycle	40	—	60	%
t_{DSU}	CC	D PDI data setup time	9.5	—	—	ns
t_{DHD}	CC	D PDI data access hold time	4.5	—	—	ns
t_{CSU}	CC	D PDI control signal setup time	9.5	—	—	ns
t_{CHD}	CC	D PDI control signal hold time	4.5	—	—	ns
	CC	D TFT interface data valid after pixel clock	—	—	6	ns
	CC	D TFT interface VSYNC valid after pixel clock	—	—	5.5	ns
	CC	D TFT interface DE valid after pixel clock	—	—	5.6	ns
	CC	D TFT interface hold time for data and control bits	2	—	—	ns
	CC	D Relative skew between the data bits	—	—	3.7	ns

¹ The characteristics in this table are based on the assumption that data is output at positive edge and displays latch data on negative edge

² Intra bit skew is less than 2 ns

³ Load $C_L = 50$ pF for panel frequency up to 20 MHz

⁴ Load $C_L = 25$ pF for panel frequency from 20 to 32 MHz

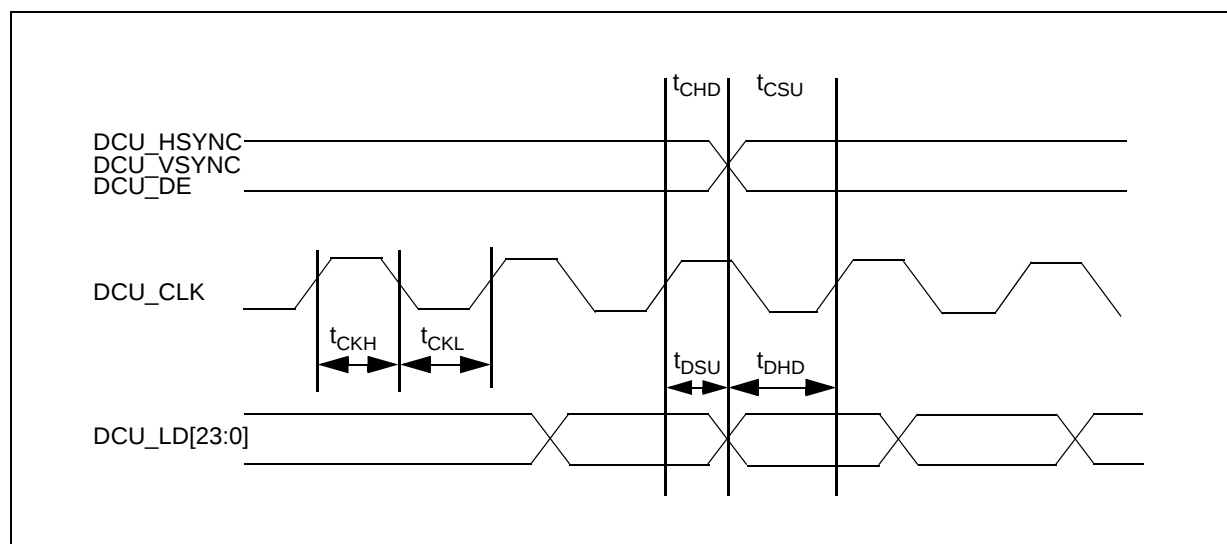


Figure 34. TFT LCD interface timing parameters

3.20.4 External Interrupt (IRQ) and Non-Maskable Interrupt (NMI) timing

Table 59. IRQ and NMI timing

No.	Symbol		C	Parameter	Value		Unit
					Min	Max	
1	t _{IPWL}	CC	T	IRQ/NMI Pulse Width Low	200	—	ns
2	t _{IPWH}	CC	T	IRQ/NMI Pulse Width High	200	—	ns
3	t _{ICYC}	CC	T	IRQ/NMI Edge to Edge Time ¹	400	—	ns

¹ Applies when IRQ/NMI pins are configured for rising edge or falling edge events, but not both.

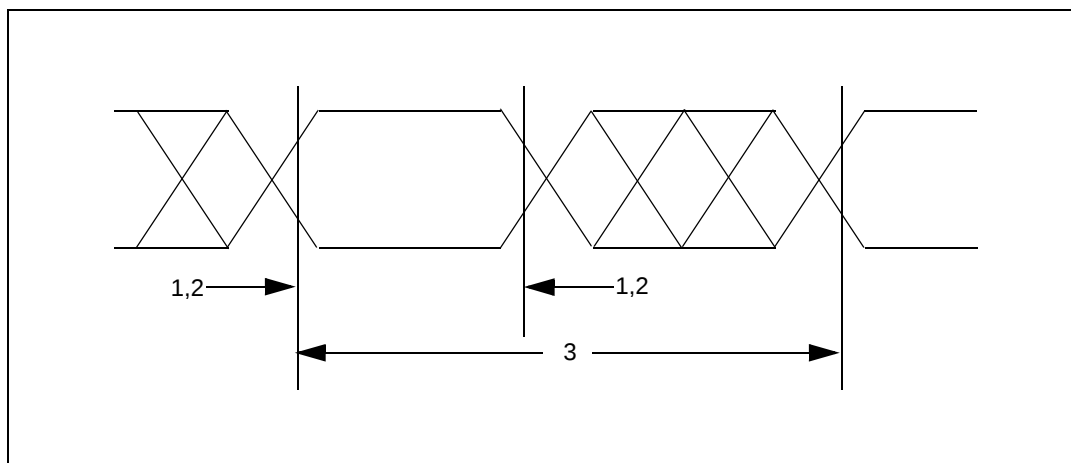


Figure 35. IRQ and NMI timing

3.20.5 eMIOS timing

Table 60. eMIOS timing¹

No.	Symbol		C	Parameter	Value		Unit
					Min ²	Max	
1	t _{MIPW}	CC	D	eMIOS input pulse width	4	—	t _{cyc}
2	t _{MOPW}	CC	D	eMIOS output pulse width	1	—	t _{cyc}

¹ eMIOS timing specified at $f_{SYS} = 64$ MHz, $V_{DD12} = 1.14$ V to 1.32 V, $VDDE_x = 3.0$ V to 5.5 V, $T_A = -40$ to 105 °C, and $C_L = 50$ pF with SRC = 0b00

² There is no limitation on the peripheral for setting the minimum pulse width, the actual width is restricted by the pad delays. Refer to the pad specification section for the details.

3.20.6 FlexCAN timing

The CAN functions are available as TX pins at normal IO pads and as RX pins at the always on domain. There is no filter for the wakeup dominant pulse. Any high-to-low edge can cause wakeup if configured.

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Table 61. FlexCAN timing¹

No.	Symbol		C	Parameter	Value		Unit
					Min	Max	
1	t _{CANOV}	CC	D	CTNX Output Valid after CLKOUT Rising Edge (Output Delay)	—	22.48	ns
2	t _{CANSU}	CC	D	CNRX Input Valid to CLKOUT Rising Edge (Setup Time)	—	12.46	ns

¹ FlexCAN timing specified at f_{SYS} = 64 MHz, V_{DD12} = 1.14 V to 1.32 V, VDDE_x = 3.0 V to 5.5 V, T_A = –40 to 105 °C, and C_L = 50 pF with SRC = 0b00.

3.20.7 Deserial Serial Peripheral Interface (DSPI)

Table 62. DSPI timing¹

No.	Symbol	C	Parameter	Value		Unit
				Min	Max	
1	t_{SCK}	CC	D SCK Cycle Time ^{2,3}	60	—	ns
2	t_{CSC}	CC	D PCS to SCK Delay ⁴	20	—	ns
3	t_{ASC}	CC	D After SCK Delay ⁵	20	—	ns
4	t_{SDC}	CC	D SCK Duty Cycle	$t_{SCK}/2 - 2\text{ns}$	$t_{SCK}/2 + 2\text{ns}$	ns
5	t_A	CC	D Slave Access Time (PCSx active to SOUT driven)	—	25	ns
6	t_{DIS}	CC	D Slave SOUT Disable Time (PCSx inactive to SOUT High-Z or invalid)	—	25	ns
7	t_{SUI}	CC	D Data Setup Time for Inputs Master (MTFE = 0)	35	—	ns
			Slave	5	—	ns
			Master (MTFE = 1, CPHA = 0) ⁶	5	—	ns
			Master (MTFE = 1, CPHA = 1)	35	—	ns
8	t_{HI}	CC	D Data Hold Time for Inputs Master (MTFE = 0)	−4	—	ns
			Slave	10	—	ns
			Master (MTFE = 1, CPHA = 0) ⁶	26	—	ns
			Master (MTFE = 1, CPHA = 1)	−4	—	ns
9	t_{SUO}	CC	D Data Valid (after SCK edge) Master (MTFE = 0)	—	15	ns
			Slave	—	35	ns
			Master (MTFE = 1, CPHA = 0)	—	30	ns
			Master (MTFE = 1, CPHA = 1)	—	15	ns
10	t_{HO}	CC	D Data Hold Time for Outputs Master (MTFE = 0)	−15	—	ns
			Slave	5.5	—	ns
			Master (MTFE = 1, CPHA = 0)	0	—	ns
			Master (MTFE = 1, CPHA = 1)	−15	—	ns

¹ DSPI timing specified at $V_{DDE_x} = 3.0\text{ V}$ to 5.5 V , $T_A = -40$ to $105\text{ }^\circ\text{C}$, and $C_L = 50\text{ pF}$ with $SRC = 0b11$.

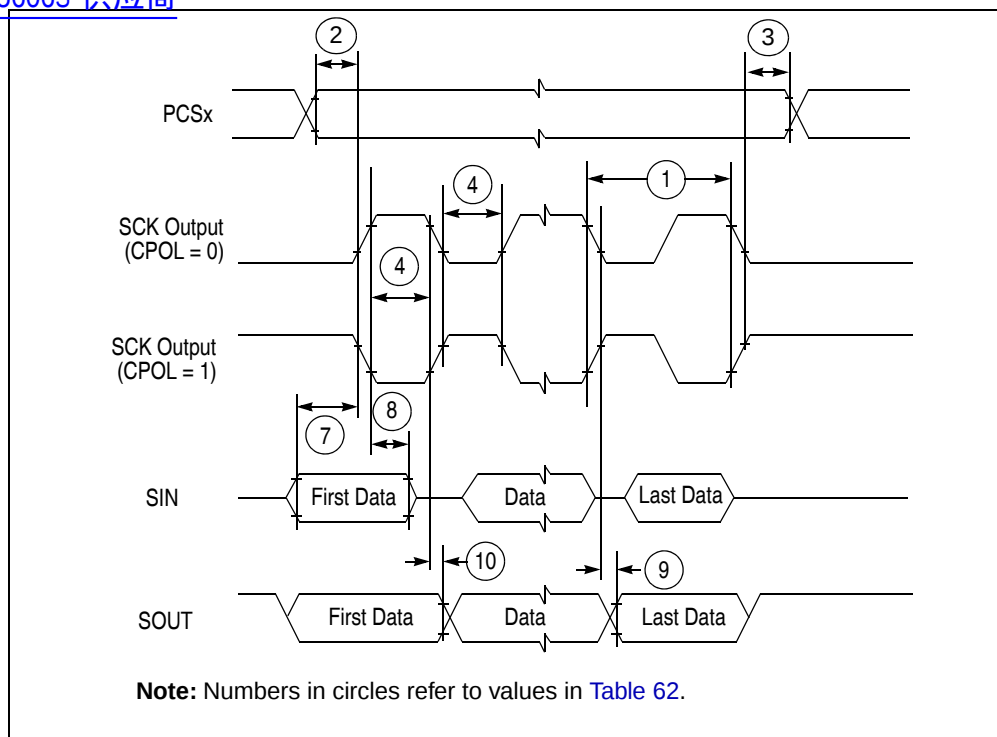
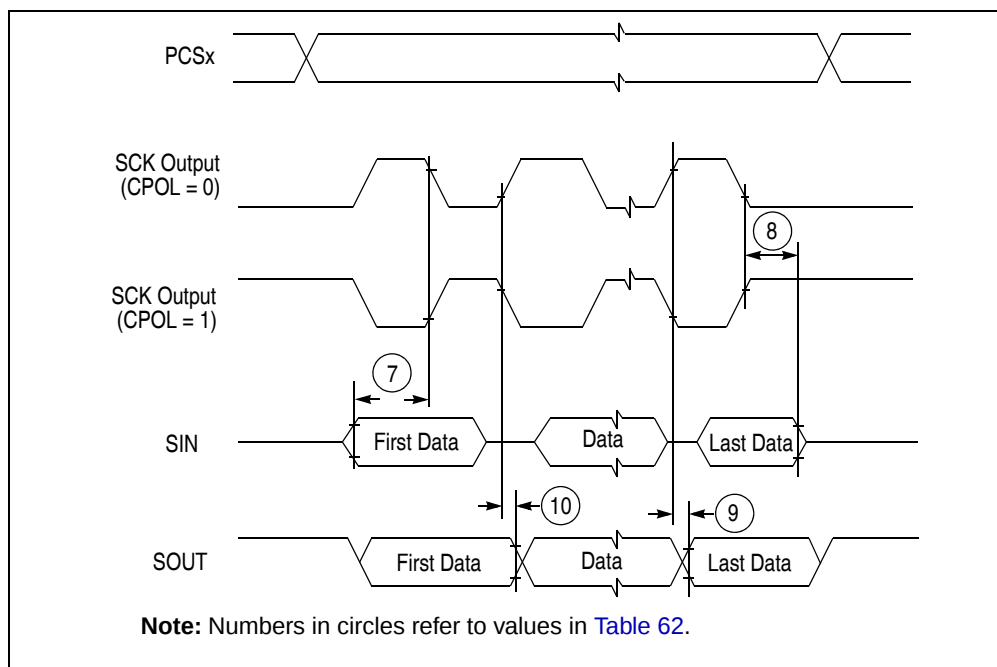
² The minimum SCK Cycle Time restricts the baud rate selection for given system clock rate.

³ The actual minimum SCK Cycle Time is limited by pad performance.

⁴ The maximum value is programmable in $DSPI_CTARx[PSSCK]$ and $DSPI_CTARx[CSSCK]$, program $PSSCK = 2$ and $CSSCK = 2$

⁵ The maximum value is programmable in $DSPI_CTARx[PASC]$ and $DSPI_CTARx[ASC]$

⁶ This delay value is corresponding to $SMPL_PT = 00b$ which is bit field 9 and 8 of $DSPI_MCR$ register.

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Figure 36. DSPI classic SPI timing — Master, CPHA = 0

Figure 37. DSPI classic SPI timing — Master, CPHA = 1

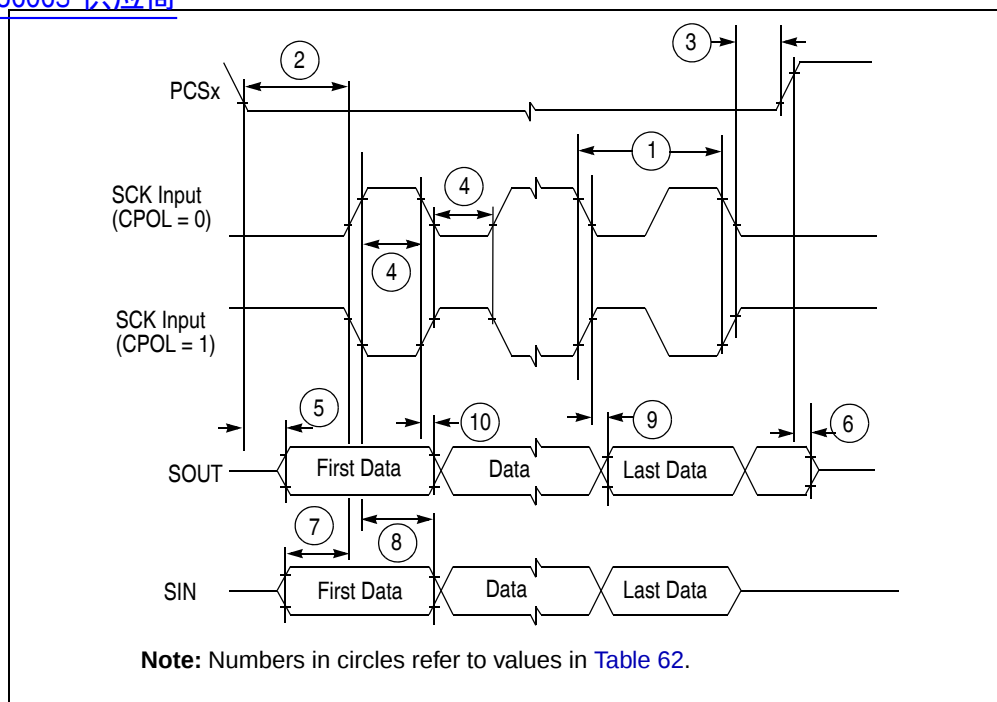


Figure 38. DSPI classic SPI timing — Slave, CPHA = 0

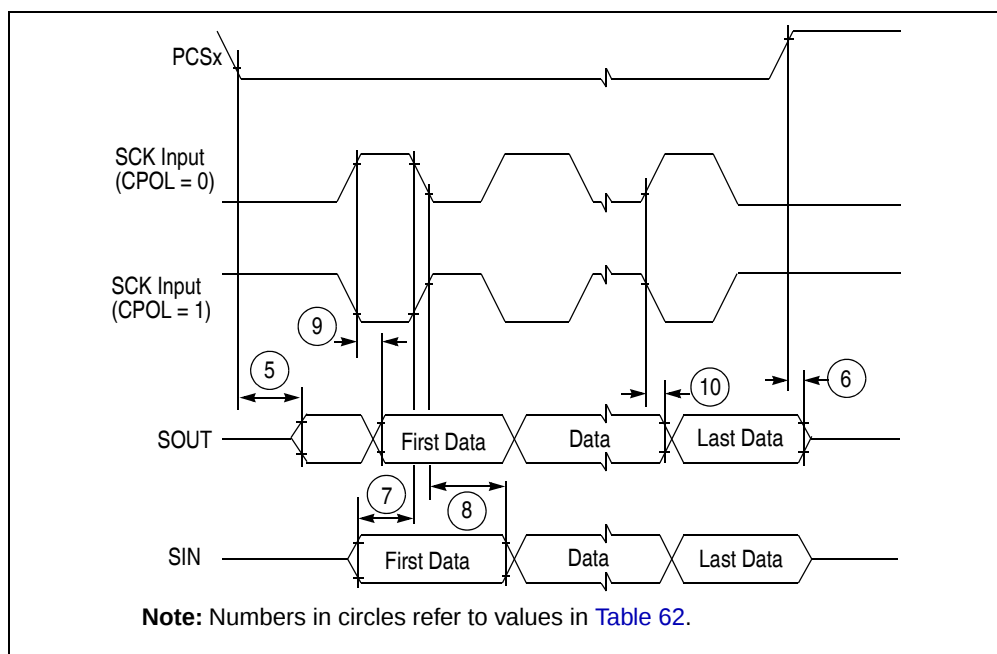
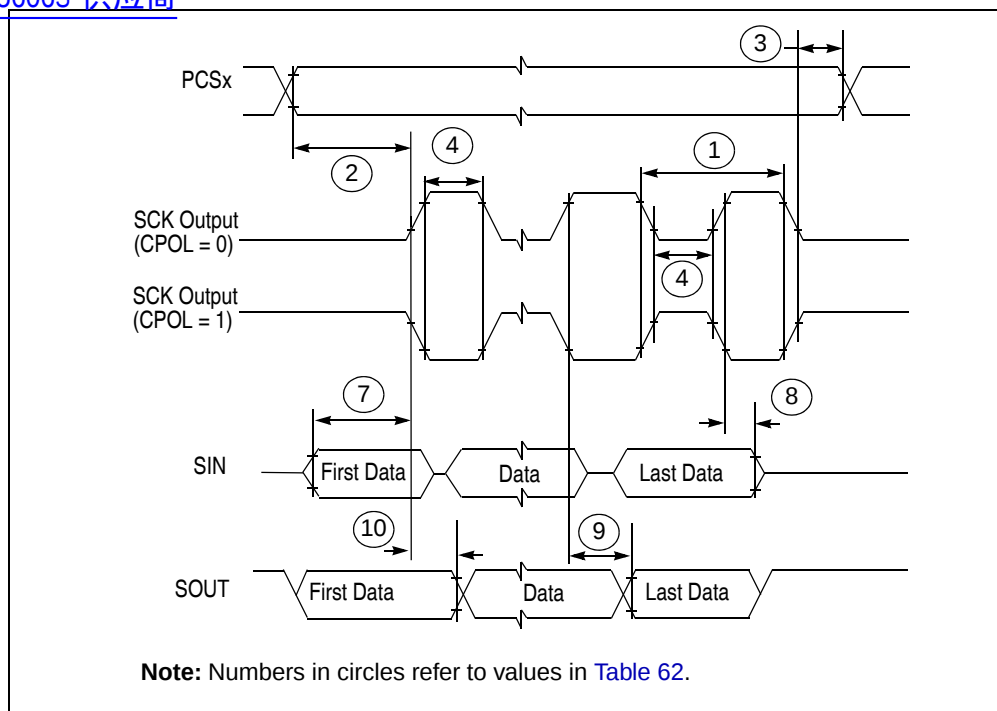
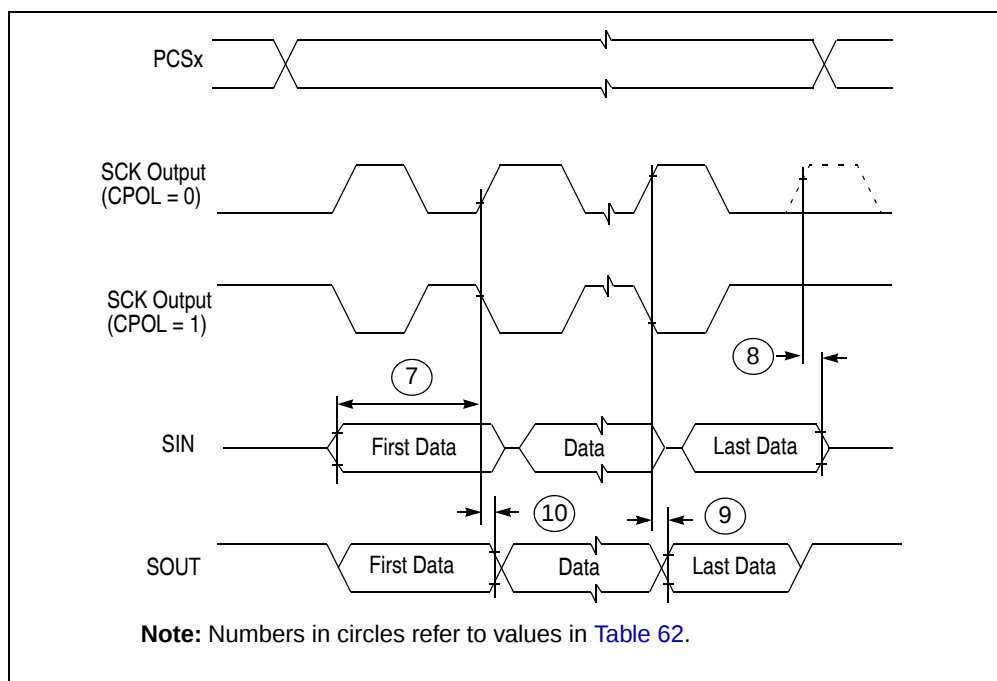


Figure 39. DSPI classic SPI timing — Slave, CPHA = 1

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Figure 40. DSPI modified transfer format timing — Master, CPHA = 0

Figure 41. DSPI modified transfer format timing — Master, CPHA = 1

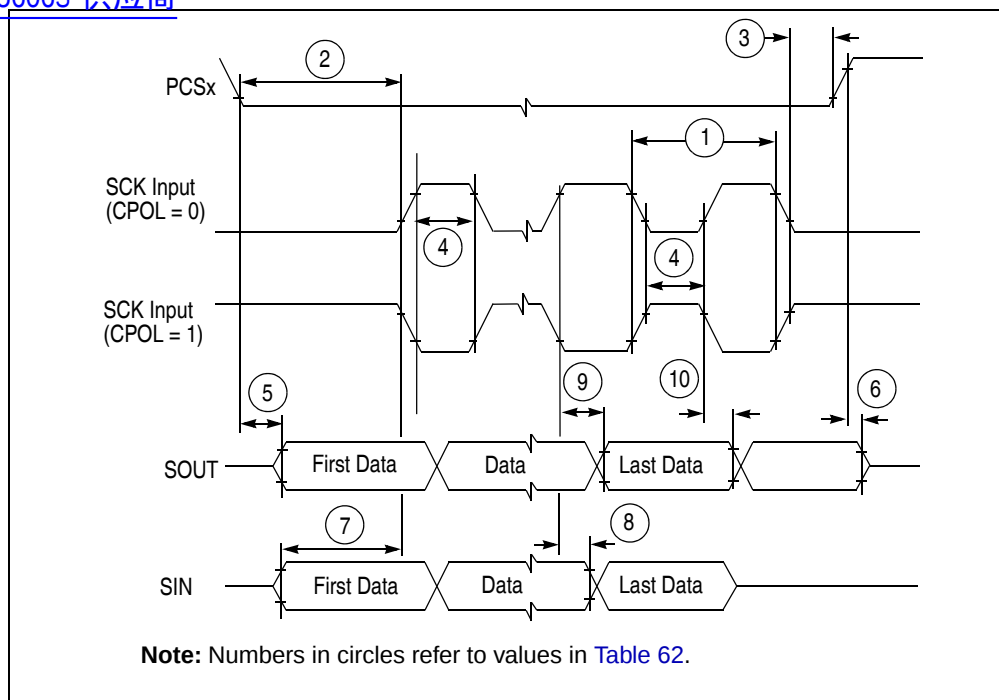


Figure 42. DSPI modified transfer format timing — Slave, CPHA = 0

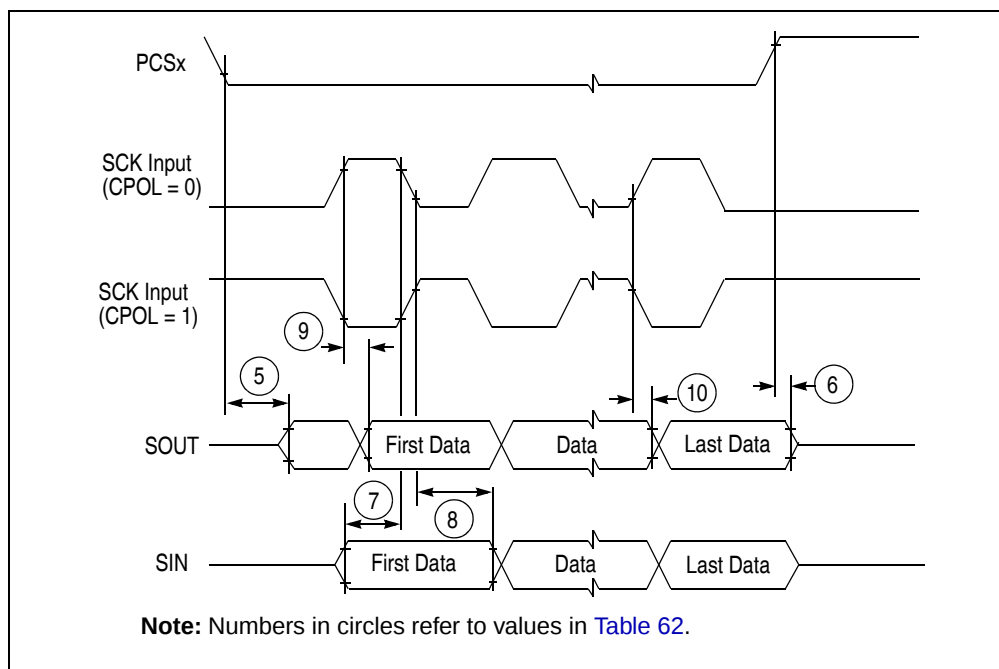


Figure 43. DSPI modified transfer format timing — Slave, CPHA = 1

Table 63. I²C input timing specifications — SCL and SDA

No.	Symbol		C	Parameter	Value		Unit
					Min	Max	
1	—	CC	D	Start condition hold time	2	—	IP-Bus Cycle ¹
2	—	CC	D	Clock low time	8	—	IP-Bus Cycle ¹
4	—	CC	D	Data hold time	0.0	—	ns
6	—	CC	D	Clock high time	4	—	IP-Bus Cycle ¹
7	—	CC	D	Data setup time	0.0	—	ns
8	—	CC	D	Start condition setup time (for repeated start condition only)	2	—	IP-Bus Cycle ¹
9	—	CC	D	Stop condition setup time	2	—	IP-Bus Cycle ¹

¹ Inter Peripheral Clock is the clock at which the I²C peripheral is working in the device

Table 64. I²C output timing specifications — SCL and SDA

No.	Symbol		C	Parameter	Value		Unit
					Min	Max	
1 ¹	—	CC	D	Start condition hold time	6	—	IP-Bus Cycle ²
2 ¹	—	CC	D	Clock low time	10	—	IP-Bus Cycle ¹
3 ³	—	CC	D	SCL/SDA rise time	—	99.6	ns
4 ¹	—	CC	D	Data hold time	7	—	IP-Bus Cycle ¹
5 ¹	—	CC	D	SCL/SDA fall time	—	99.5	ns
6 ¹	—	CC	D	Clock high time	10	—	IP-Bus Cycle ¹
7 ¹	—	CC	D	Data setup time	2	—	IP-Bus Cycle ¹
8 ¹	—	CC	D	Start condition setup time (for repeated start condition only)	20	—	IP-Bus Cycle ¹
9 ¹	—	CC	D	Stop condition setup time	10	—	IP-Bus Cycle ¹

¹ Programming IBFD (I²C bus Frequency Divider) with the maximum frequency results in the minimum output timings listed. The I²C interface is designed to scale the data transition time, moving it to the middle of the SCL low period. The actual position is affected by the prescale and division values programmed in IFDR.

² Inter Peripheral Clock is the clock at which the I²C peripheral is working in the device

³ Because SCL and SDA are open-drain-type outputs, which the processor can only actively drive low, the time SCL or SDA takes to reach a high level depends on external signal capacitance and pullup resistor values.

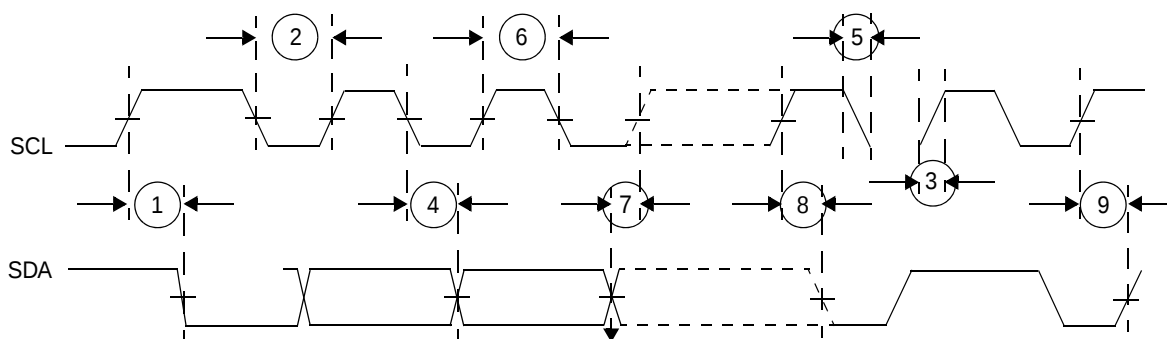


Figure 44. I²C input/output timing

3.20.9 QuadSPI timing

The following notes apply to [Table 65](#):

- All data are based on a negative edge data launch from MPC5606S and a positive edge data capture as shown in the timing diagrams.
- Typical values are provided from center-split material at 25 °C and 3.3 V. Minimum and maximum values are from a temperature variation of –45 °C to 105 °C and the following supply conditions:
 - IO voltage: 3.2 V, core supply: 1.2 V
 - IO voltage: 3.6 V, core supply: 1.2 V
- All measurements are taken at 70% of VDDE levels for clock pin and 50% of VDDE level for data pins.
- Timings correspond to QSPI_SMPR = 0x0000_000x. See the *MPC5606S Microcontroller Reference Manual* for details.
- A negative value of hold is an indication of pad delay on the clock pad (delay between the edge capturing data inside the device and the edge appearing at the pin).
- Values are with a load of 15pF on the output pins.

Table 65. QuadSPI timing

Symbol	C	Parameter	Value			Unit
			Min	Typ	Max	
t_{CQ}	CC	T	1.60	2.4	5.33	ns
t_S	CC	T	6.1	9.4	12.1	ns
t_H	CC	T	–12.5	–8.5	–7.5	ns
t_R	CC	T	0.4	0.6	1.0	ns
t_F	CC	T	0.3	0.5	0.9	ns

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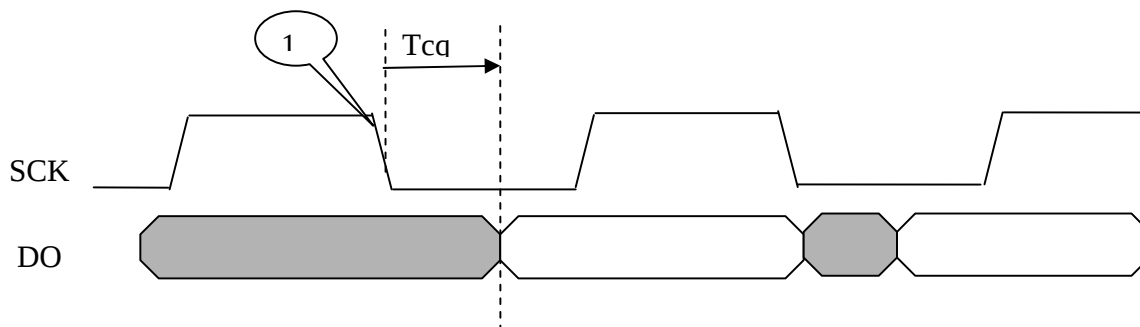


Figure 45. QuadSPI output timing diagram

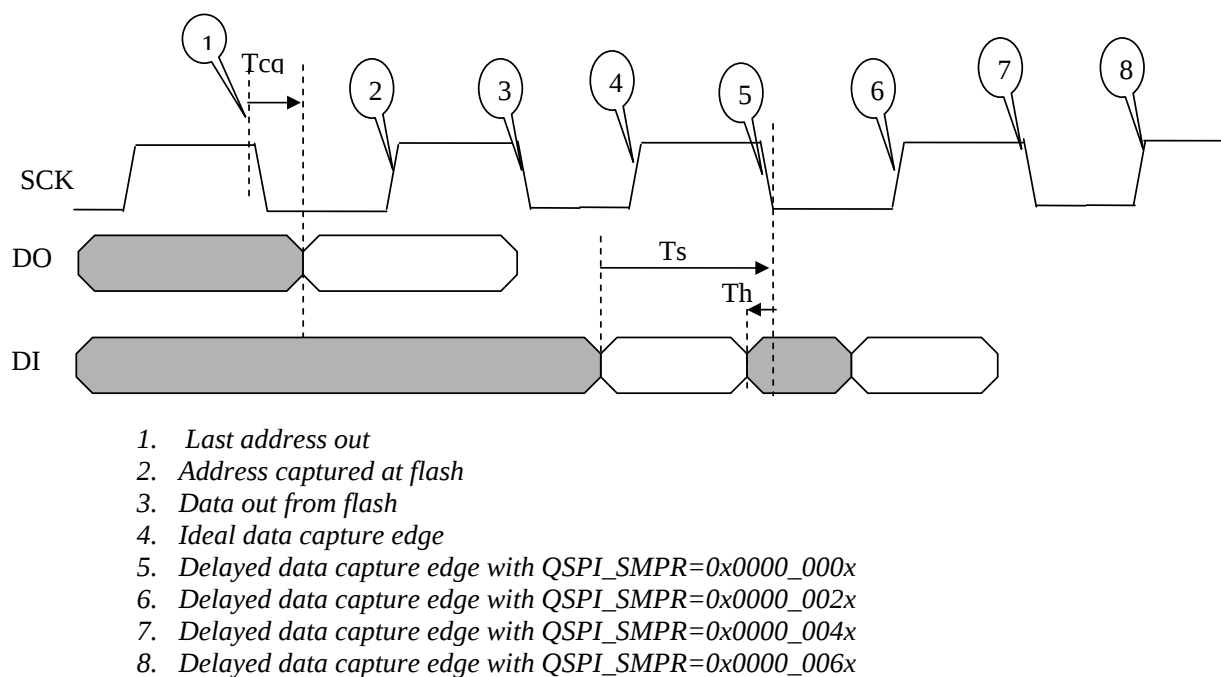


Figure 46. QuadSPI input timing diagram

The clock profile in [Figure 47](#) is measured at 30% to 70% levels of VDDE.

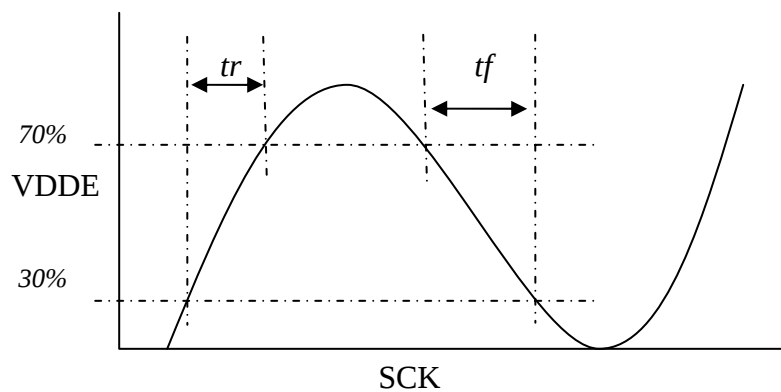
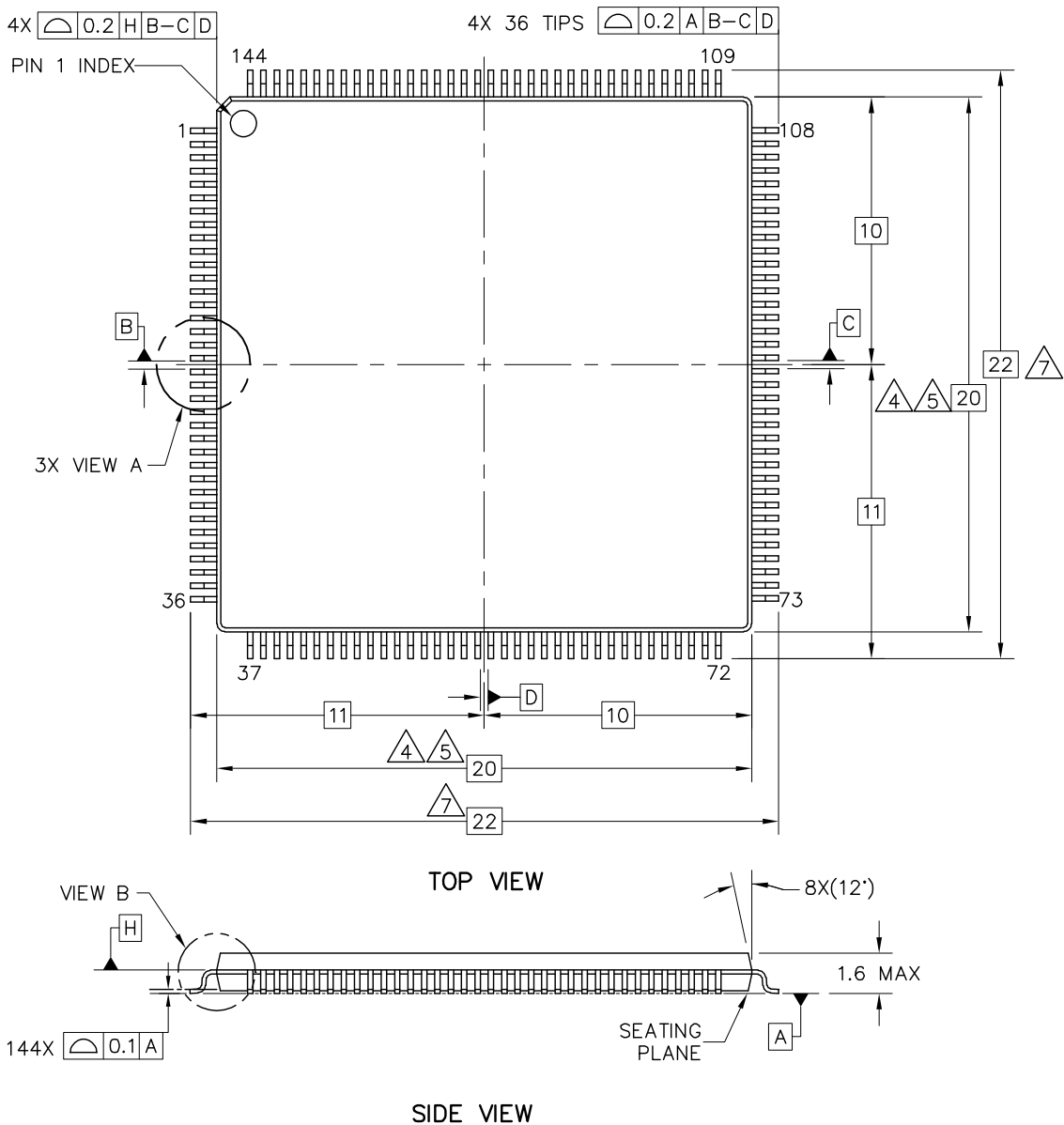


Figure 47. QuadSPI clock profile

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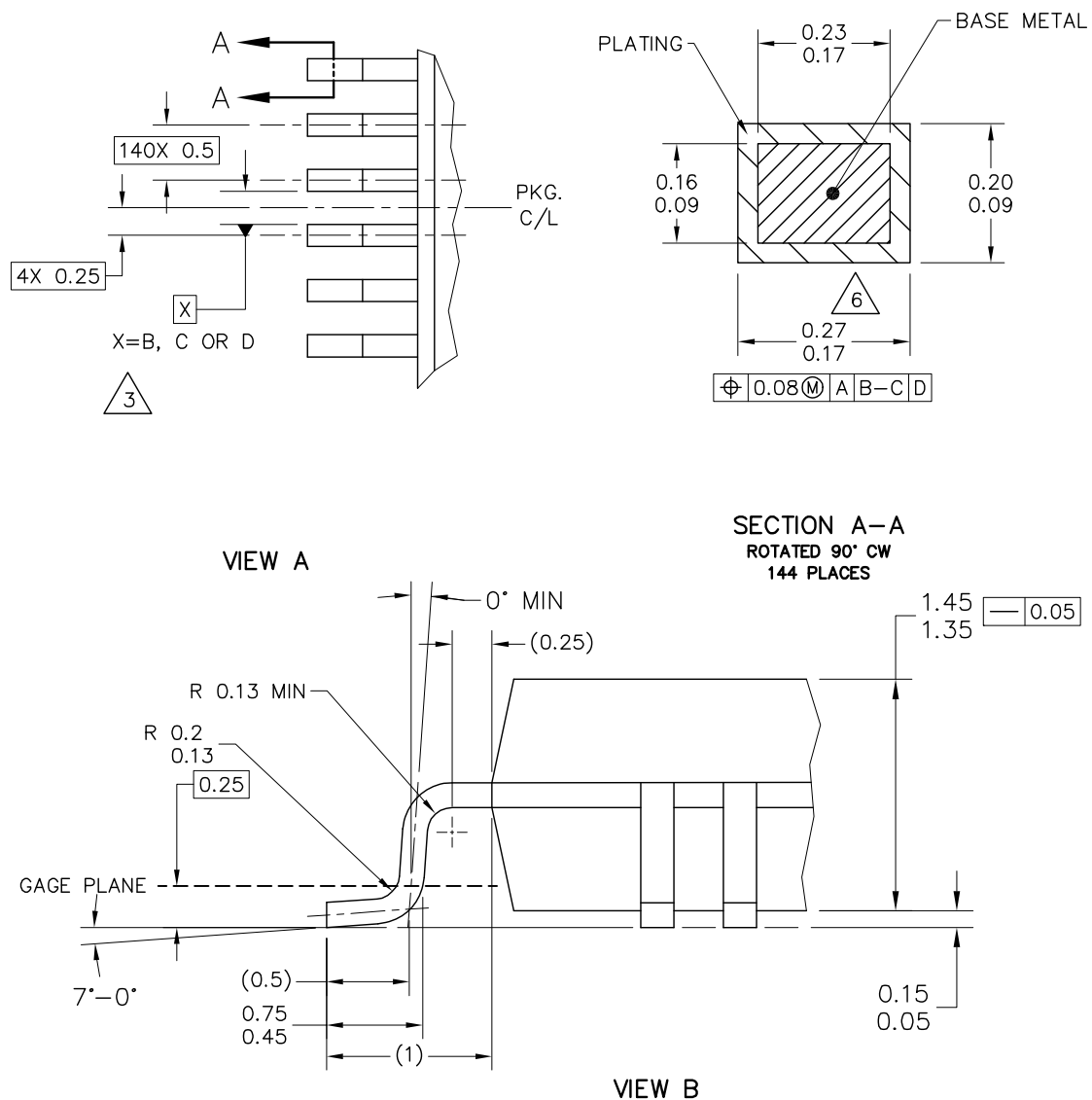
4 Package mechanical data

4.1 144 LQFP



© FREESCALE SEMICONDUCTOR, INC. ALL RIGHTS RESERVED.	MECHANICAL OUTLINE		PRINT VERSION NOT TO SCALE	
	TITLE:		DOCUMENT NO: 98ASS23177W	REV: F
	144 LEAD LQFP		CASE NUMBER: 918-03	20 MAY 2005
	20 X 20, 0.5 PITCH, 1.4 THICK		STANDARD: NON-JEDEC	

Figure 48. LQFP144 mechanical drawing (part 1 of 3)



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TITLE: 144 LEAD LQFP 20 X 20, 0.5 PITCH, 1.4 THICK	DOCUMENT NO: 98ASS23177W	REV: F
	CASE NUMBER: 918-03	20 MAY 2005
	STANDARD: NON-JEDEC	

Figure 49. LQFP144 mechanical drawing (part 2 of 3)

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NOTES:

1. ALL DIMENSIONS ARE IN MILLIMETERS.

2. INTERPRET DIMENSIONS AND TOLERANCES PER ASME Y14.5M-1994.

3. DATUMS B, C AND D TO BE DETERMINED AT DATUM PLANE H.

4. THE TOP PACKAGE BODY SIZE MAY BE SMALLER THAN THE BOTTOM PACKAGE SIZE BY A MAXIMUM OF 0.1 mm.

5. THIS DIMENSIONS DO NOT INCLUDE MOLD PROTRUSIONS. THE MAXIMUM ALLOWABLE PROTRUSION IS 0.25 mm PER SIDE. THIS DIMENSIONS ARE MAXIMUM BODY SIZE DIMENSIONS INCLUDING MOLD MISMATCH.

6. THIS DIMENSION DOES NOT INCLUDE DAM BAR PROTRUSION. PROTRUSIONS SHALL NOT CAUSE THE LEAD WIDTH TO EXCEED 0.35. MINIMUM SPACE BETWEEN PROTRUSION AND AN ADJACENT LEAD SHALL BE 0.07 mm.

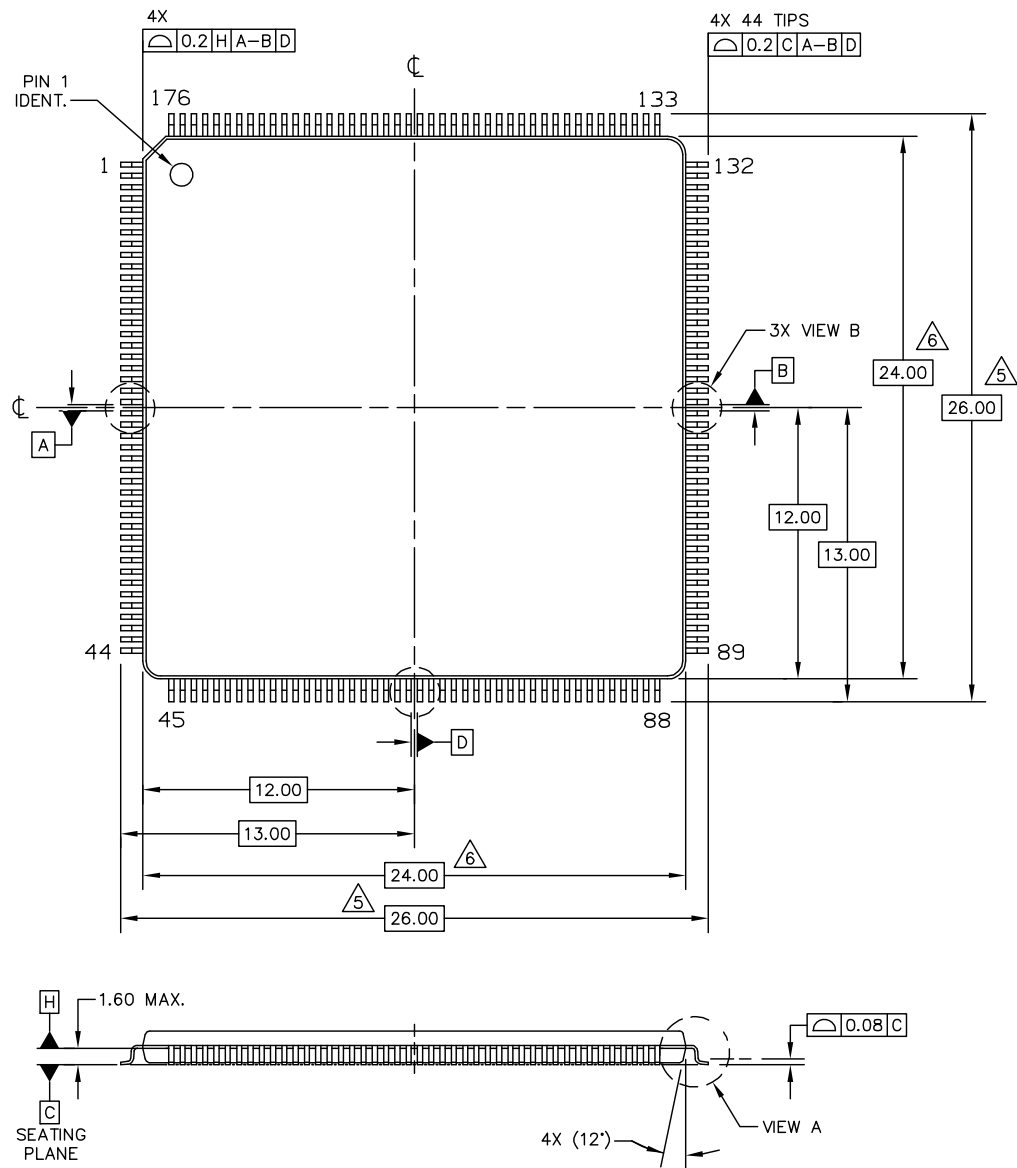
7. THIS DIMENSIONS ARE DETERMINED AT THE SEATING PLANE, DATUM A.

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TITLE: 144 LEAD LQFP 20 X 20, 0.5 PITCH, 1.4 THICK			DOCUMENT NO: 98ASS23177W		REV: F
			CASE NUMBER: 918-03		20 MAY 2005
			STANDARD: NON-JEDEC		

Figure 50. LQFP144 mechanical drawing (part 3 of 3)

Package mechanical data

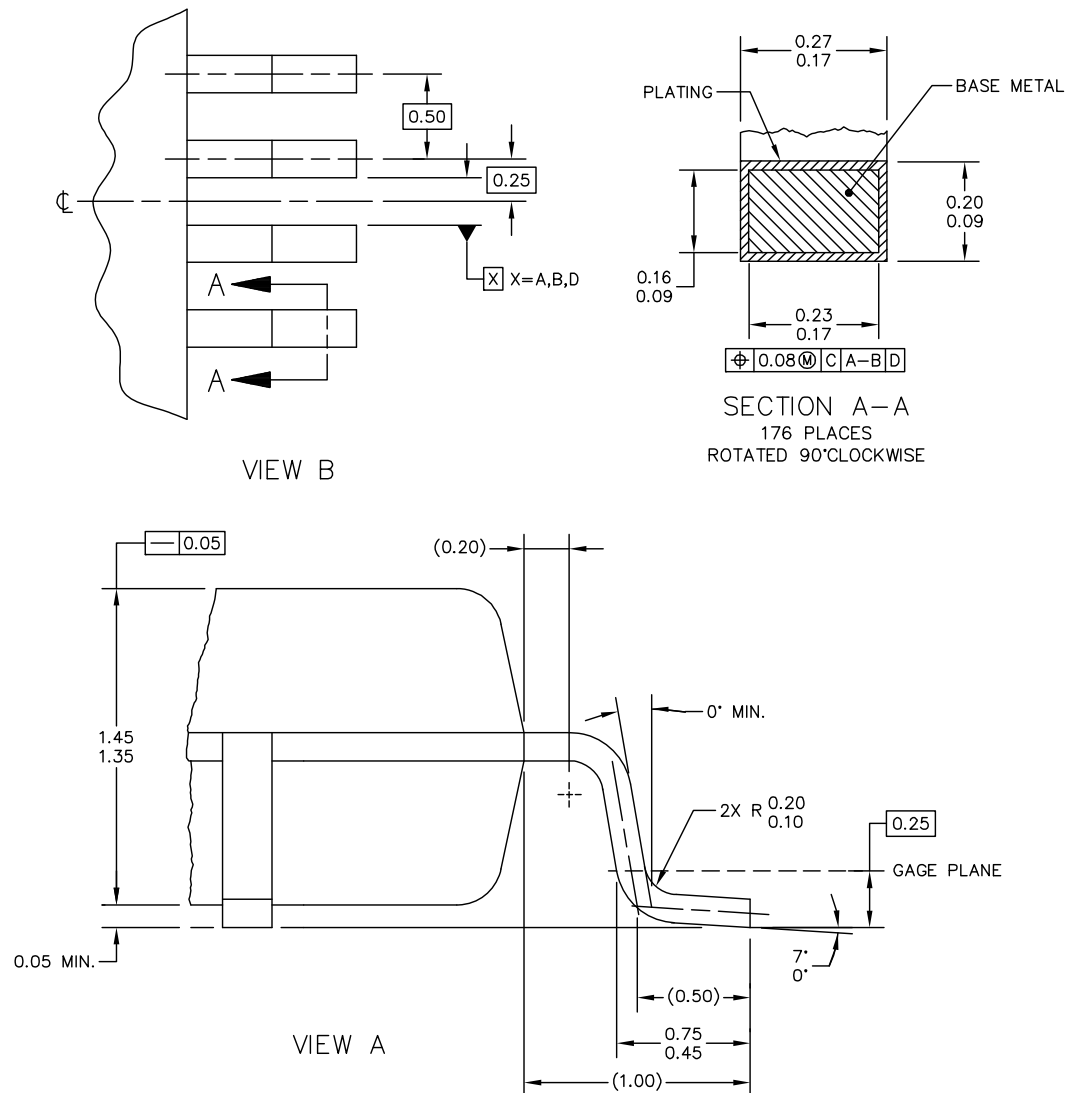
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4.2 176 LQFP



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TITLE: 176 LD TQFP, 24 X 24 PKG, 0.5 PITCH, 1.4 THICK		DOCUMENT NO: 98ASS23479W	REV: B
		CASE NUMBER: 1101-01	02 JUN 2005
		STANDARD: JEDEC MS-026 BGA	

Figure 51. LQFP176 mechanical drawing (part 1 of 3)

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TITLE: 176 LD TQFP, 24 X 24 PKG, 0.5 PITCH, 1.4 THICK			DOCUMENT NO: 98ASS23479W		REV: B
			CASE NUMBER: 1101-01		02 JUN 2005
			STANDARD: JEDEC MS-026 BGA		

Figure 52. LQFP176 mechanical drawing (part 2 of 3)

Package mechanical data

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NOTES:

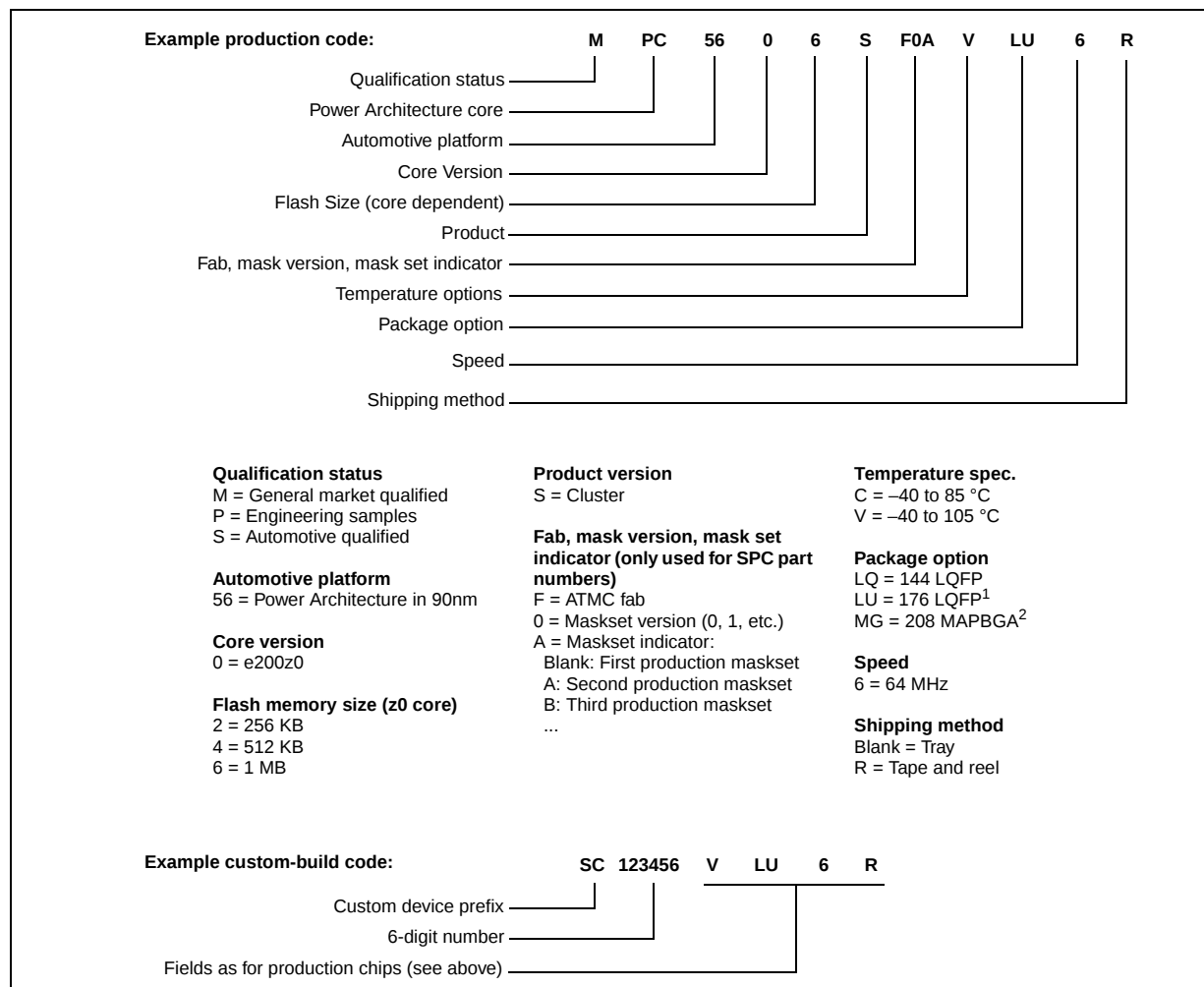
- 1 DIMENSIONS AND TOLERANCING PER ASME Y14.5M-1994.
- 2 DIMENSIONS IN MILLIMETERS.
- 3 DATUM PLANE H IS LOCATED AT BOTTOM OF LEAD AND IS COINCIDENT WITH THE LEAD WHERE THE LEAD EXITS THE PLASTIC BODY AT THE BOTTOM OF THE PARTING LINE.
- 4 DATUMS A, B AND D TO BE DETERMINED AT DATUM PLANE H.
- 5 THIS DIMENSIONS TO BE DETERMINED AT SEATING PLANE, DATUM C.
- 6 THIS DIMENSIONS DO NOT INCLUDE MOLD PROTRUSION. ALLOWABLE PROTRUSION IS 0.25 PER SIDE. THIS DIMENSIONS INCLUDE MOLD MISMATCH AND ARE DETERMINED AT DATUM PLANE H.
- 7 THIS DIMENSION DOES NOT INCLUDE DAMBAR PROTRUSION. DAMBAR PROTRUSION SHALL NOT CAUSE THE LEAD WIDTH TO EXCEED 0.35. MINIMUM SPACE BETWEEN PROTRUSION AND ADJACENT LEAD 0.07.

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TITLE: 176 LD TQFP, 24 X 24 PKG, 0.5 PITCH, 1.4 THICK	DOCUMENT NO: 98ASS23479W		REV: B
	CASE NUMBER: 1101-01		02 JUN 2005
	STANDARD: JEDEC MS-026 BGA		

Figure 53. LQFP176 mechanical drawing (part 3 of 3)

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5 Ordering information



¹ The 176-pin package is available only for chips with 1 MB flash memory.

² 208 MAPBGA available only as development package for Nexus2+, and will not be qualified for production

Figure 54. Commercial product code structure

6 Revision history

Table 66. Document revision history

Revision	Date	Substantive changes
1	10-2008	Initial release.
2	18 Aug 2009	Editorial changes and improvements. Harmonized oscillator naming throughout document Section 1.5, "MPC5606S features: Updated description of ADC channels Table 2: Changed max number of GPIOs from 132 to 133 for LQFP176 Table 3: Corrected "Peripheral interrupt timer (PIT)" to "Periodic interrupt timer (PIT)" Figure 2: – Added GPIOs to pin function names – Changed function of pin 32: was NC—is VREG_BYPASS – Pin 55: Changed XTAL32 to OSC32K_XTAL – Pin 56: Changed EXTAL32 to OSC32K_EXTAL Figure 5: – Added GPIOs to pin function names – Changed function of pin 32: was NC—is VREG_BYPASS – Pin 71: Changed XTAL32 to OSC32K_XTAL – Pin 72: Changed EXTAL32 to OSC32K_EXTAL Table 6: – Removed pins EXTAL32, XTAL32 and NMI – Updated VRC_CTL I/O direction and pad type Table 7: - Replaced "A" with "I" in pad type column - Modified table footnote 3 to replace pad type "A" definition with pad type "I" definition Table 8: Moved MA[0:2] to follow AN[0:15] Added Section 3.2, "Parameter classification and added classification tags to electrical characteristics tables where appropriate Added Section 3.3, "NVUSRO register Table 14: Removed ESD_{HBM} Table 17: Merged 144- and 176-pin LQFP characteristics into single table Added Section 3.6, "Electromagnetic compatibility (EMC) characteristics Table 26: Removed "T_A = 25 °C, after trimming" from conditions for V_{PORH}, V_{LVDH3V} and V_{LVDH5V} Table 27: – Changed T_A = –40 to 125 °C to T_A = –40 to 105 °C in note 1 – Added STANDBY1 and STANDBY2 mode current characteristics Figure 12: Updated to reference GPD1 register and values for bit PDI Section 3.8.1, "I/O pad types: Corrected "four main I/O pad types" to read "three main I/O pad types" Section 3.8.3, "I/O output DC characteristics: Replaced ipp_hve with PAD3V5V

Table 66. Document revision history

Revision	Date	Substantive changes
2 (continued)	18 Aug 2009 (continued)	Table 37: – I_{RMSMED}: Replaced SLOW with MEDIUM in parameter column – I_{RMSFST}: Replaced SLOW with FAST in parameter column Section 3.8.4, "I/O pad current specification: Replaced ipp_hve with PAD3V5V Section 3.10, "RESET electrical characteristics: Replaced ipp_hve with PAD3V5V Updated Figure 13 Updated Figure 16 Updated Figure 18 Section 3.19, "Pad AC specifications: Replaced IPP_HVE with PAD3V5V Table 45: Added rows $I_{FIRCSTOP}$ and t_{FIRCSU} Table 46: – Added rows t_{SIRCSU} and $\Delta_{SIRCTRIM}$ – Updated conditions for $\Delta_{SIRCVAR}$ Added Table 42 "ADC input leakage current" Table 50: Updated TUEp and TUEx
		Table 7: Modified PC[0] to PC[9]: – I/O direction: was I, is I/O – pad type: was I, is S Table 50: Updated values for 'Input current injection' Section 3.20.3, "Interface to TFT LCD panels: Modified description of event No. 1 in sequence for active matrix interface timing Table 57: Removed value for Display pixel clock period Table 53: Removed duplicated row for part number MPC5604SEMLQ Section 2.4.2, "Voltage Supply Pins": Added preferred power up sequence. Section 2.9, "Port pin summary": Changed reset configuration on ADC pins. Section 3, "Electrical characteristics: Made updates to data. All data is still considered preliminary. Section 3.7.1, "Voltage regulator electrical characteristics": Added lower power voltage regulator and ultra-low power voltage regulator characteristics.
3	—	Not released; no substantive changes between Rev. 2 and Rev. 3.
4	—	Not released; no substantive changes between Rev. 3 and Rev. 4.

Table 66. Document revision history

Revision	Date	Substantive changes
5	1 Sep 2010	Editorial changes and improvements. Replaced “validation” with “characterization” throughout. Added an entry for Rev. 3 to this table. In the block diagram, in the SXOSC block, changed “32 kHz” to “32 KHz”. Revised the feature section and added the “Feature details” subsection. Renamed the analog pins (were AN..., are ANS...) throughout. Changed several pin names that contained _A, _B, _C, ... to contain _0, _1, _2, ... throughout. Changed the PCS and oscillator pin names throughout. Revised the feature section and added the “Feature details” subsection. Deleted the out-of-date “Block summary” section. In the 144-pin pinout: - For pin 122, changed PCS_B1 to PCS1_1. - For pin 123, changed PCS_B0 to PCS0_1. In the “144 LQFP package pinout” section, added pinouts for the chips with 512 KB and 256 KB flash memory. In the 176-pin pinout: - For pin 152, changed PCS_B1 to PCS1_1. - For pin 153, changed PCS_B0 to PCS0_1. Revised the “Pad configuration during reset phases”, “Voltage supply pins”, “Pad types”, “System pins”, and “Nexus pins” sections. Changed several module names and abbreviations to be consistent with the official module names and abbreviations. In the “Voltage supply pin descriptions” table, revised the entry for VDD12. In the “Debug pin descriptions” table, changed pad type M to pad type M1. In the “Pad types” section, changed “registers in the device reference manual” to “registers in the SIUL chapter of the device reference manual”. Changed the name of the port-pin summary section (was “Functional ports A, B, C, D, E, F, G, H, I, J, K”, is “Port pin summary”). In the “Signal details” section: - Renamed the analog pins (were AN..., are ANS...). - Added “ANS[0:15] connect to ATD channels [32:47]” to the ANS signal description. - Added “The available 8 multiplexed channels connect to ATD channels [64:71]” to the MA signal description. - Deleted “when high; otherwise low to allow a subframe display for pixels” from the DCU_DE description. - Changed the description for DCU_TAG, PDI_PCLK, TXD_A, and SSD signals. - Added QuadSPI signals. - Deleted “For valid Pixel Data this is high, otherwise low” from the PDI_DE description. - Changed several pin names that contained _A, _B, _C, ... to contain _0, _1, _2, ... In the “Port pin summary” table: - Changed the pad type for PC[0]—PC[9] (was S, is J). - Moved the AN[0]—AN[15] entries from the “Function” column to the “Special function” column. - Moved the OSC32K_EXTAL and OSC32K_XTAL entries from the “Function” column to the “Special function” column. - Added alternate function names and clarifying footnotes to the PF[11]—PF[14] entries. - Added new information on pad types (including splitting up the existing M pads into two categories, M1 and M2). - Added a footnote to the “Special function” column title.

Table 66. Document revision history

Revision	Date	Substantive changes
5 (continued)	1 Sep 2010 (continued)	Added a footnote to the "Pad type description" table. In the "Pad type description" table: - Revised the entry for SMD. - Revised the description for the J and M2 pad types. Revised the entry for VSSPLL in the "Absolute maximum ratings" and "Recommended operating conditions" table. Changed the max value for V_{DDPLL} (was 1.32 V, is 1.4 V) in several tables. Added the "Connecting power supply pins: What to do and what not to do" section. In the "Recommended operating conditions" table, changed the note to state "Maximum slew..." instead of "Minimum slew...". In footnote 2 of the "Recommended operating conditions" table, changed "200 μF capacitance must be connected between V_{DDR} and V_{SS12}" to "10 μF capacitance must be connected between V_{DDR} and V_{SS12}". In the "Recommended operating conditions" section, added a caution on which voltages must be the same. In the "Recommended operating conditions (3.3 V)" table: - Revised the footnote affecting V_{DD12}/V_{SS12} supply capacitances. - Deleted footnote 9. - Deleted the entries for V_{DDPLL} and V_{DD12}. In the "Recommended operating conditions (5.0 V)" table: - Changed the footnote text "200 μF capacitance must be connected between V_{DDR} and V_{SS12}" to "10 μF capacitance must be connected between V_{DDR} and V_{SS12}" and revised the footnote affecting V_{DD12}/V_{SS12} supply capacitances. - Added a specification for TV_{DD}. - Deleted the entries for V_{DDPLL} and V_{DD12}. Revised the "EMC requirements on board" section. Added meaningful values to the "EMI testing specifications" table. In the "ESD absolute maximum ratings" table, added a specification for $V_{ESD(MM)}$. Deleted the empty "DC Electrical Characteristics" section. In the "I/O pad types" section, added an entry for SMD pads. Added SMC pad electrical characteristics. Revised the "Voltage regulator electrical characteristics" section. Revised the "Low-power voltage regulator electrical characteristics" table. Revised the "Ultra-low power voltage regulator electrical characteristics" table. Revised the "Low voltage monitor electrical characteristics" table. Added the "Recommended power-up and power-down order" section. Added the "Power-up inrush current profile" section. Added the "HPREG load regulation characteristics" section. Revised the "DC electrical characteristics" table. Replaced all values for "STANDBY mode current". Revised the "I/O pad types" section. In the "I/O input DC electrical characteristics" table: - Changed the specifications for ILKG (was min = <1 μA, is min = -1 μA; was max = —, is max = 1 μA). - Added an entry for R_{ON}. Revised the "I/O output DC characteristics" section. Revised the "MEDIUM configuration output buffer electrical characteristics" table. Revised the "SMC pad electrical characteristics" table and changed its name (is "SMC pad..."). In the "SMC pad electrical characteristics" table, changed R_{DSOH} to R_{DSOH} and R_{DSOL} to R_{DSOL}. Moved the I_{MAX} specification from the "SMC pad electrical characteristics" table to the "Absolute maximum ratings" table.

Table 66. Document revision history

Revision	Date	Substantive changes
5 (continued)	1 Sep 2010 (continued)	Added the "SMC pad delays" table. Added the "SSD specifications" section. In the "I/O consumption" table, added a specification for $I_{DDMxAVG}$. Revised the "Fast external crystal oscillator (4–16 MHz) electrical characteristics" table. In the "Slow external crystal oscillator (32 kHz) electrical characteristics" figure, changed V_{OSC32K_XTAL} to V_{SXOSC_XTAL}. In footnote 2 of the "FMPPLL electrical characteristics" table, changed "f_{CPU} 64 MHz can be achieved only at up to 105 °C" to "f_{CPU} 64 MHz can be achieved only at temperatures up to 105 °C with a maximum FM depth of 2%". In the first "Crystal oscillator and resonator connection scheme" figure: • Swapped "XTAL" and "EXTAL". • Deleted R_P. In the second "Crystal oscillator and resonator connection scheme" figure, deleted R_P. Added the "Crystal description" table. In the "Fast internal RC oscillator (16 MHz) electrical characteristics" table: • Changed the conditions for $\Delta_{FIRCVAR}$ (was "$T_A = -25$ °C", is "$T_A = -40$ to 105 °C, trimmed"), removed the associated footnote, and changed the associated guarantee method (was P, is C). • Changed the max specification for $I_{FIRCPWD}$ (was 10 μA, is 1 μA). Added the "Resonator description" table. In the "Fast external crystal oscillator (4 to 16 MHz) electrical characteristics" table, changed footnote 1 (was "... to 125 °C", is "... to 105 °C"). In the "Slow external crystal oscillator" section, changed "32 kHz" to "32 KHz". In the "Slow external crystal oscillator (32 KHz) electrical characteristics" table, added a footnote to the start-up timing specification. In the "Slow internal RC oscillator (128 KHz) electrical characteristics" table: • Changed the condition for $\Delta_{SIRCVAR}$ (was —, is "Trimmed") and the associated guarantee method (was P, is C). • Changed the guarantee method for f_{SIRC} (was P, is C). Revised the "Program and erase specifications" table. In the "Flash memory read access timing" table, changed footnote 1 (was "... to 125 °C", is "... to 105 °C"). Revised the "Flash module life" table. Added flash read access timing characteristics. In the "ADC conversion characteristics" table: • Deleted the entry for TUEp (precision channels are not implemented on this device). • Changed the specification for INL (was min = -1.5 LSB and max = 1.5 LSB, is min = max = 2.5 LSB). • Revised the entry for I_{INJ} (was ± 10 mA, is ± 5 mA). • Changed the max specifications for R_{SW1} (was 3 kΩ, is 1 kΩ) and for R_{SW2} (was 2 kΩ, is 1 kΩ). Added the "LCD driver electrical characteristics" section. Revised the table titles in the "Pad AC specifications" section. Added the "QuadSPI timing" section. Revised the "JTAG interface timing" table. Revised the "Nexus debug port timing" table. Renamed the "Interface to TFT LCD panels—access level" section (is "Interface to TFT LCD panels") and revised the table (title and contents) within it. In the "DSPI timing" table, added a min specification for t_{CSC} (is 20 ns). In the DSPI section, added a note (referring to the "DSPI timing" table) to each timing diagram. Revised the "Ordering information" section.

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